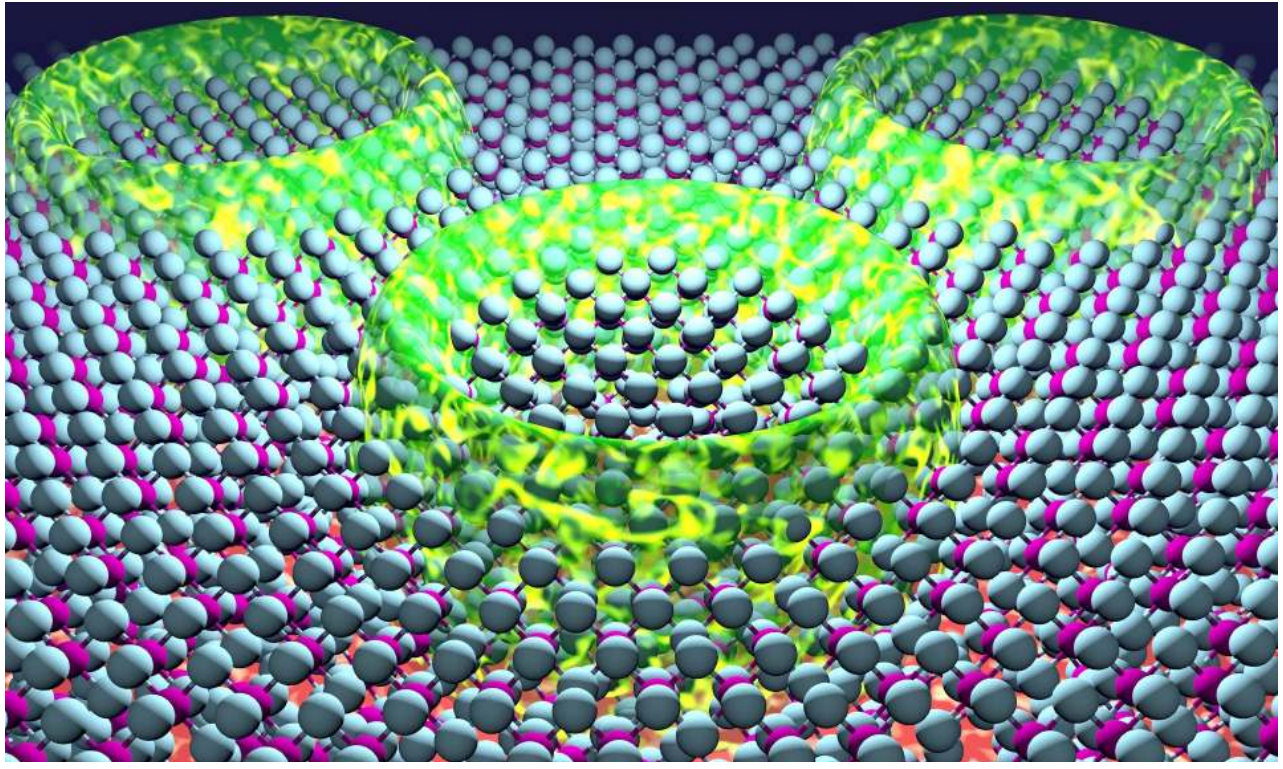
Moire electronic states and twisted van der Waals heterostructures



Jyväskylä Summer School "Emergent Quantum Matter in Artificial Two-dimensional Materials"

Thursday August 11th 2022

Schedule for the lecture

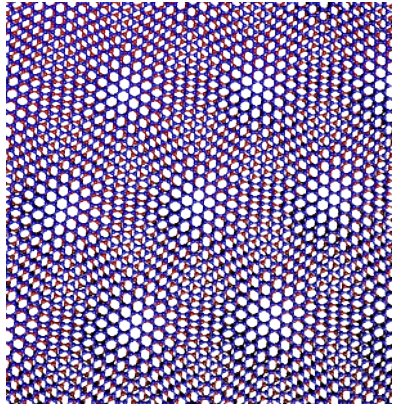
- 40 min lecture
- 15 min break
- 40 min lecture
- 15 min break
- 40 min lecture

Today’s plan

- Moire and quasiperiodicity
- Band structure folding, unfolding and minibands
- Correlations in moire electronic structures
- Topology in moire systems
- Twisted graphene multilayers

Moire materials

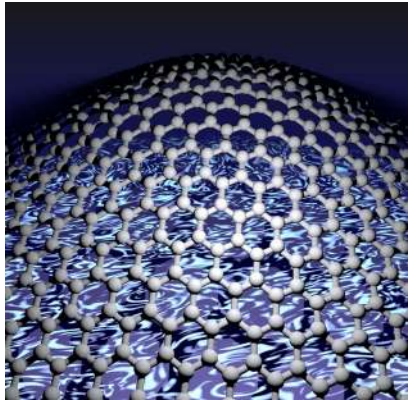
Twisted graphene multilayers



graphene

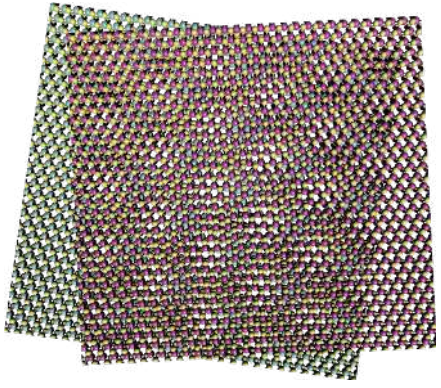
Moire states in several layers

Buckled 2D materials



Moire states in single layer

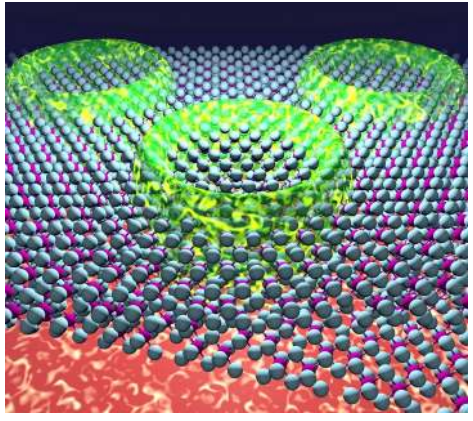
Twisted TMDCs



MoS_2, WSe_2

Moire states in single/several layer

Twisted magnetic 2D materials



$CrCl_3$, $CrBr_3$

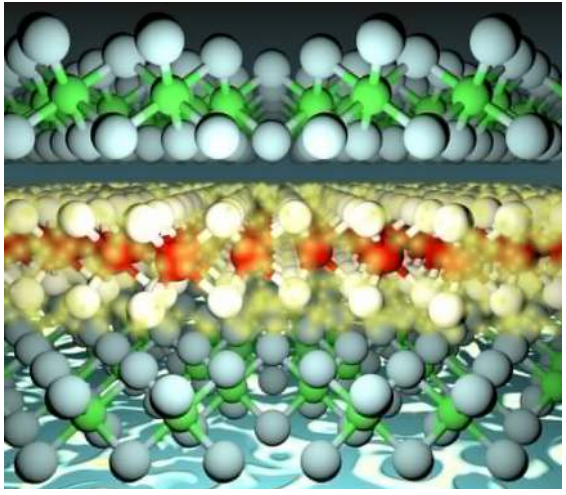
Moire magnetism

Moire in electronic properties

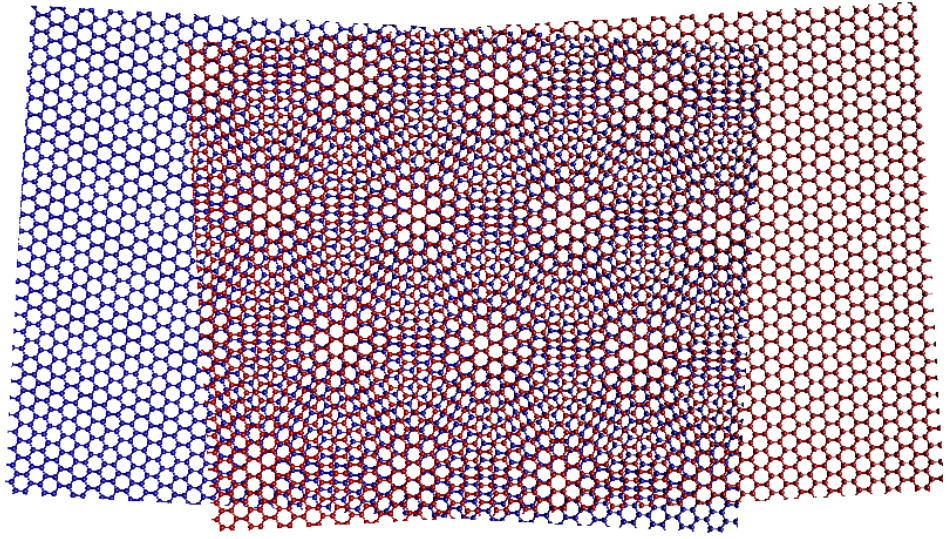
Moire in magnetic properties

How to create moire states with 2D materials

Stacking



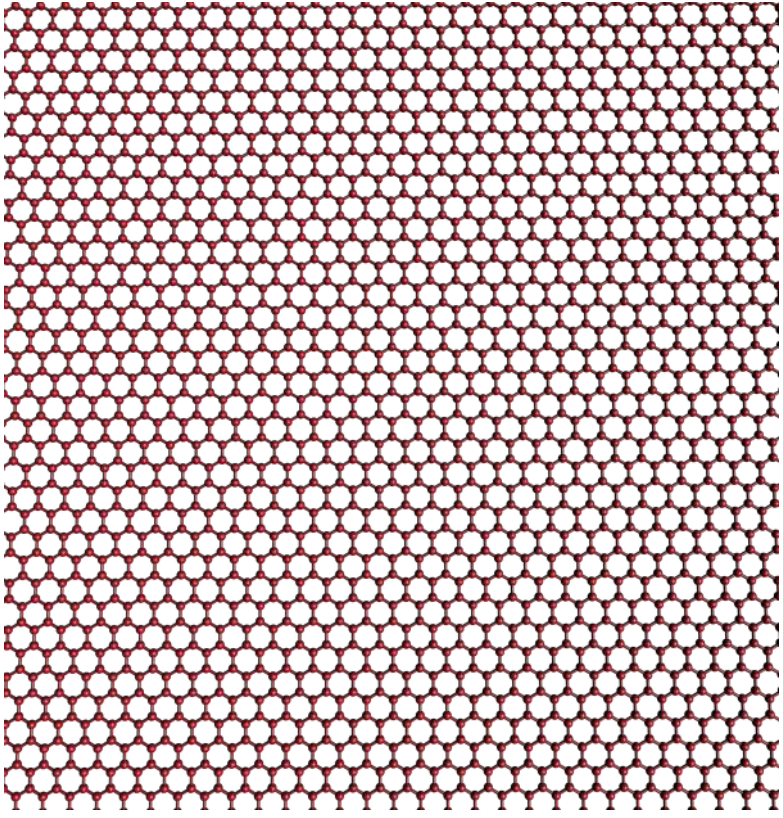
Rotating



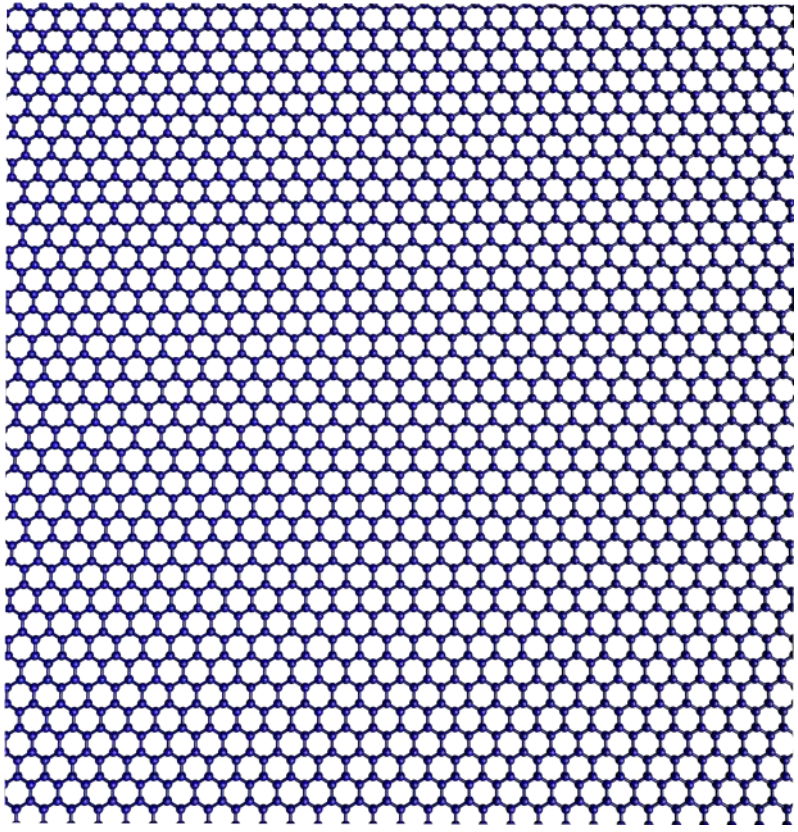
These are unique features of two-dimensional materials

A bilayer van der Waals heterostructure

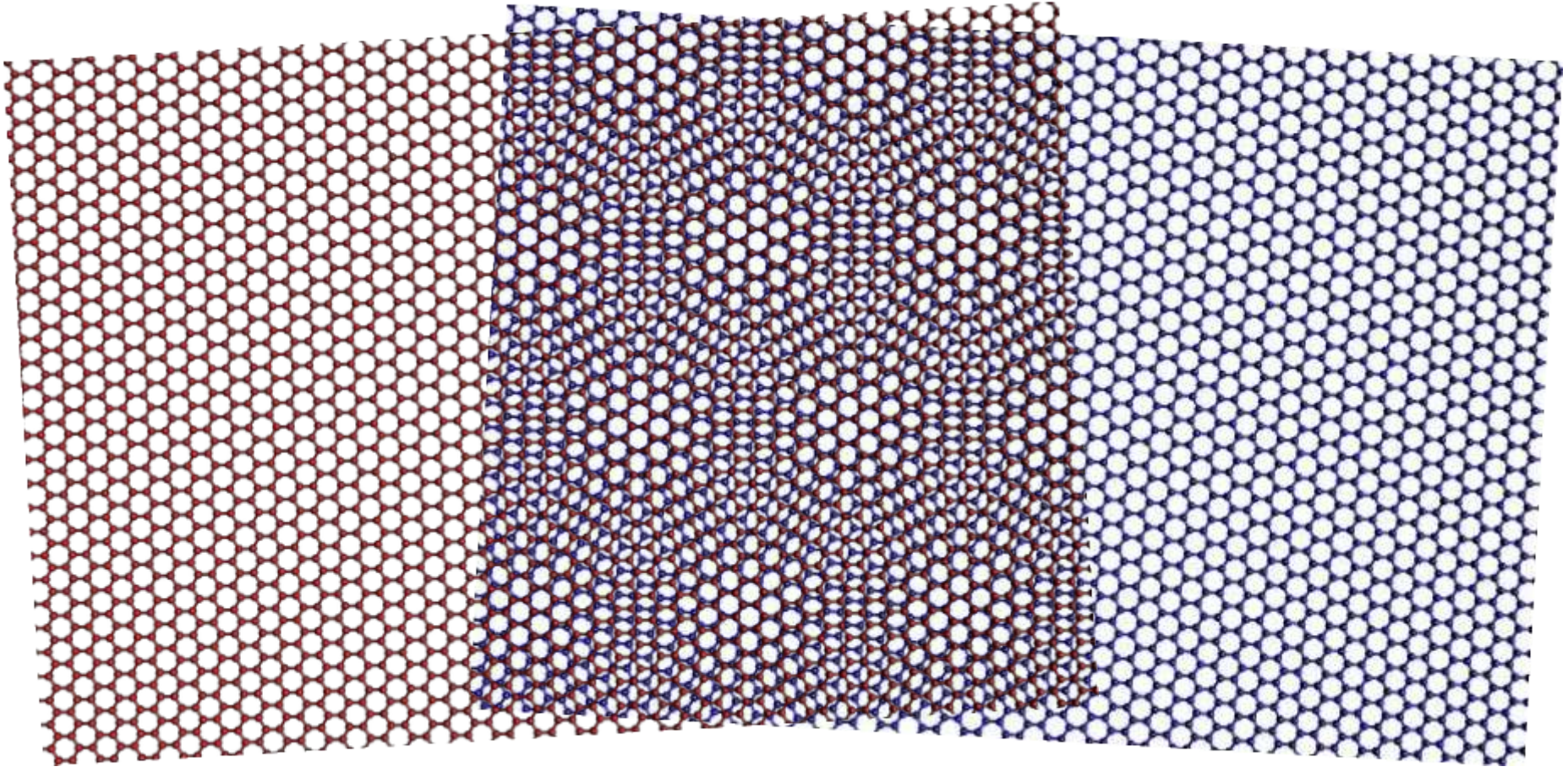
Upper graphene layer



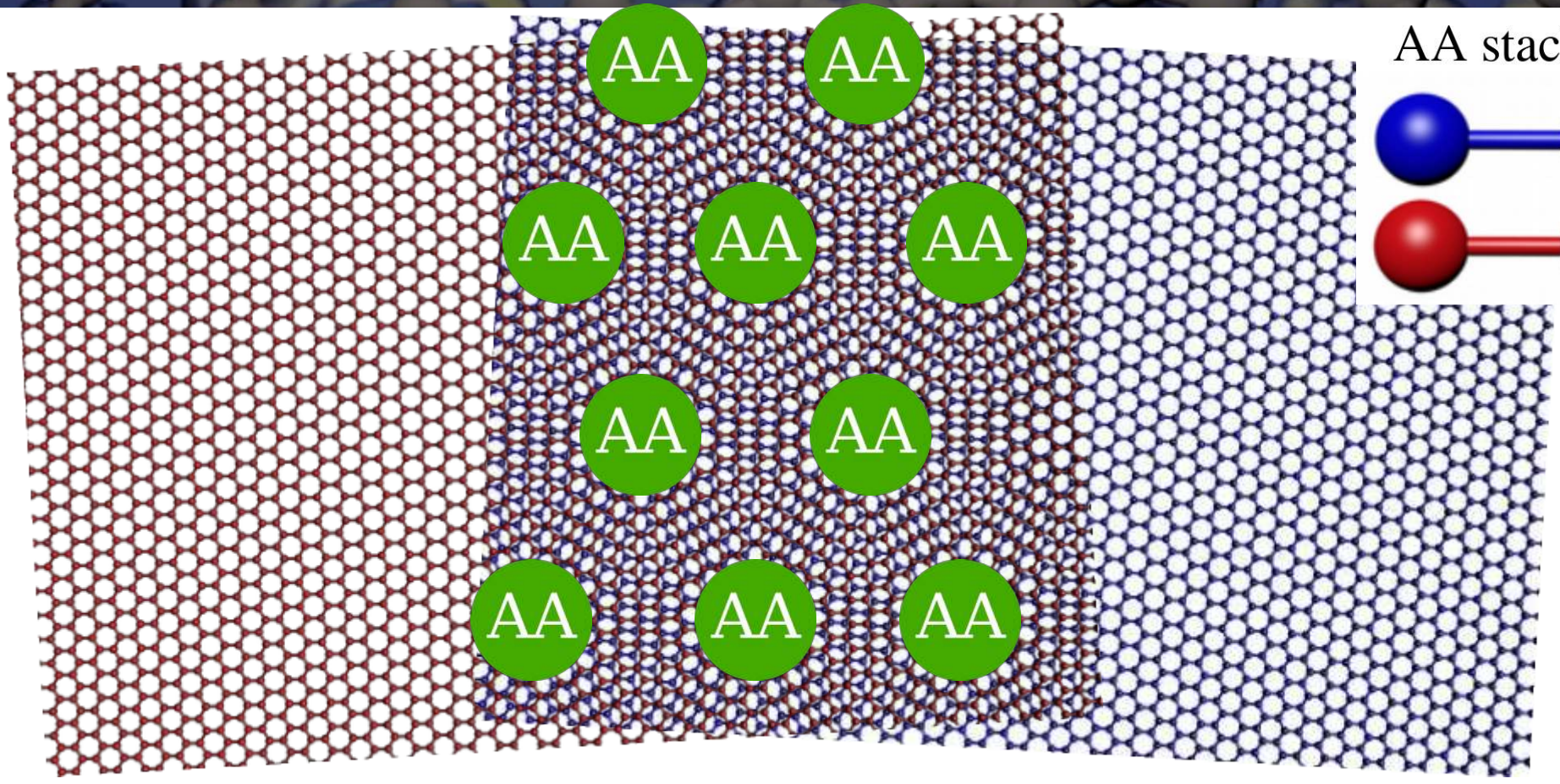
Lower graphene layer



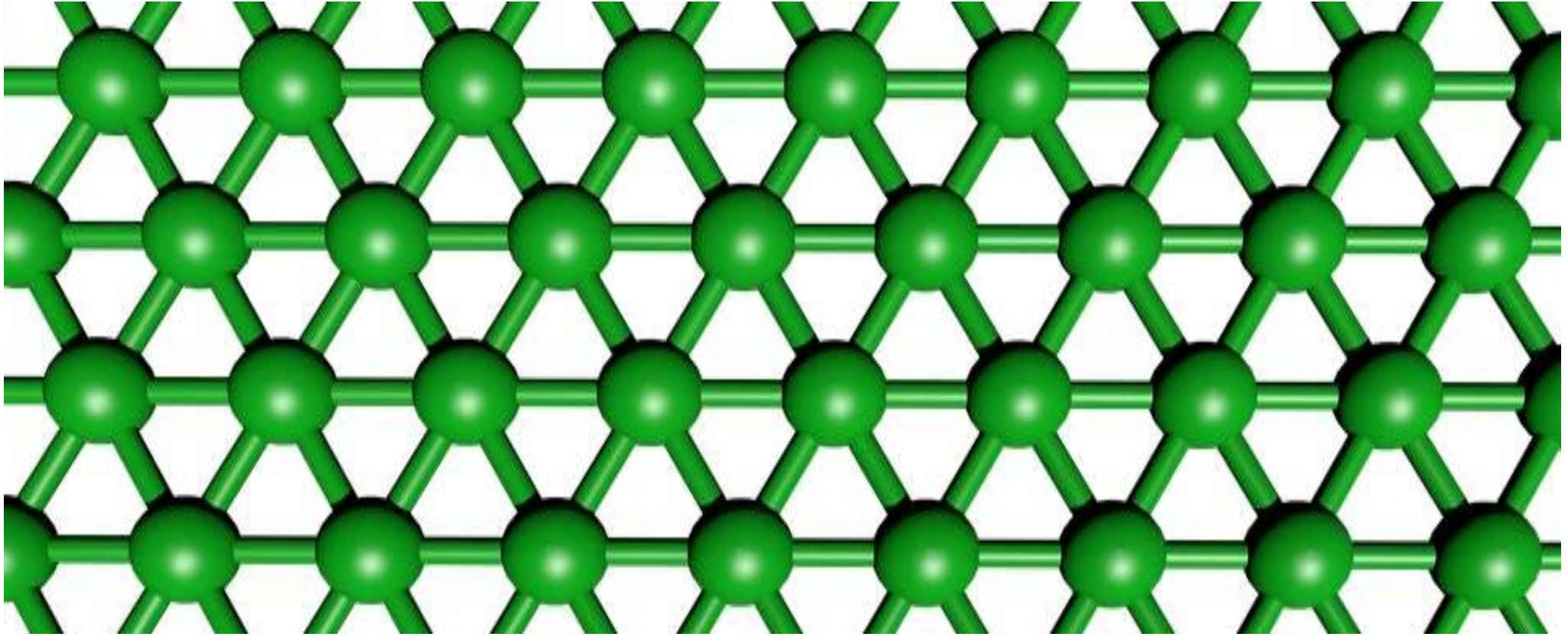
A bilayer van der Waals heterostructure



A bilayer van der Waals heterostructure

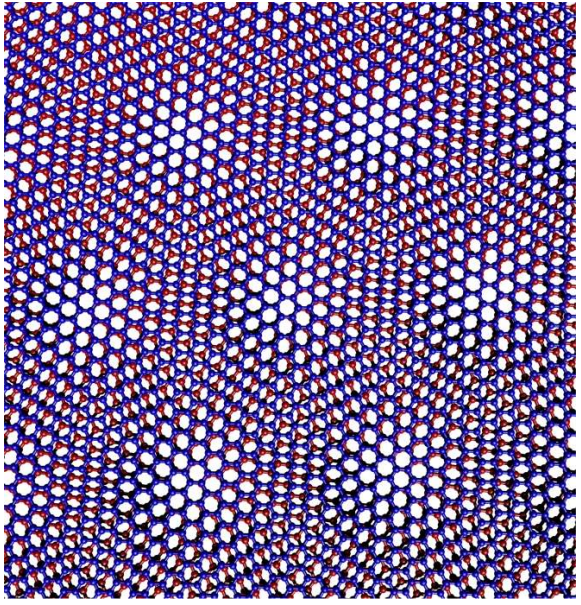


A bilayer van der Waals heterostructure



Electronic states in a single moire superlattice

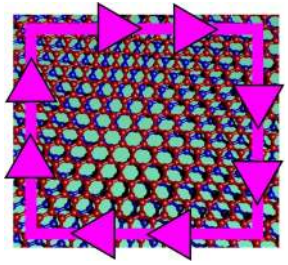
Twisted bilayer graphene



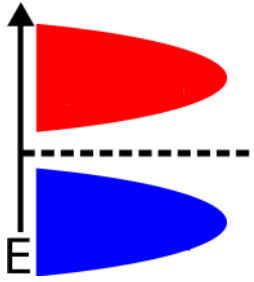
Superconductivity

Topological networks

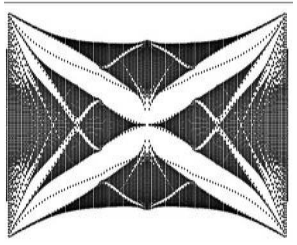
Chern insulators



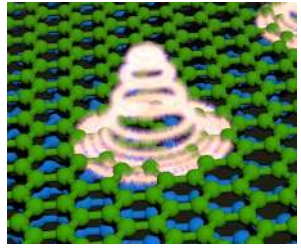
Correlated insulators



Quasicrystalline physics



Fractional Chern insulators

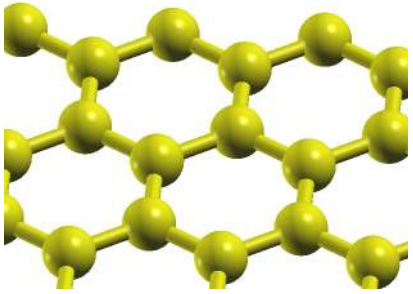


A single twisted van der Waals material realizes a variety of widely different electronic states

The building blocks for twisted van der Waals heterostructure

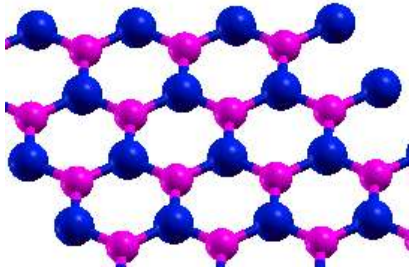
Semimetal

Graphene



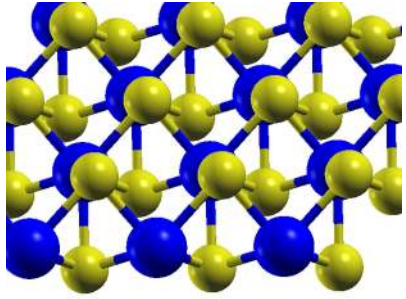
Insulator

BN



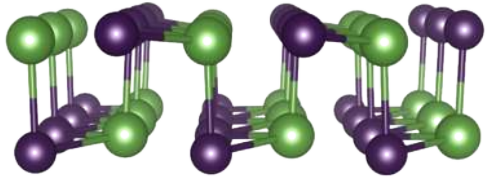
Superconductor

$NbSe_2$



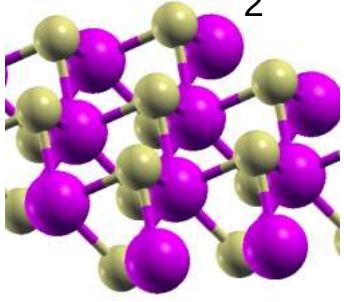
Ferroelectric

SnTe



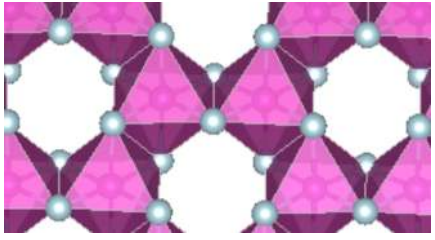
Semiconductor

WSe_2



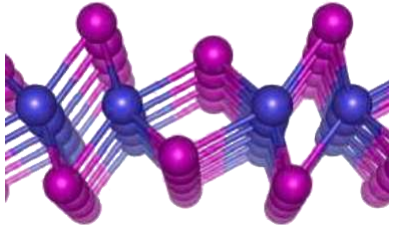
Ferromagnet

CrI_3



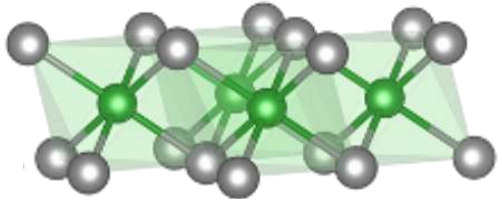
Quantum spin Hall insulator

WTe_2



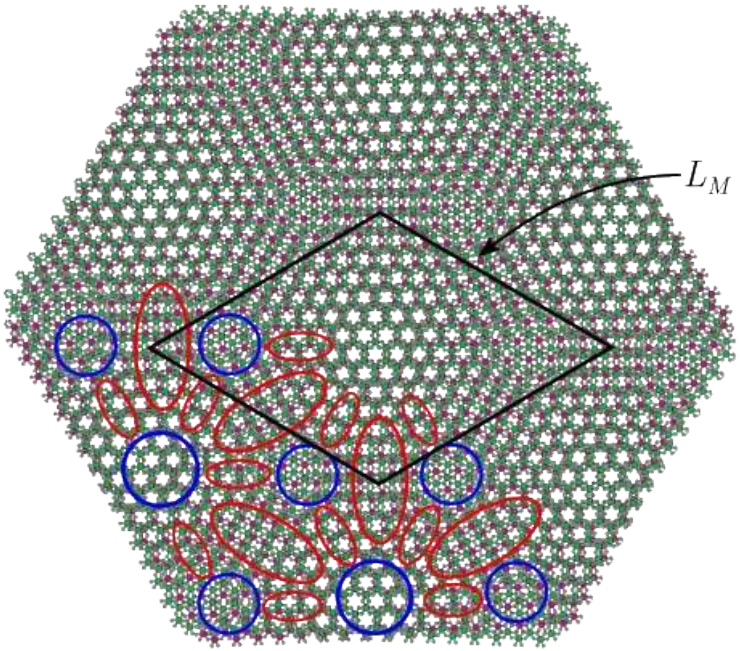
Multiferroic

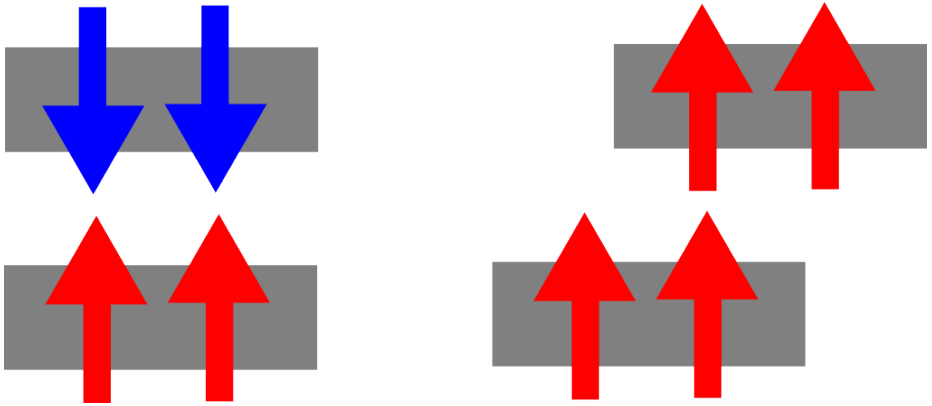
NiI_2



Twisted 2D magnetic materials

$CrCl_3$, $CrBr_3$

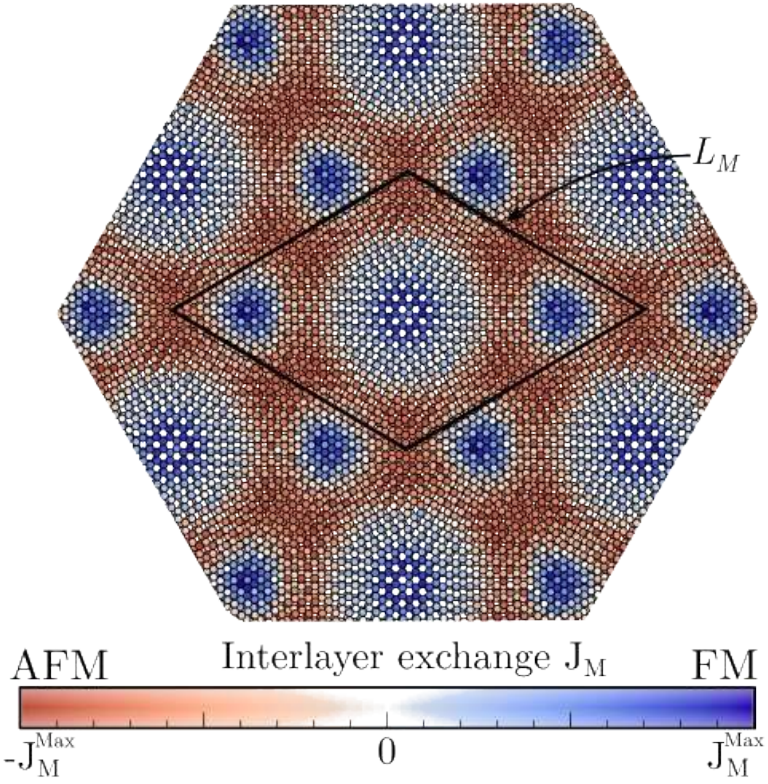


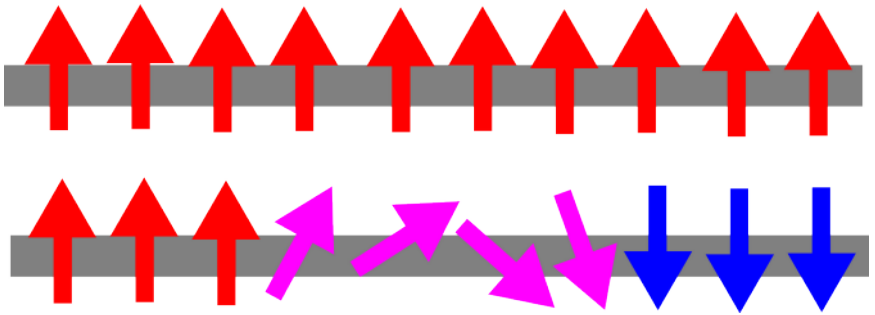


The local stacking determines the coupling between layers

Twisted 2D magnetic materials

Non-collinear magnetism and multiferroic order appear due to the moire





$$\mathbf{P} = \xi \mathbf{q} \times \mathbf{e}$$

Electric polarization

SOC driven

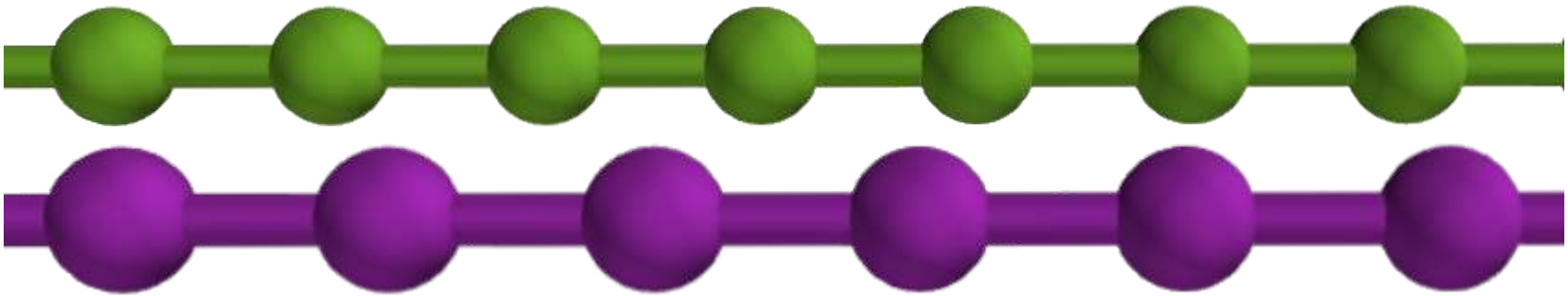
Wavevector of the spin spiral

Spin rotation axis

Superpotentials and quasiperiodicity

A minimal moire potential

Let us now take a one dimensional superlattice



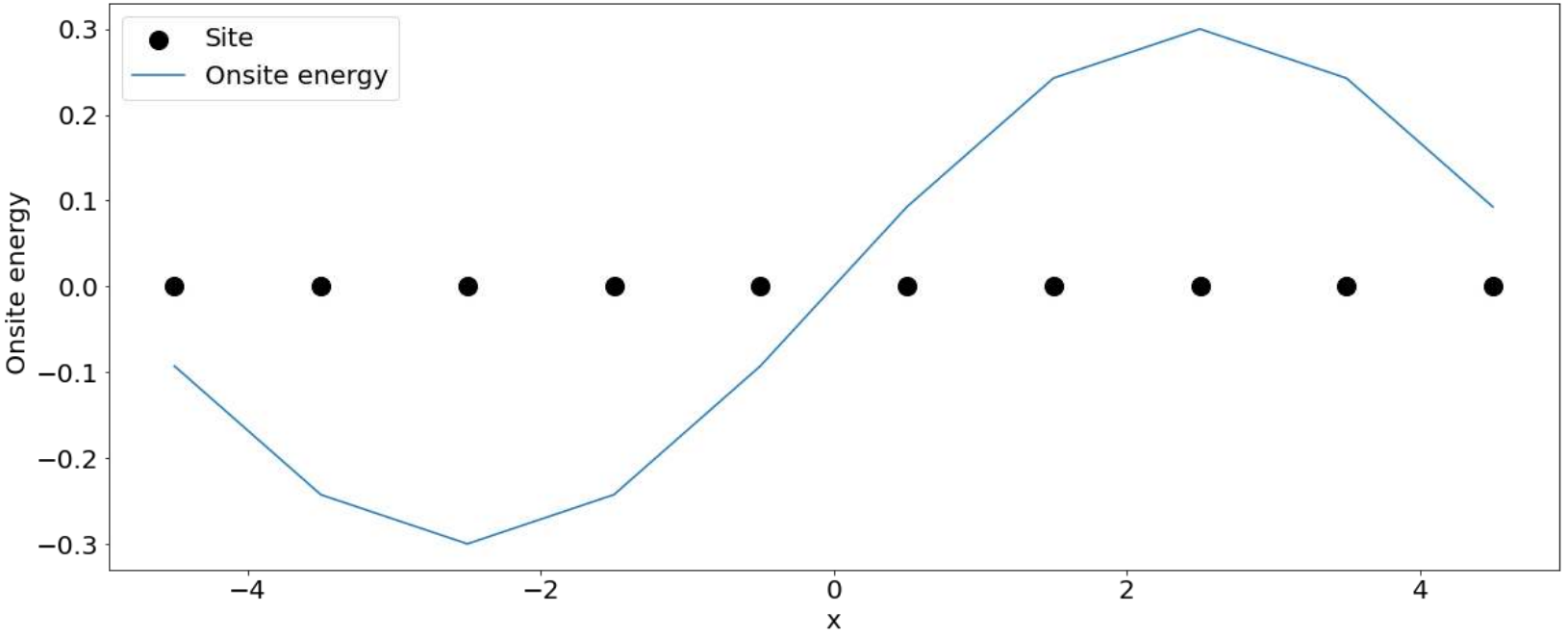
We have now two length scales

The lattice constant of the top system
The lattice constant of the bottom

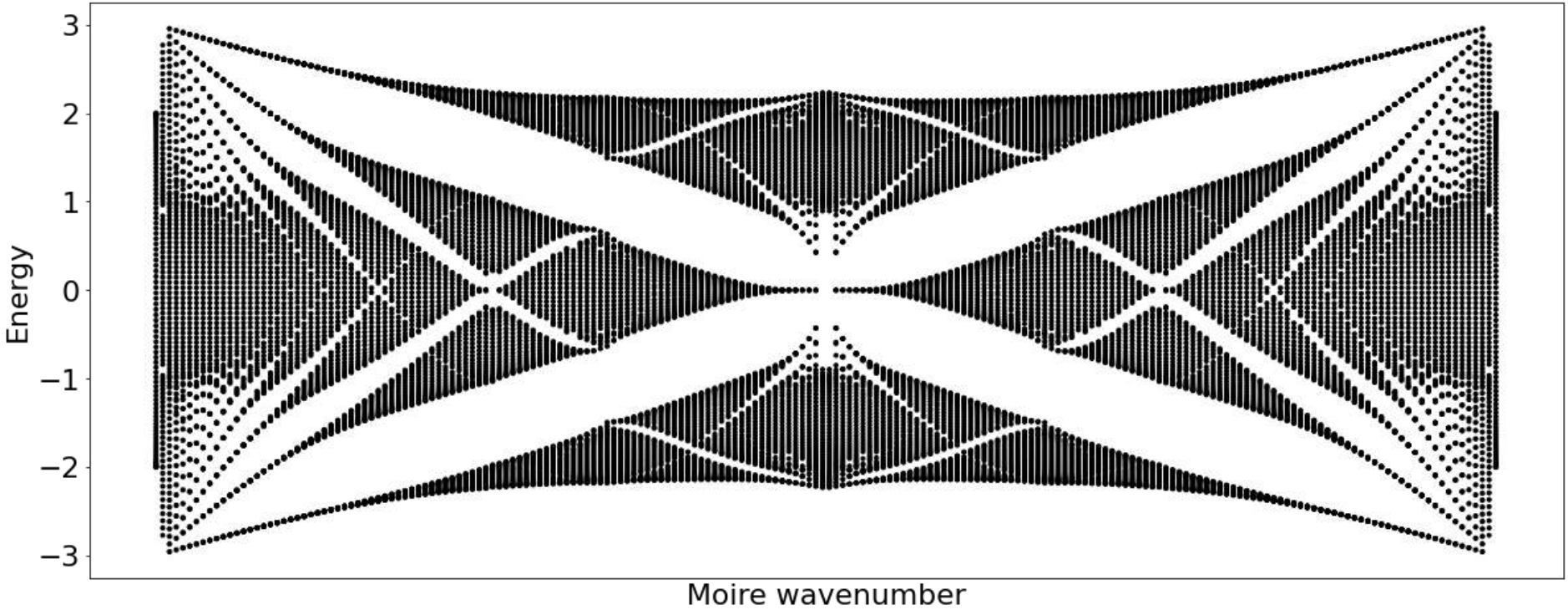
Let us see how the electronic structure gets modified by the superlattice effect

A minimal moire potential

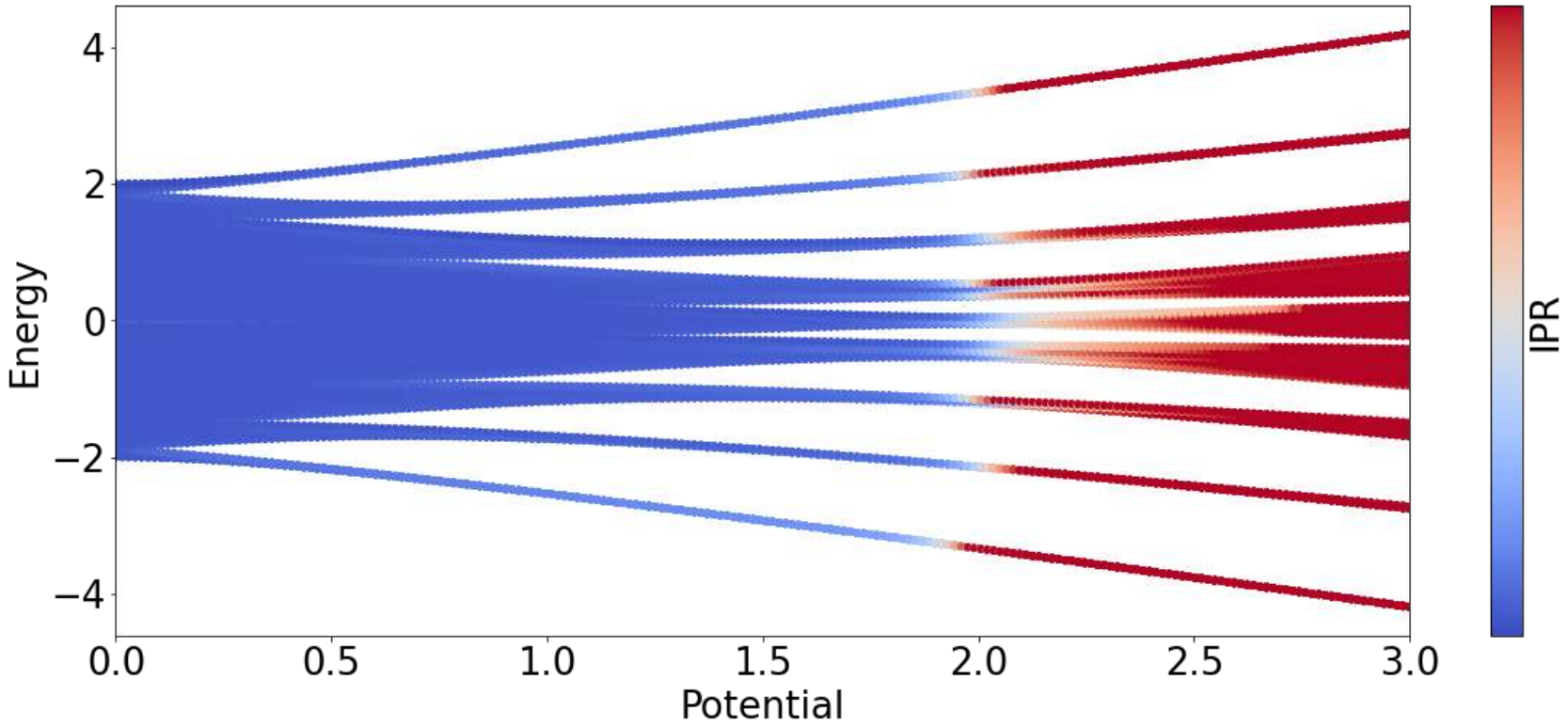
$$H = \sum_n c_n^\dagger c_{n+1} + h.c. + \lambda \sum_n \cos(qn) c_n^\dagger c_n$$



Spectrum as a function of the moire wavevector



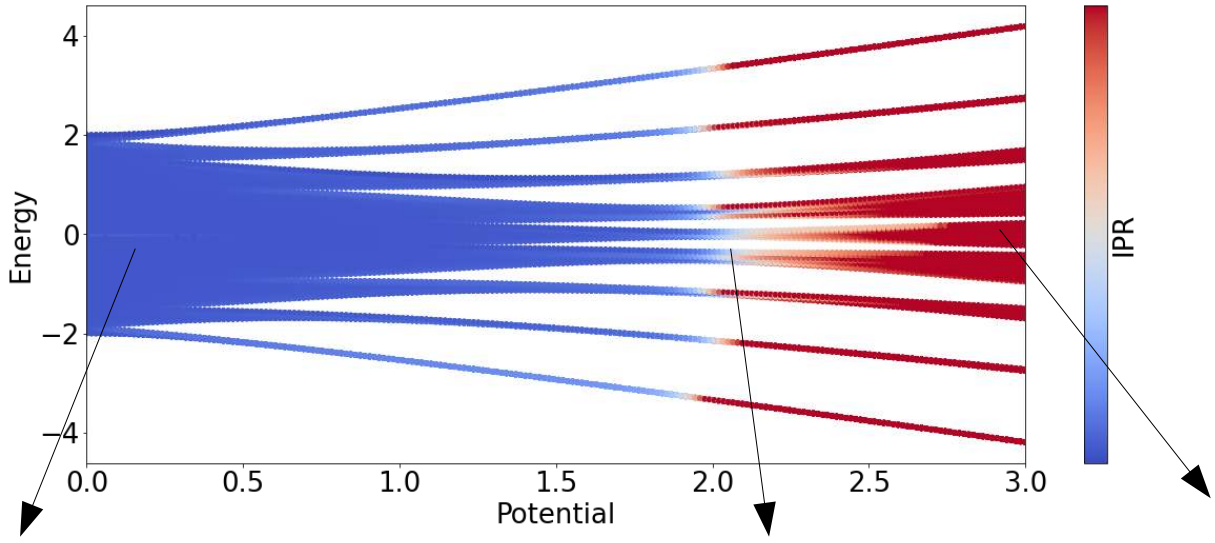
Superpotentials and criticality



Moire potentials can give rise to critical wavefunctions

$$IPR = \sum_r |\Psi(r)|^4$$

Superpotentials and criticality



$$IPR = \sum_r |\Psi(r)|^4$$

Extended states

$$|\Psi(\mathbf{r})| = 1/N$$

Critical states

$$|\Psi(\mathbf{r})| = |r|^{-\alpha}$$

Localized states

$$|\Psi(\mathbf{r})| = e^{-\lambda|r|}$$

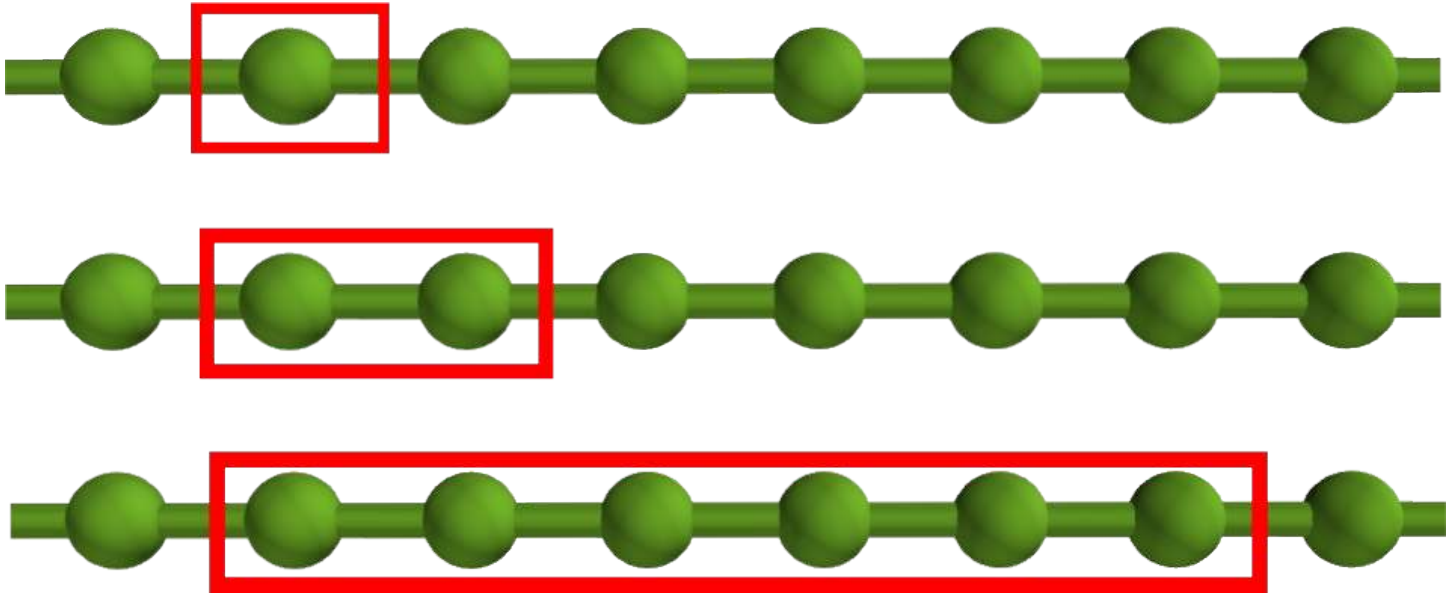
Minibands and band structure unfolding

Supercells and band folding

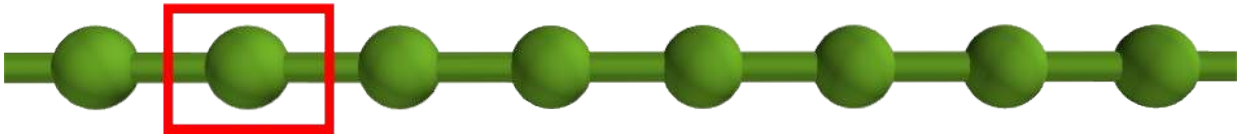
Let us take a 1D chain

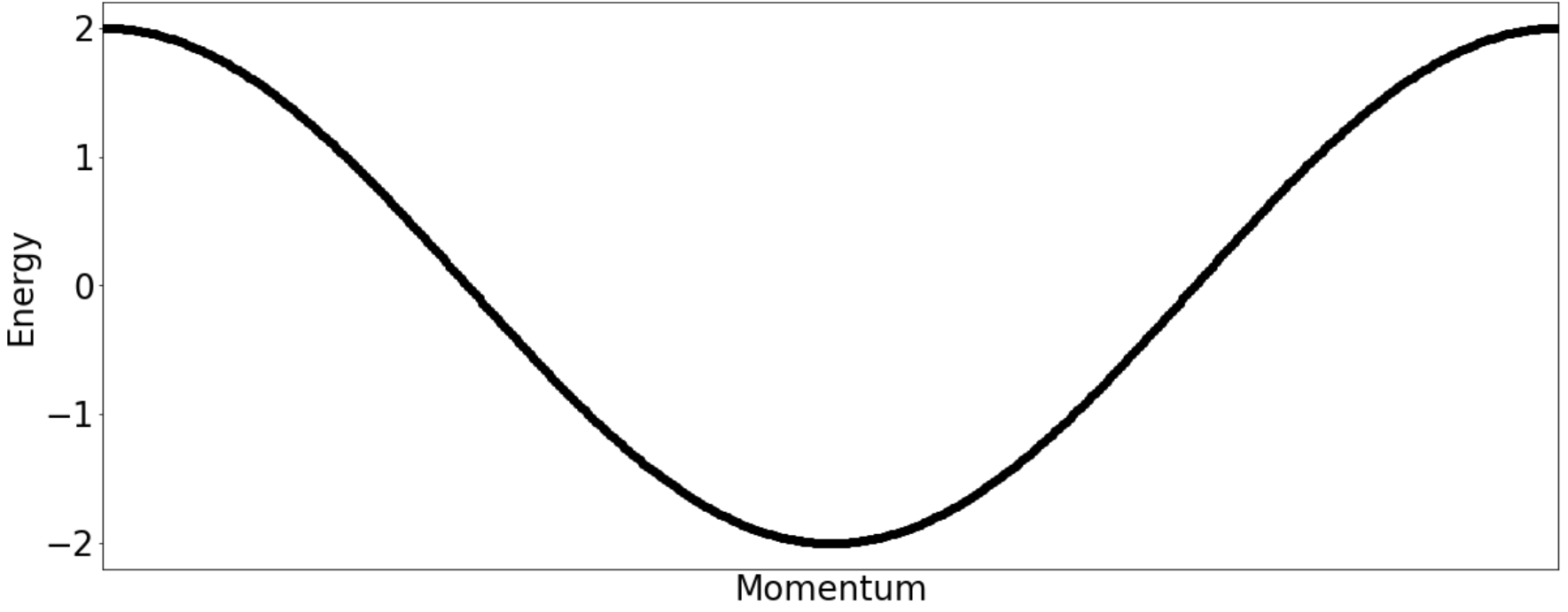
$$H = \sum_n c_n^\dagger c_{n+1} + h.c.$$

Let us see how the electronic structure changes with the unit cell

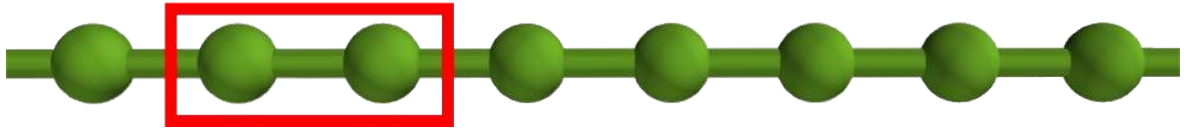


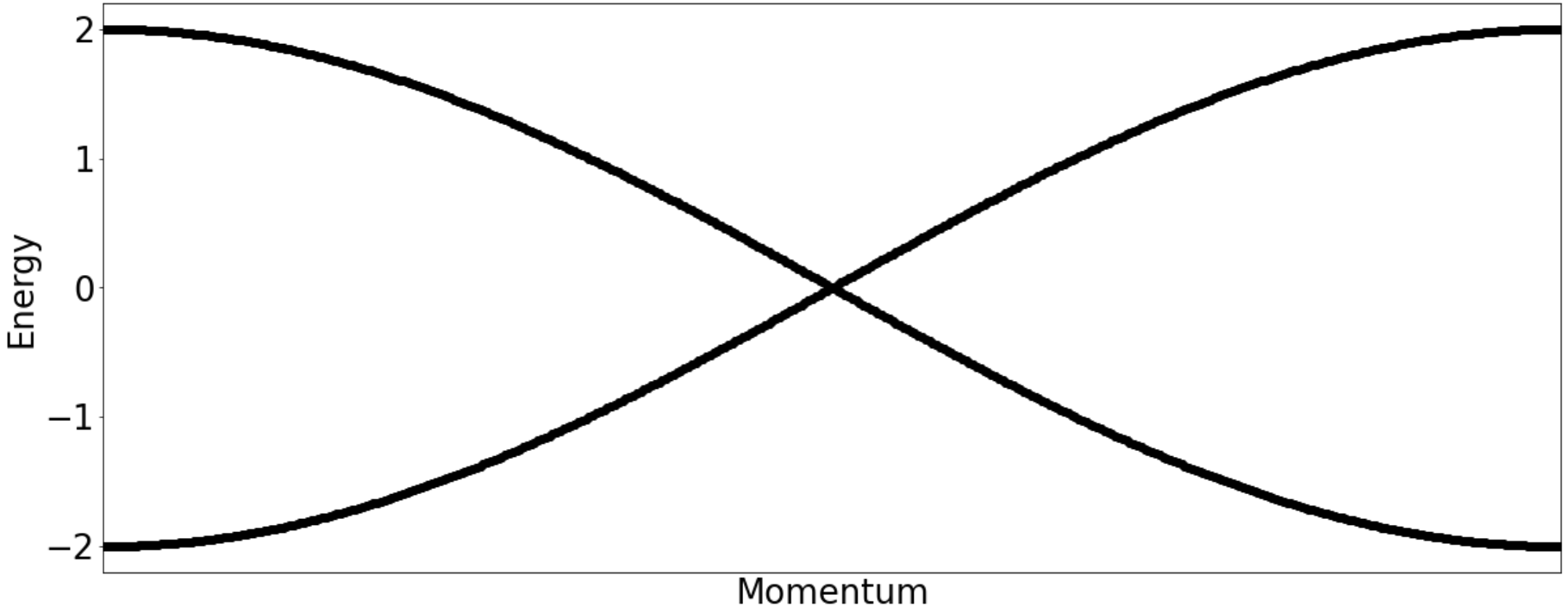
Supercells and band folding



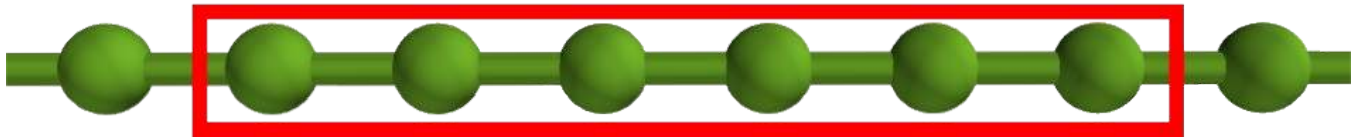


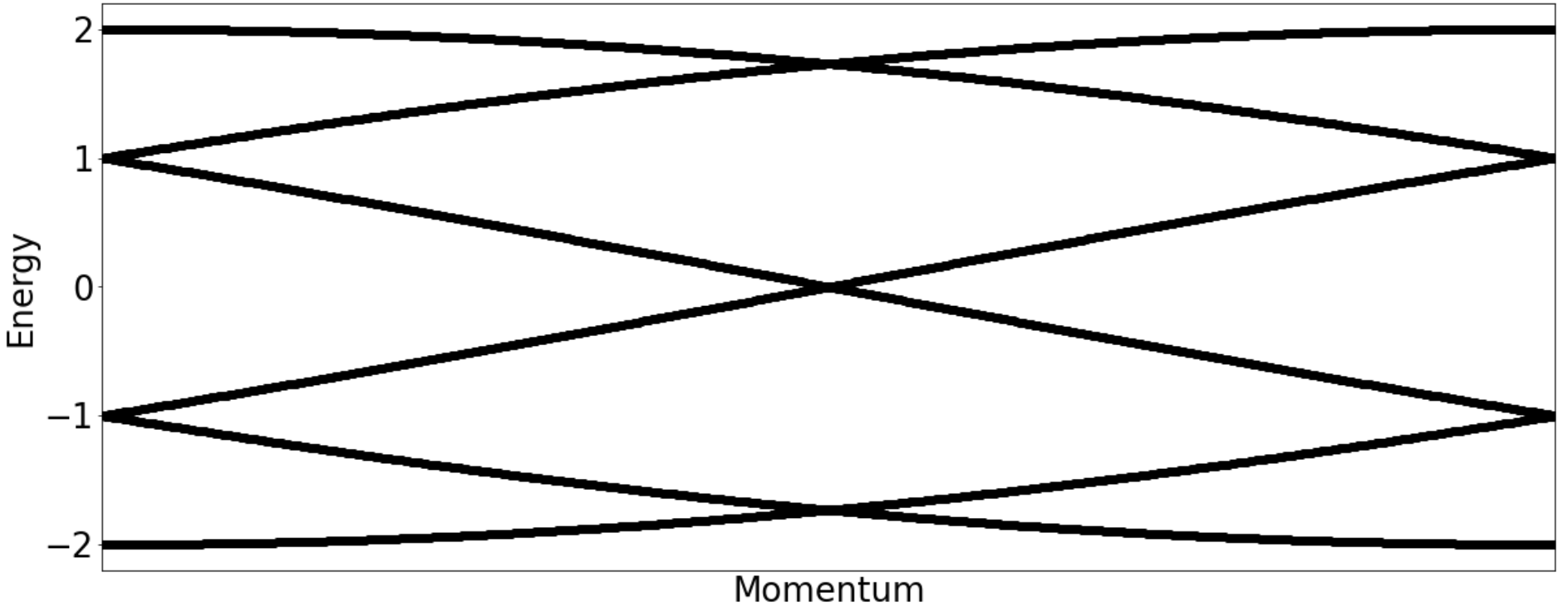
Supercells and band folding



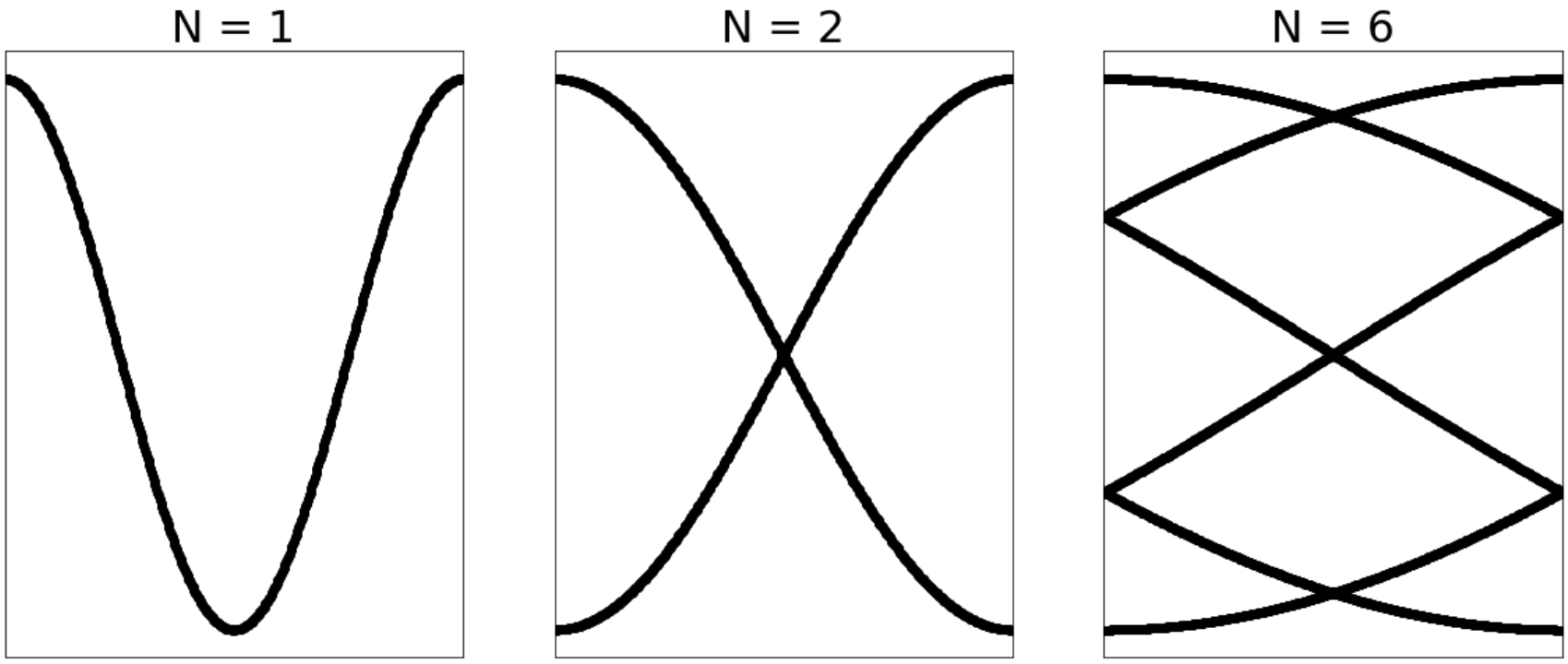


Supercells and band folding



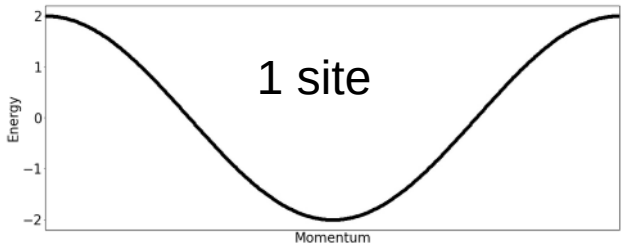


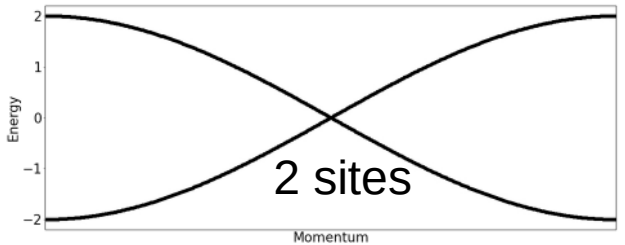
Supercells and band folding

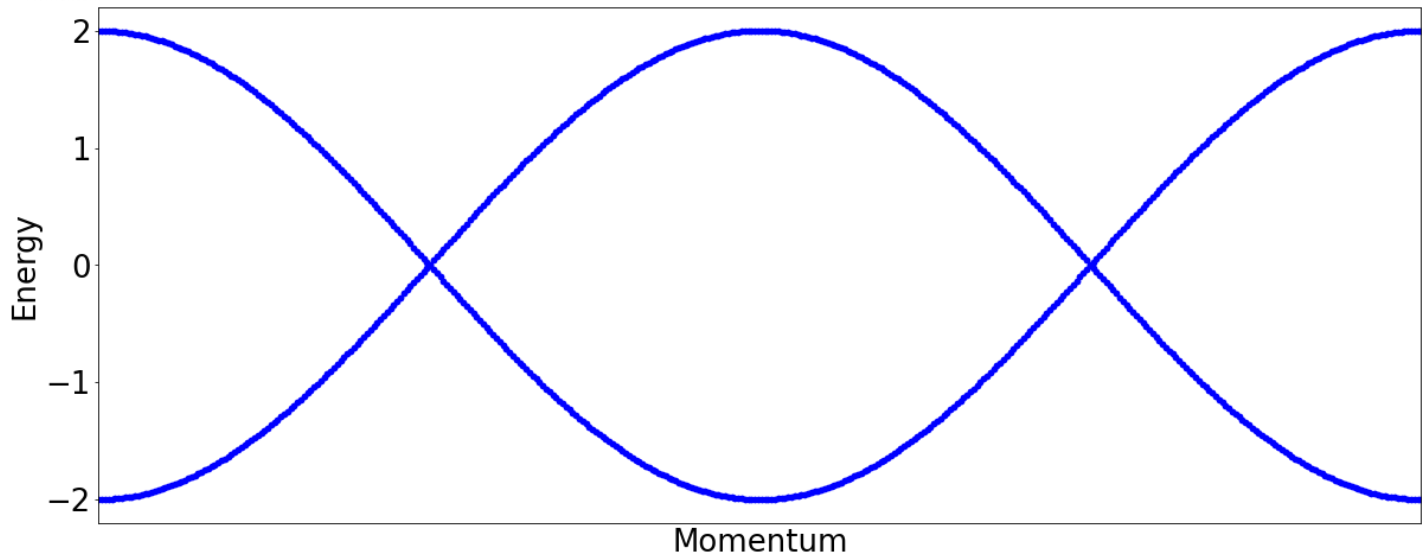


All these electronic structures represent the same physical system, but how do we see that?

Supercells and band folding

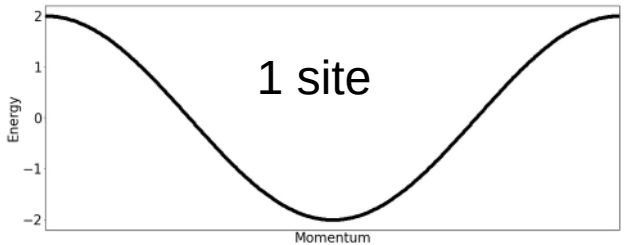


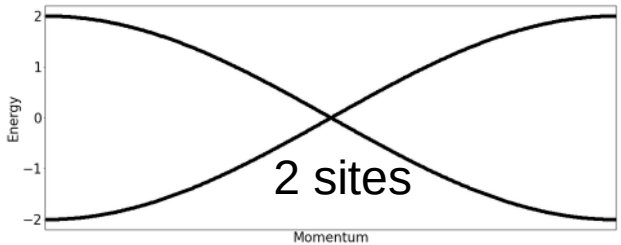


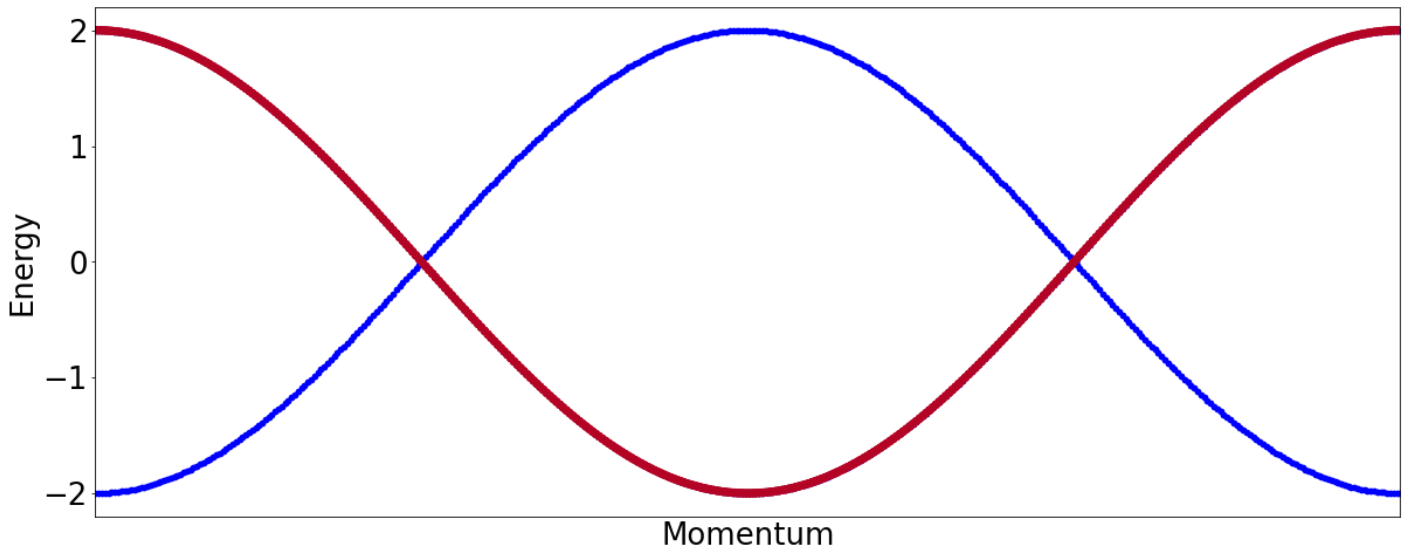


Repeating the electronic structure recovers the original electronic dispersion

Supercells and band folding

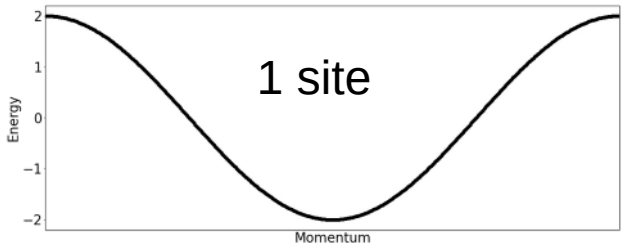


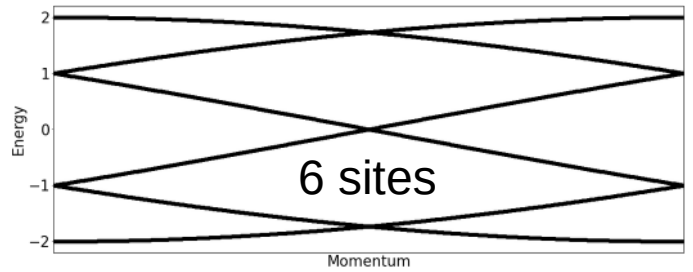


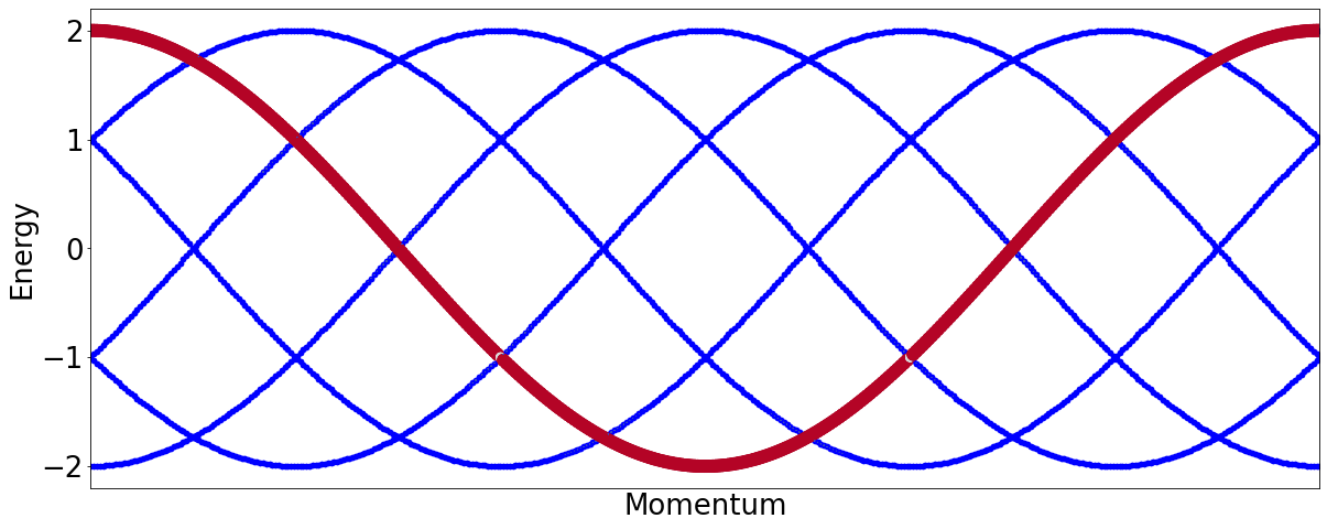


Repeating the electronic structure recovers the original electronic dispersion

Supercells and band folding



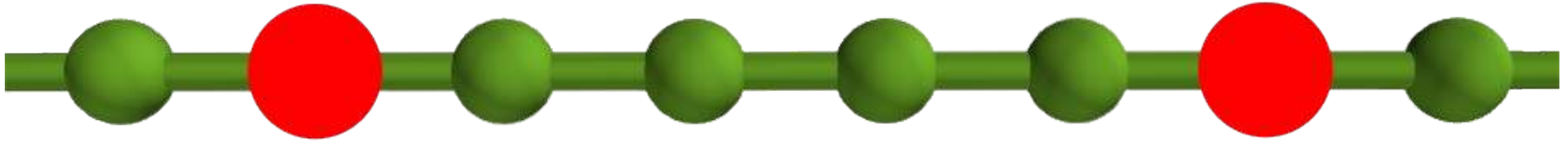




Repeating the electronic structure recovers the original electronic dispersion

Unfolding and anticrossings in superlattices

Let us now put an impurity every 6 sites (once in a supercell 6)

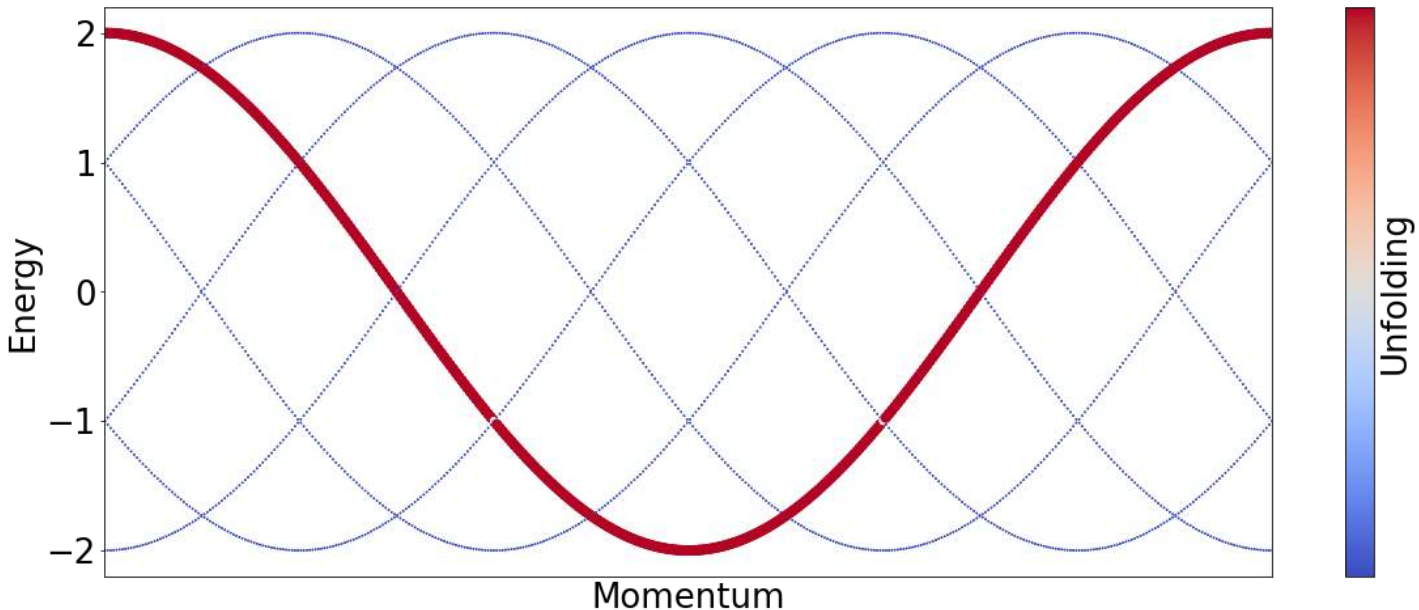


$$H = \sum_n c_n^\dagger c_{n+1} + h.c. + V_0 \sum_\alpha c_n^\dagger c_n \qquad \alpha \equiv 0 \pmod 6$$

Unfolding and anticrossings in superlattices

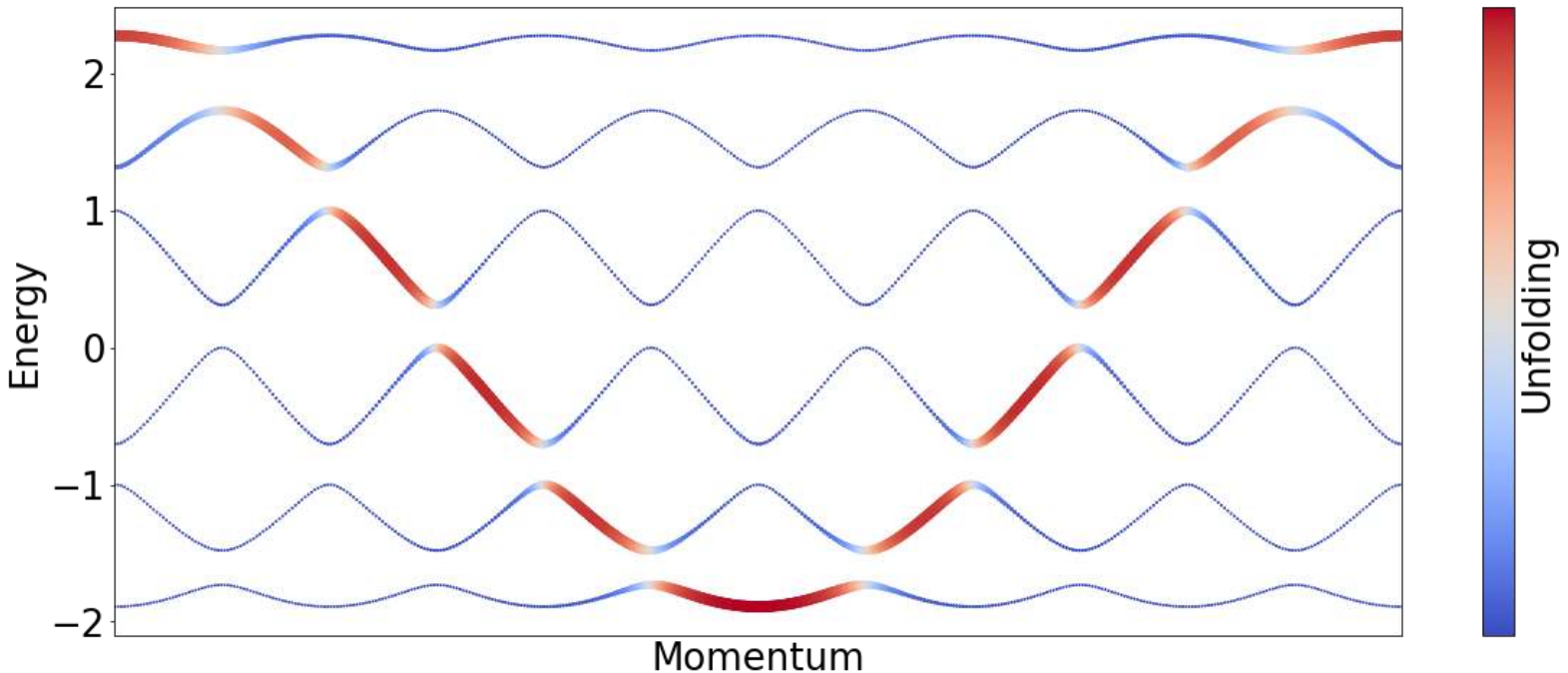
$$H = \sum_n c_n^\dagger c_{n+1} + h.c. + V_0 \sum_\alpha c_n^\dagger c_n$$

$$V_0 = 0$$



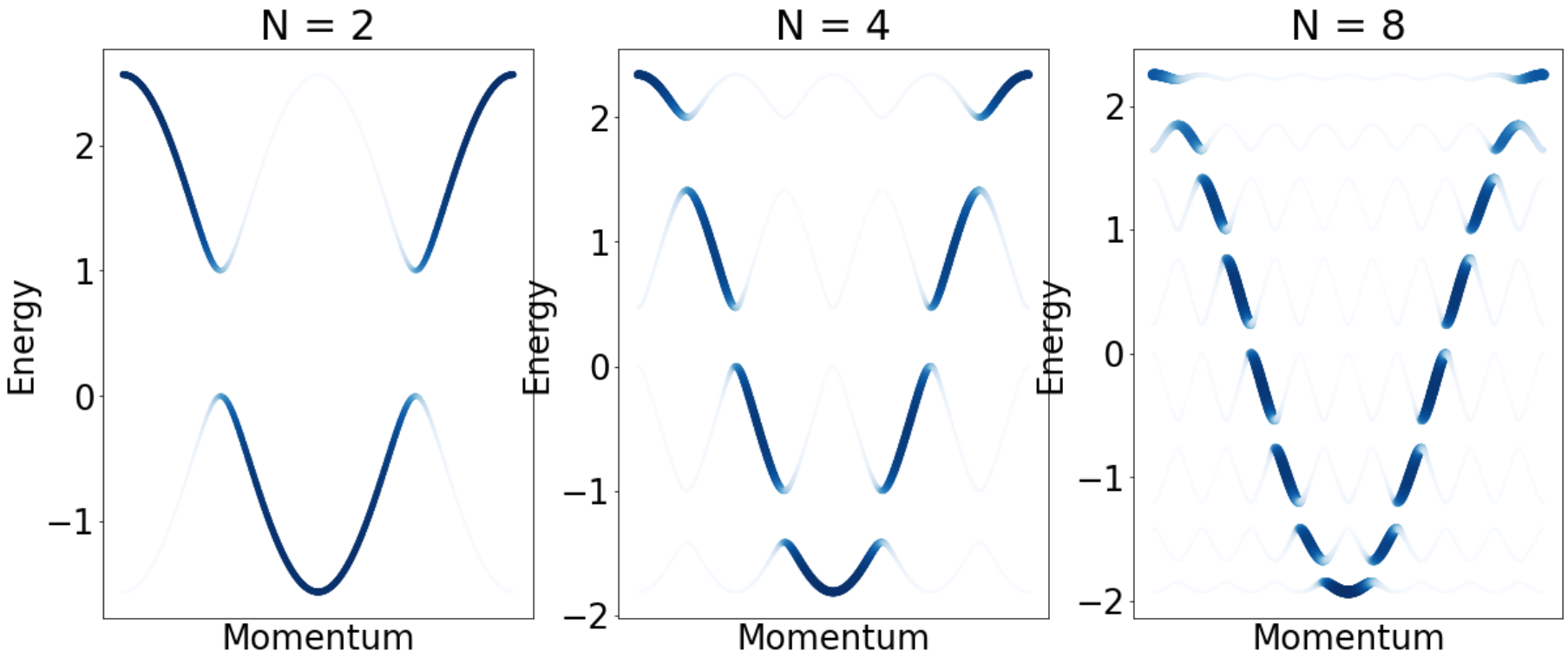
Electronic structure unfolding

$$H = \sum_n c_n^\dagger c_{n+1} + h.c. + V_0 \sum_\alpha c_n^\dagger c_n \qquad V_0 \neq 0$$



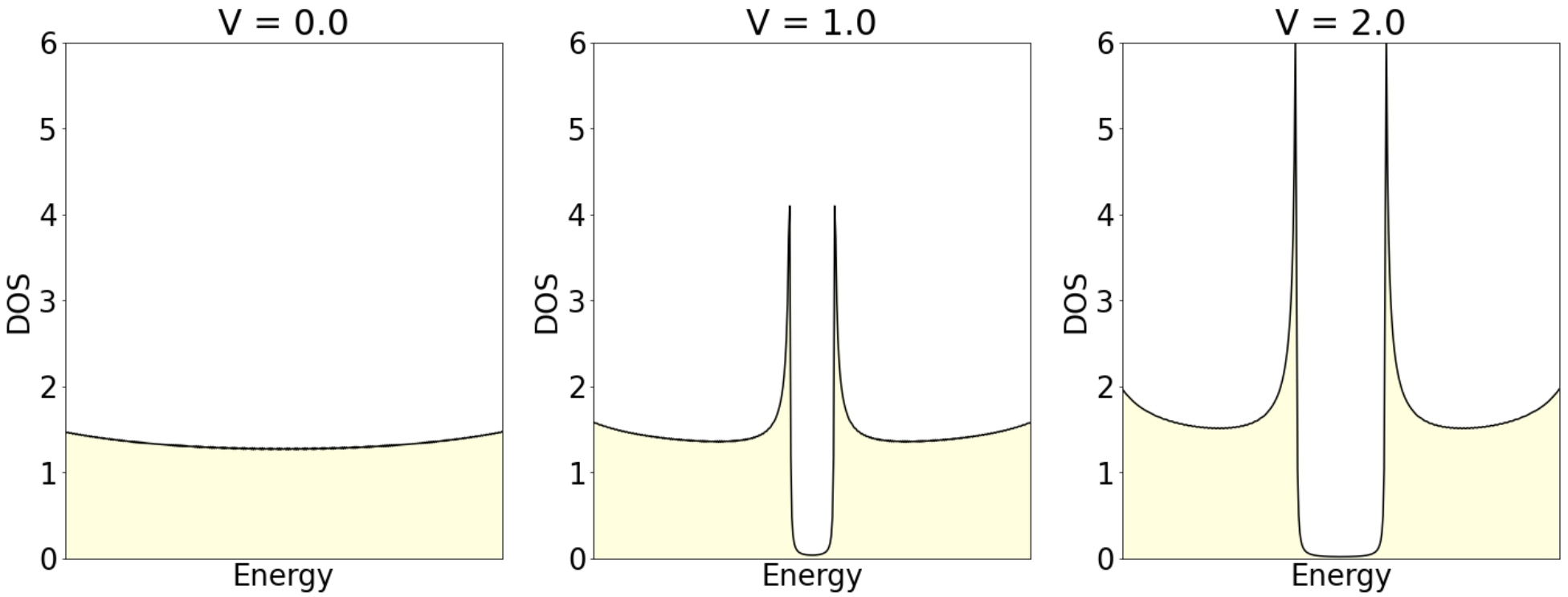
Anticrossing between the bands appear due to the superlattice potential

Electronic structure unfolding



As the periodicity of the superlattice is increased, more minibands appear

Moire electronic structure



As the strength of the miore potential increases, the density of states gets enhanced

Break

10-15 min break

(optional) to discuss during the break

$$H = \lambda \sum_n \cos(qn) c_n^\dagger c_n$$

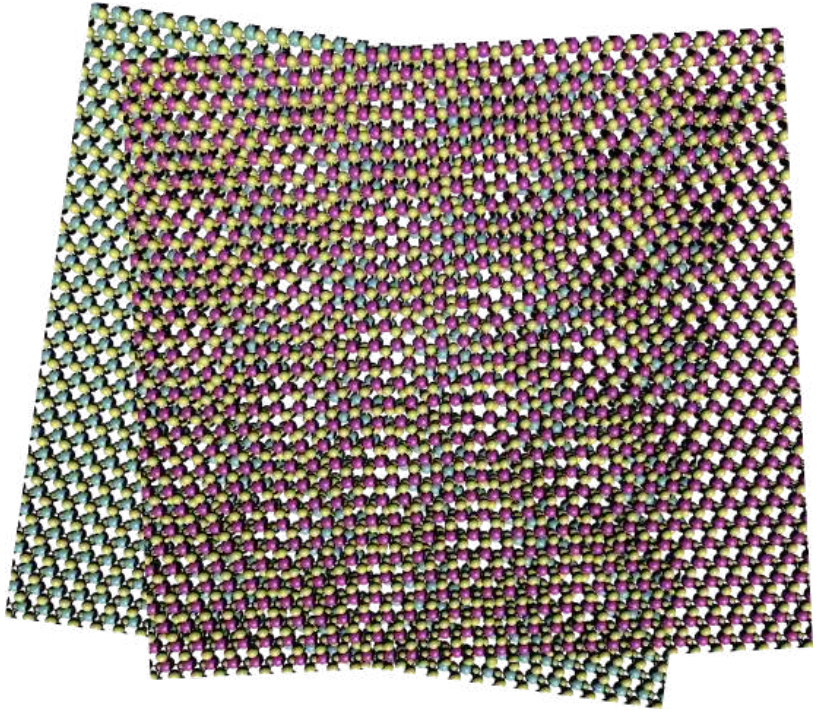
For a lattice with L sites, what is the value of q that makes the potential commensurate?

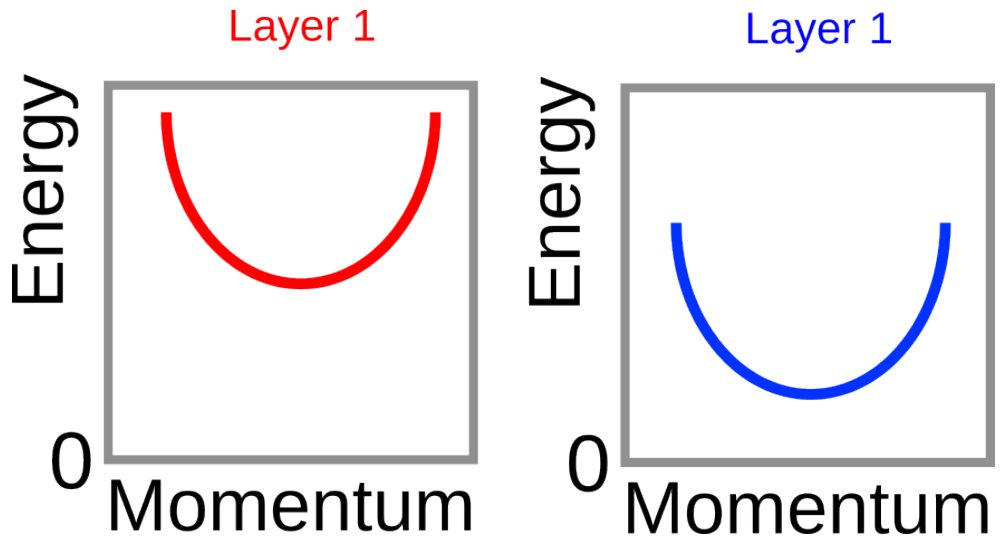
$$q = \frac{\alpha 2\pi}{L} \qquad q = \frac{\alpha \pi}{L}$$

$$\alpha = 1, 2, 3, 4, ...$$

Moire in twisted TMDC

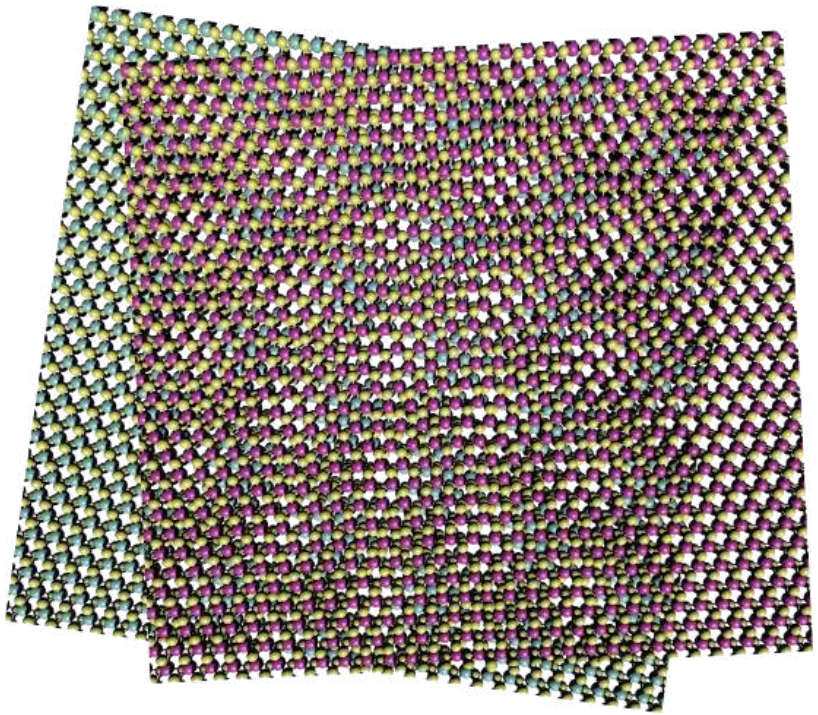
In twisted TMDC heterobilayers, the moire modulates the band off set of one layer



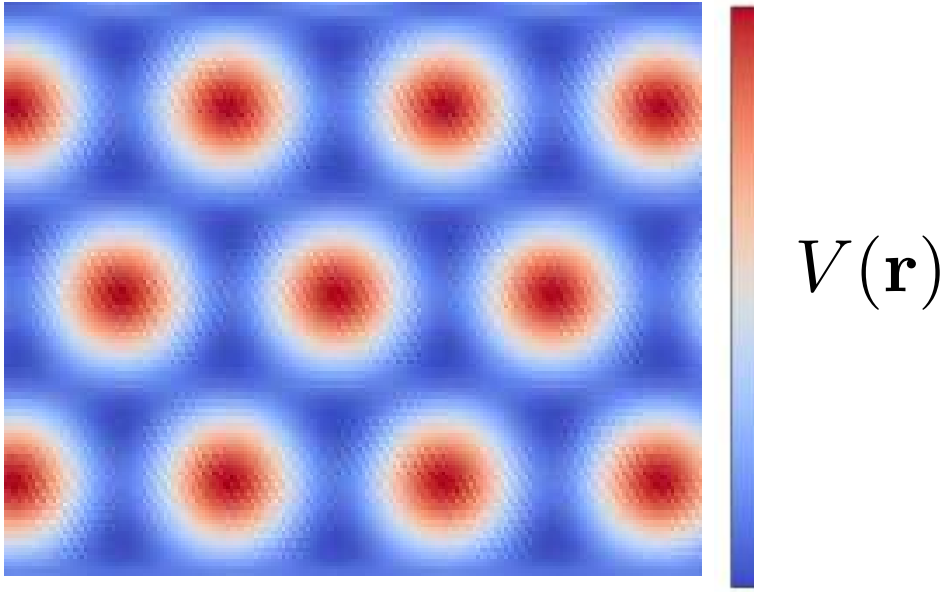


Moire in twisted TMDC

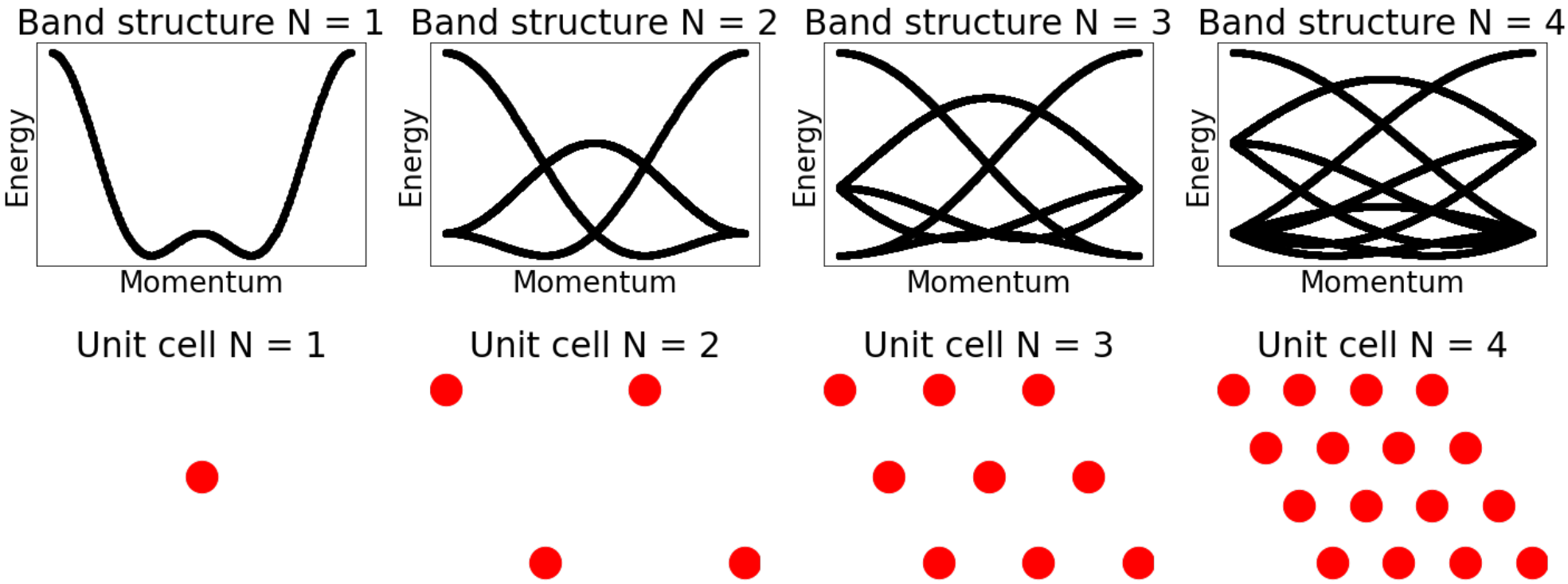
In twisted TMDC heterobilayers, the moire modulates the band off set of one layer



$$H = \sum_{ij} c_i^\dagger c_j + h.c. + \sum_n V(\mathbf{r}_n) c_n^\dagger c_n$$



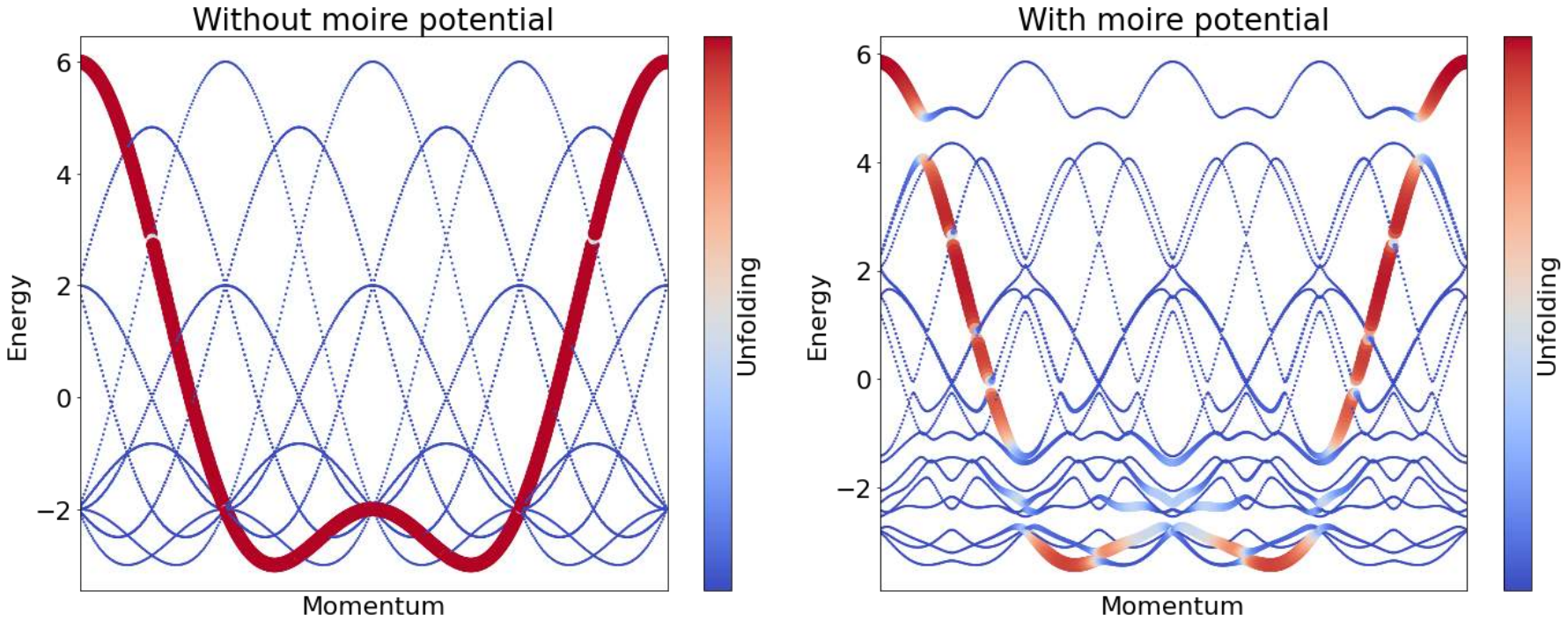
Band structure folding in 2D superlattices



A 2D superlattice gives rise to a complex folding of the electronic structure

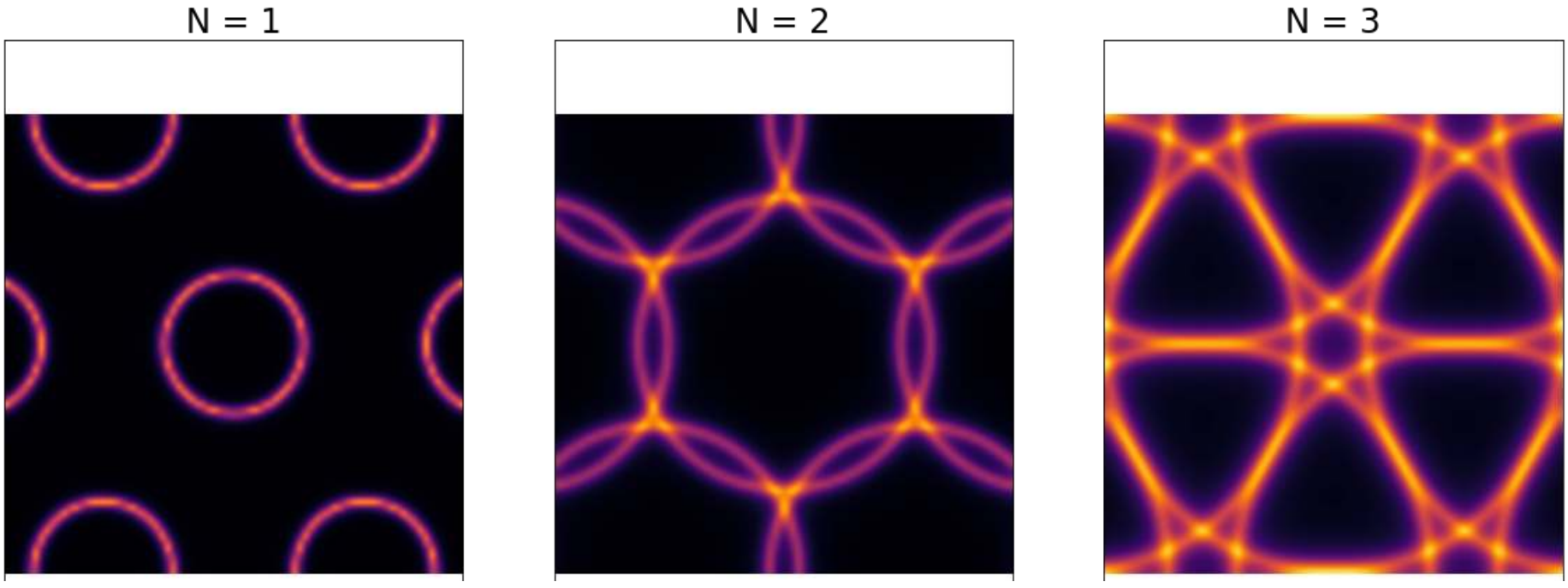
Band structure folding in 2D superlattices

Mini-bands appear due to the moire in one of the layers



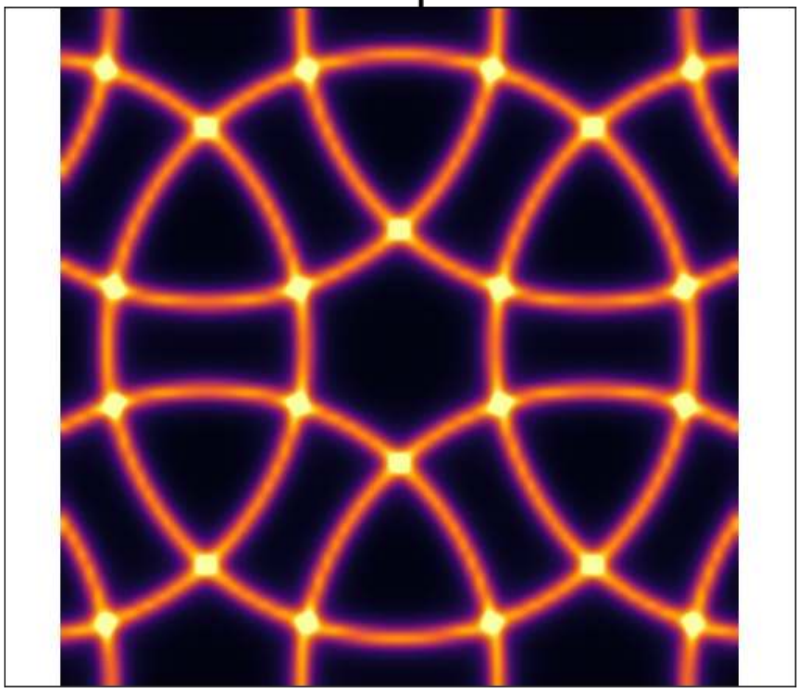
Fermi surface folding in superlattices

The Fermi surface in 2d supercell gets folder, turning one Fermi surface into many

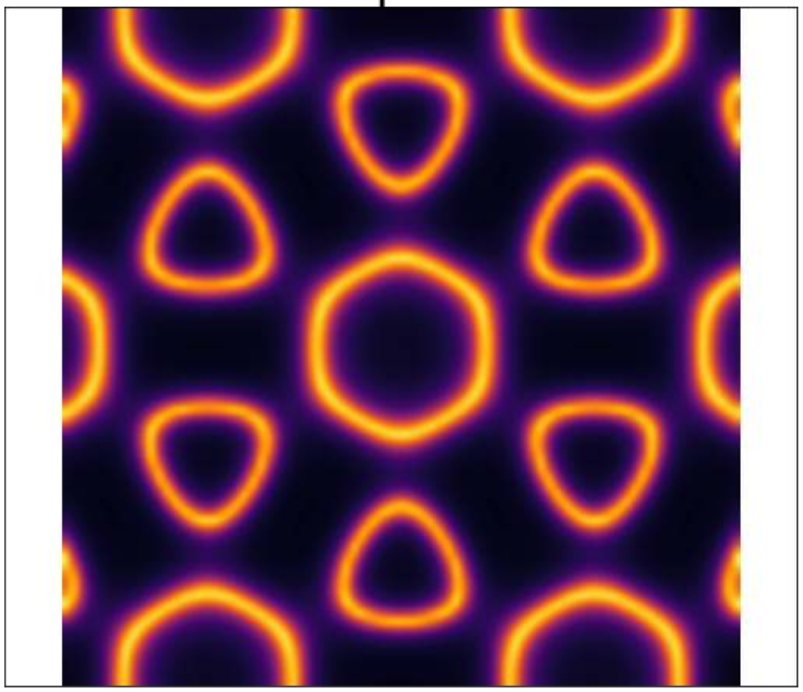


Fermi surface folding in superlattices

Without superlattice



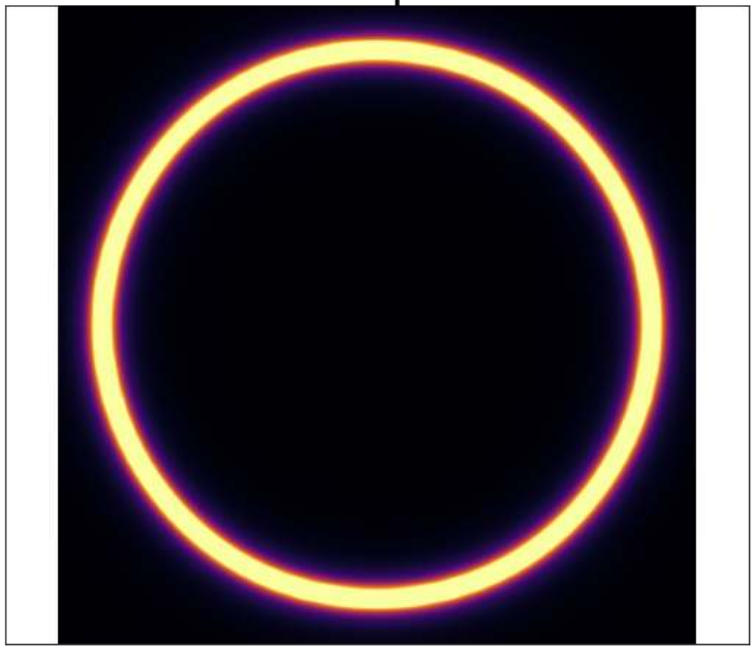
With superlattice



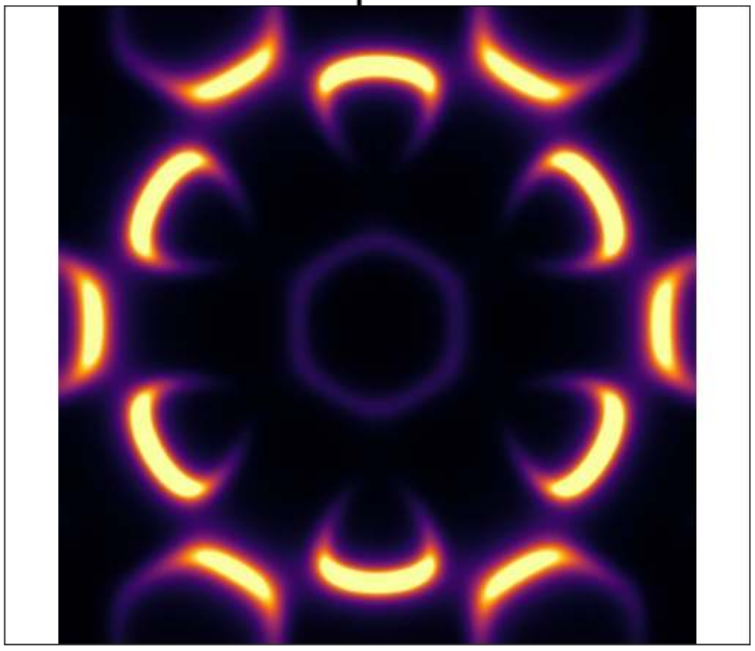
The superlattice changes the Fermi surface topology on the underlying 2D material

Fermi surface unfolding in superlattices

Without superlattice



With superlattice

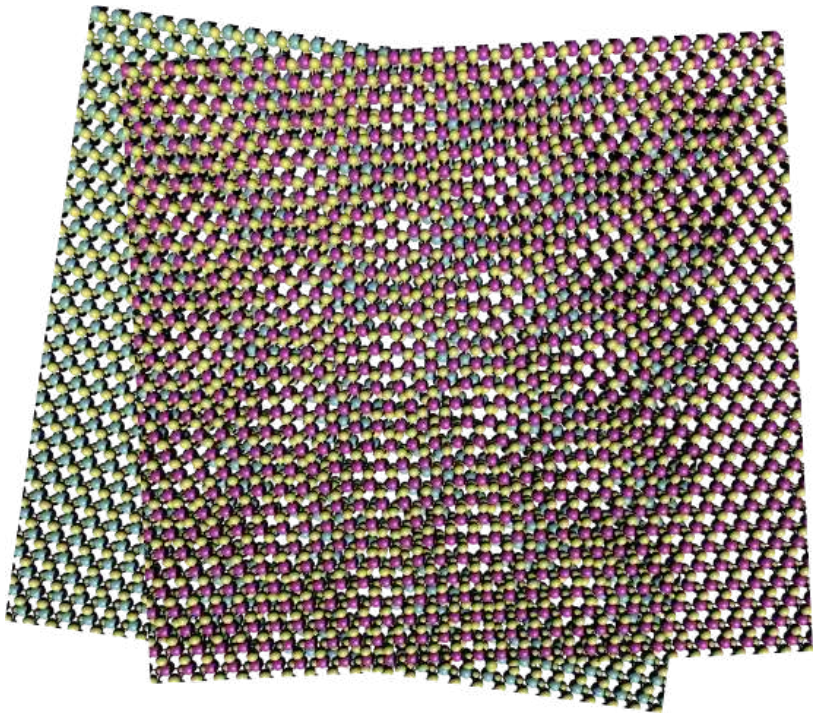


Superlattices fragment the original Fermi surface when unfolded to the original unit cell

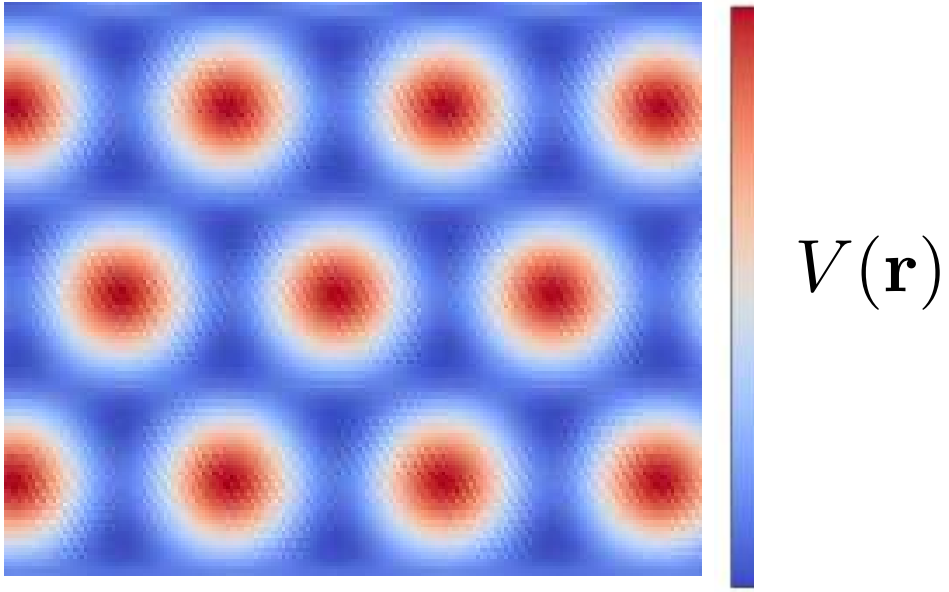
Moire-driven correlated states

Moire in twisted TMDC

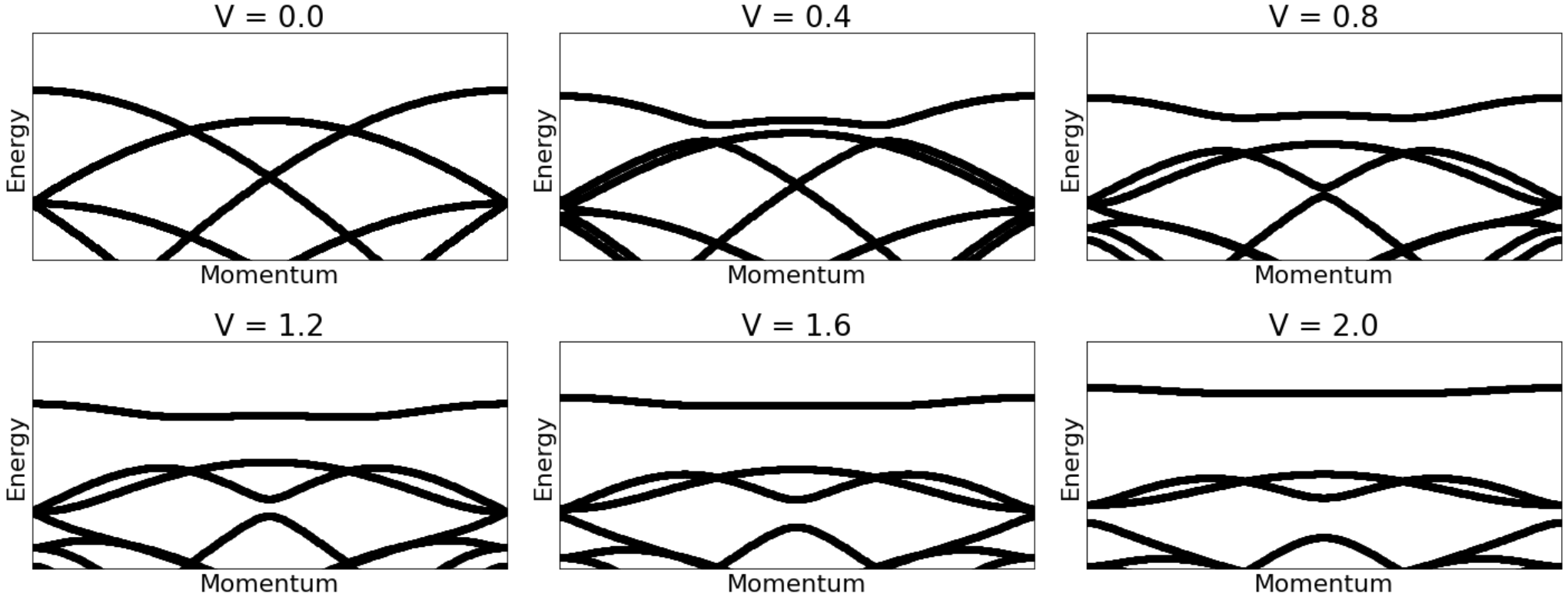
In twisted TMDC heterobilayers, the moire modulates the band off set of one layer



$$H = \sum_{ij} c_i^\dagger c_j + h.c. + \sum_n V(\mathbf{r}_n) c_n^\dagger c_n$$

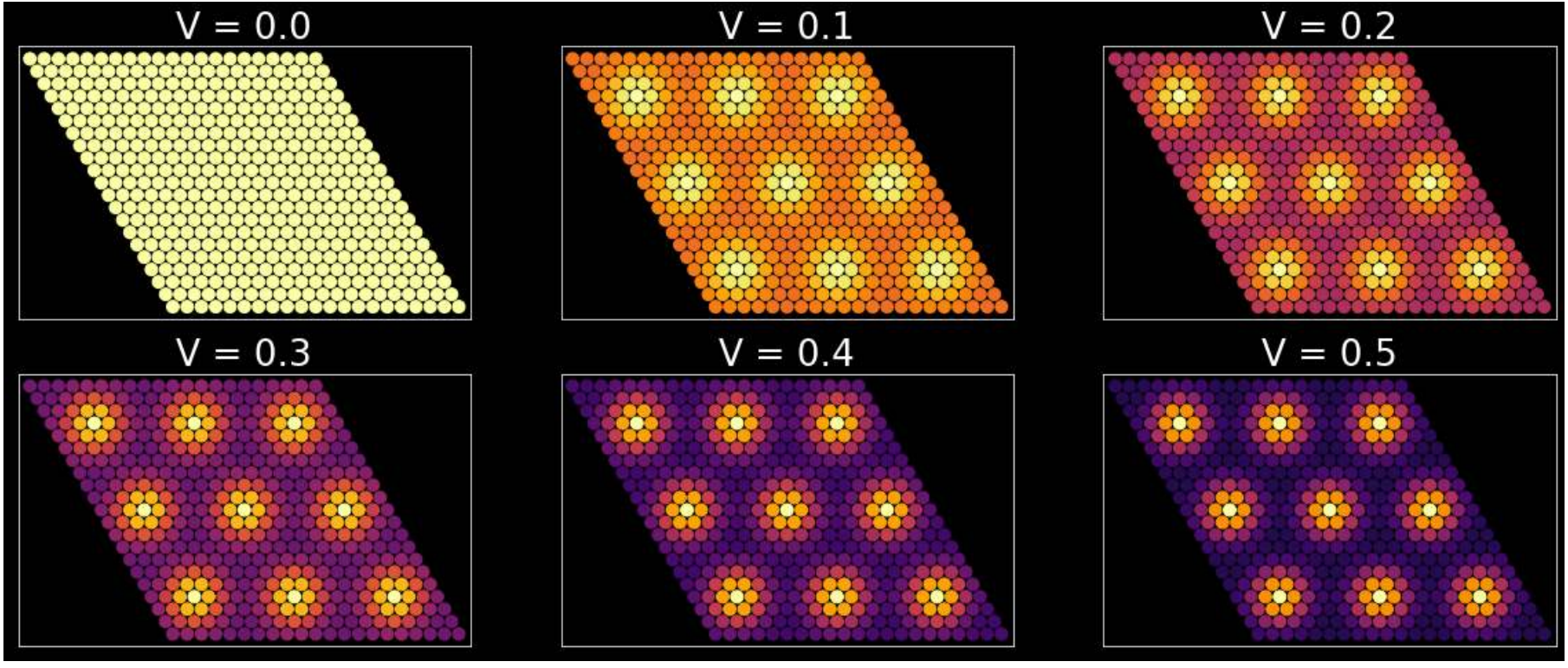


Band flattening by a moire



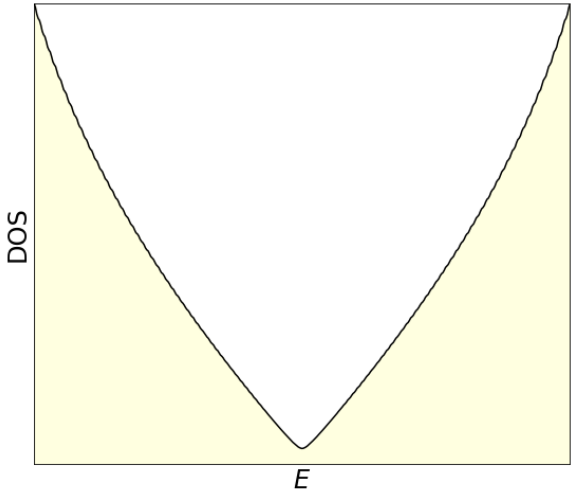
As the strength of a modulation is increased, flat bands appear

Emergence of moire states

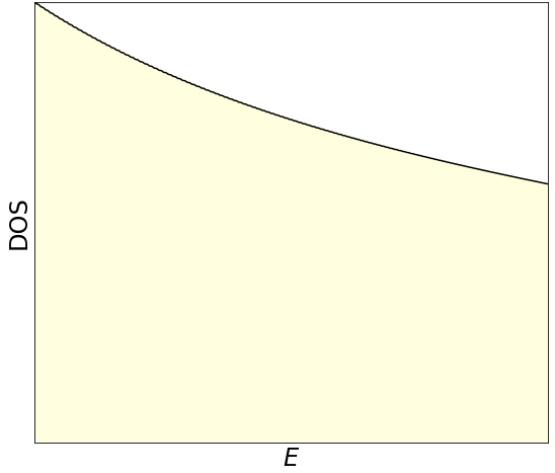


Controlling the electronic spectra with the moire angle

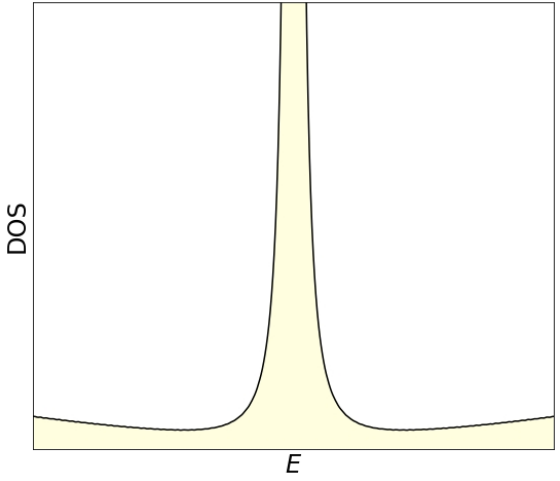
Semimetals



Metals



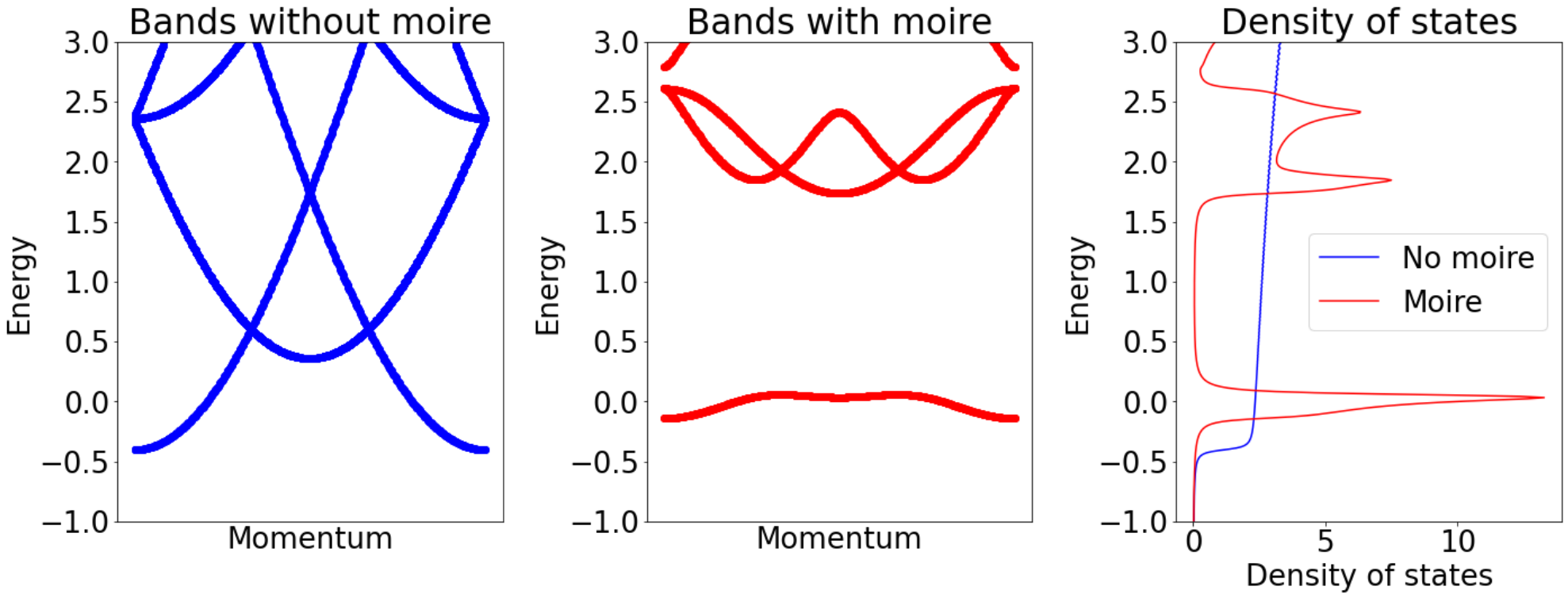
Flat bands



Moire/twist angle

Moire potentials allow driving systems to the correlated limit $U_C \sim \frac{1}{D(E_F)}$

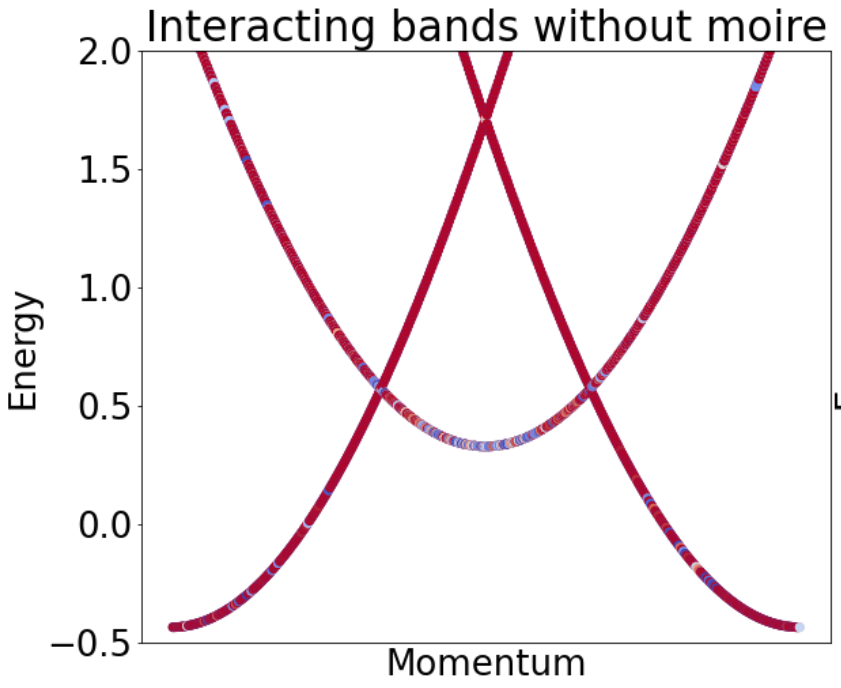
Moire-enhanced DOS

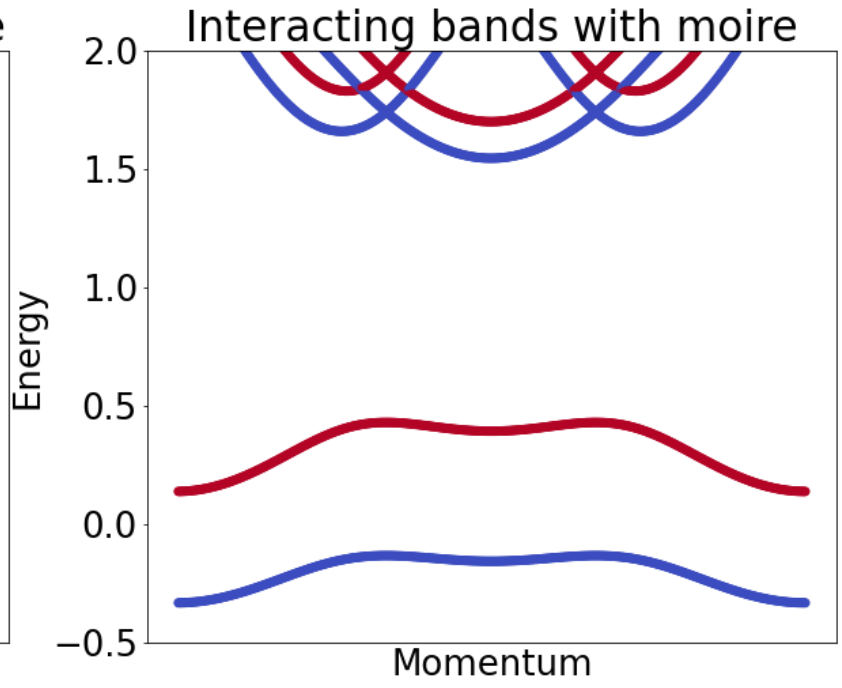


The moire potential gives rise to an enhanced DOS

Interactions in the absence and presence of a moire

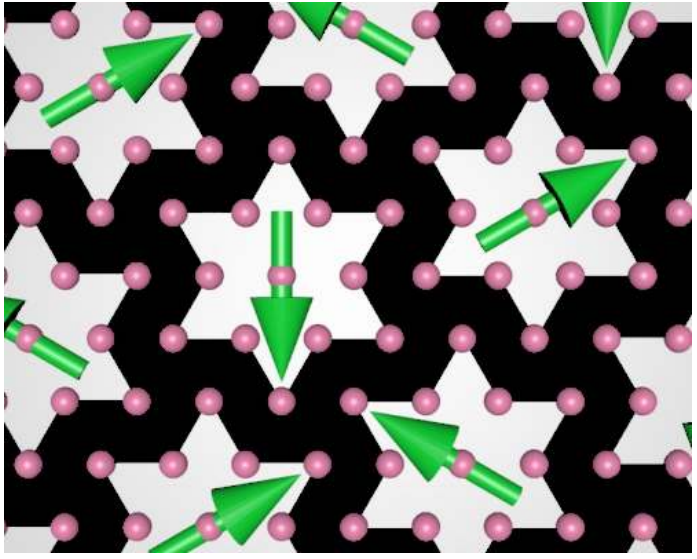
$$H = \sum_{ij,s} t_{ij} c^{\dagger}_{i,s} c_{j,s} + \sum_{i} U c^{\dagger}_{i\uparrow} c_{i\uparrow} c^{\dagger}_{i\downarrow} c_{i\downarrow} + h.c.$$

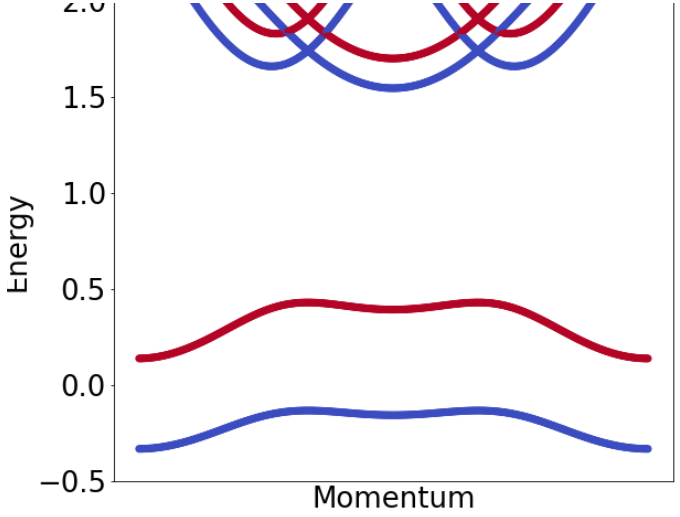




Correlated state in 1T-TaS_2 from miniband formation

Charge-density wave reconstruction, leading to a localized orbital in a $\sqrt{13} \times \sqrt{13}$ unit cell





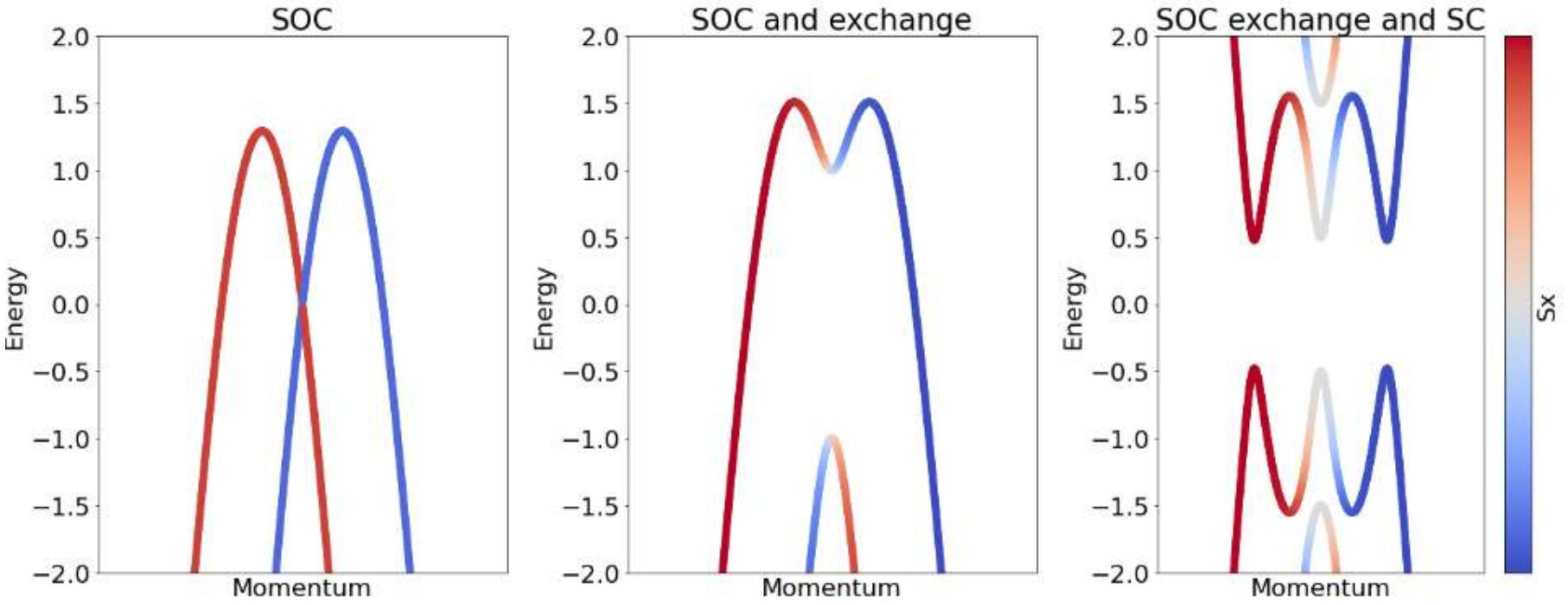
A charge density wave distortion acts as a superlattice modulation

Strong interactions give rise to local moment formation in the mini-bands

Moire-driven topological states

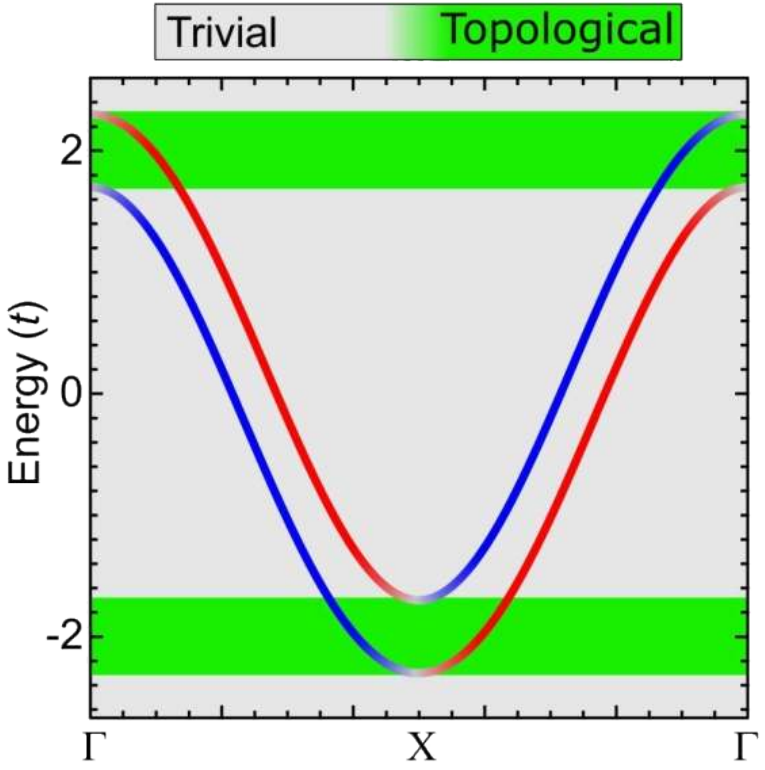
Artificial topological superconductivity

Bulk electronic structure



The combination of SOC and exchange creates helical states
Superconductivity gaps out the helical states in a non-trivial way

Artificial topological superconductor



$$H = H_0 + H_J + H_R$$

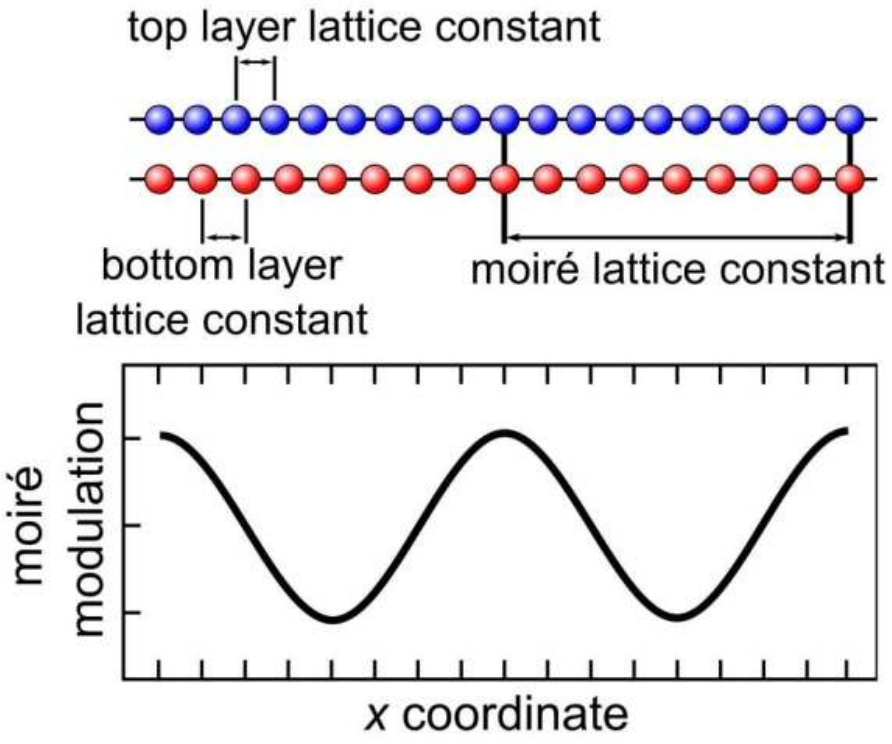
Kinetic energy

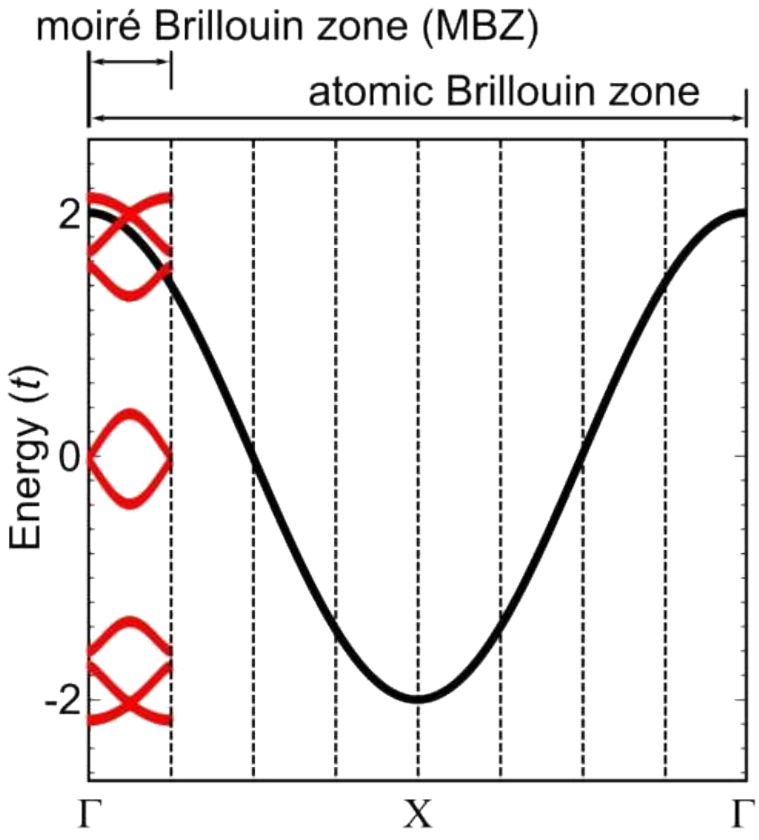
Exchange field

Rashba spin-orbit coupling

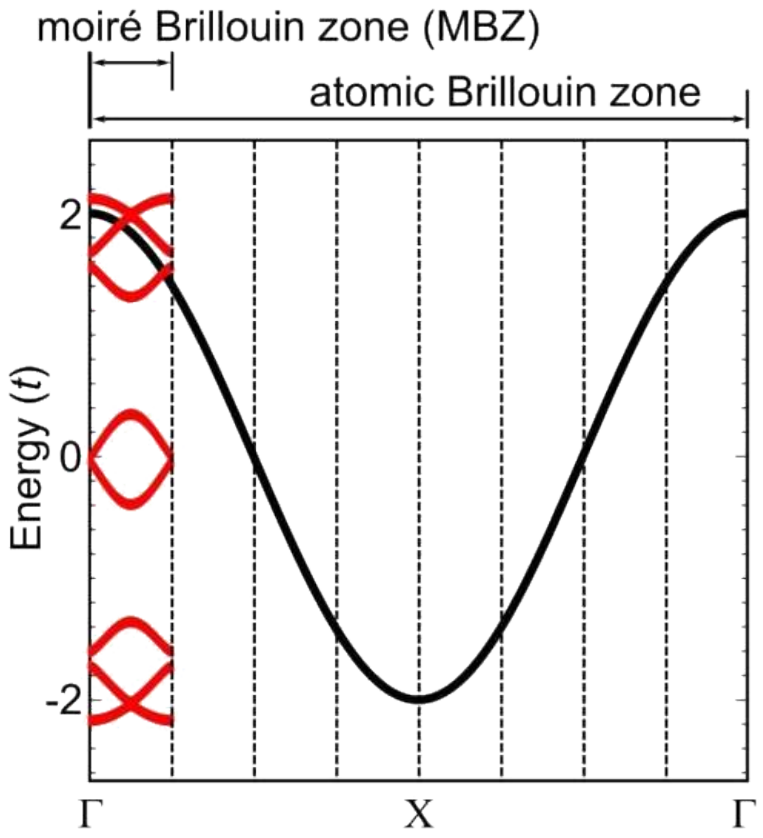
When switching on an s-wave pairing,
green regions lead to topological superconductivity

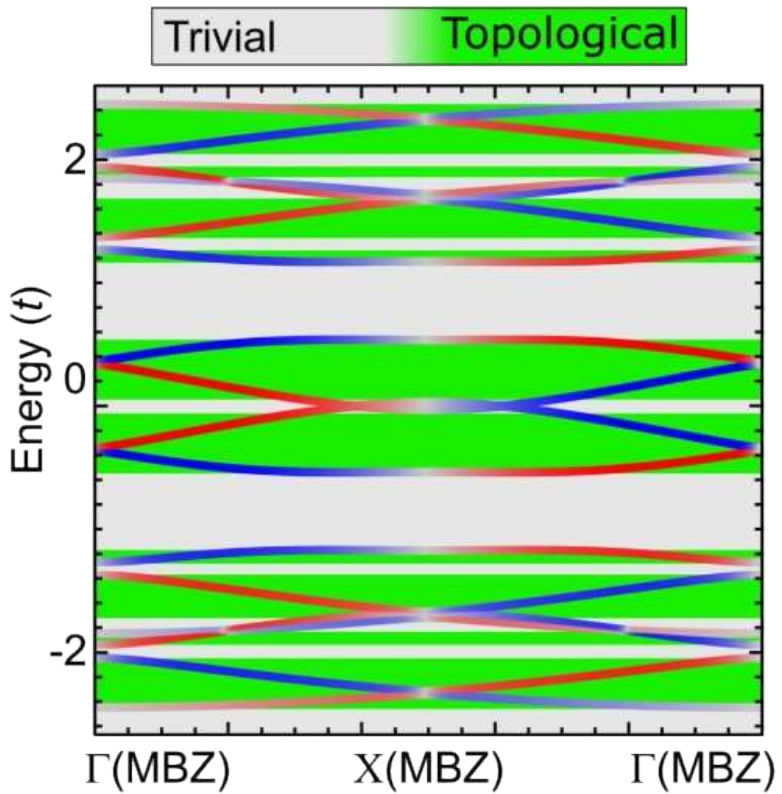
Artificial moire topological superconductor





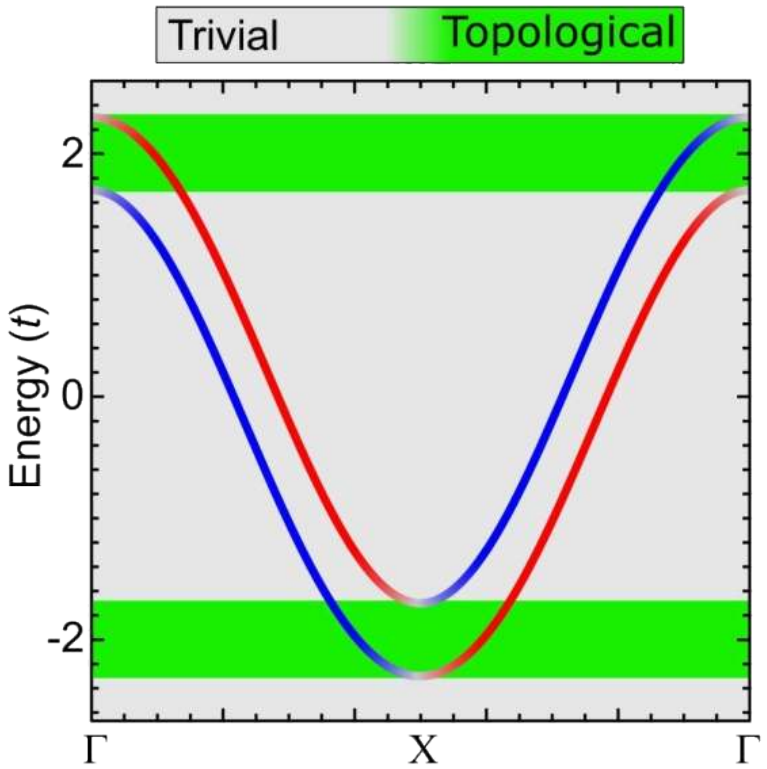
Artificial moire topological superconductor



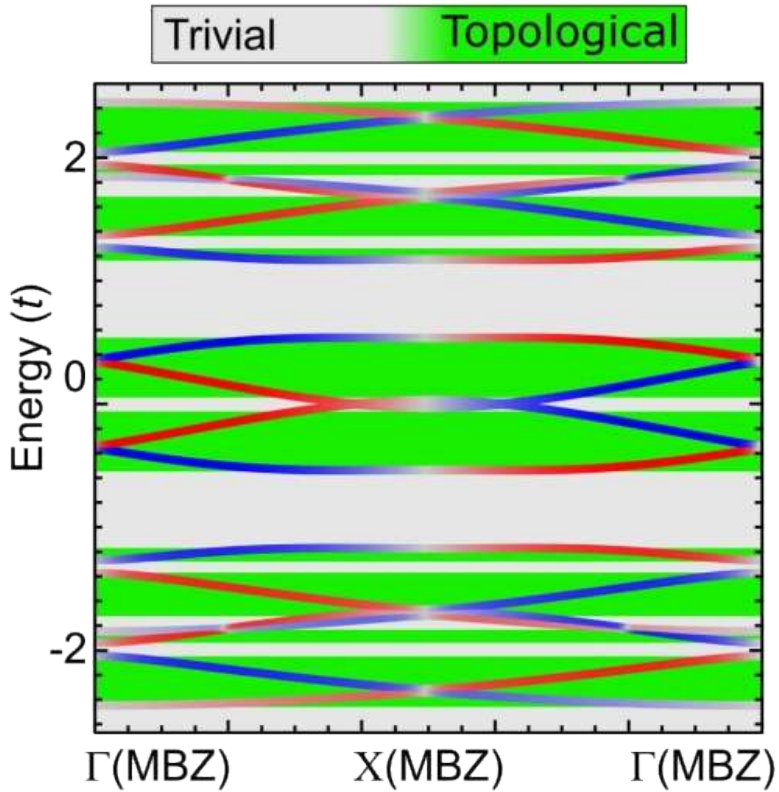


Artificial moire topological superconductor

Without moire

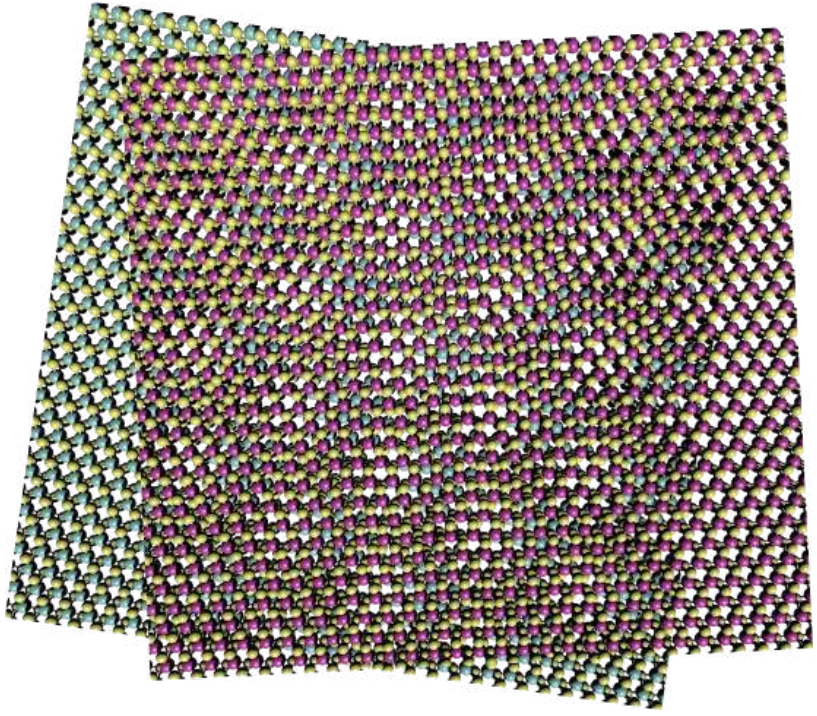


With moire



Moire driven gaps in the band structure

In twisted TMDC heterobilayers, the moire modulates the band off set of one layer



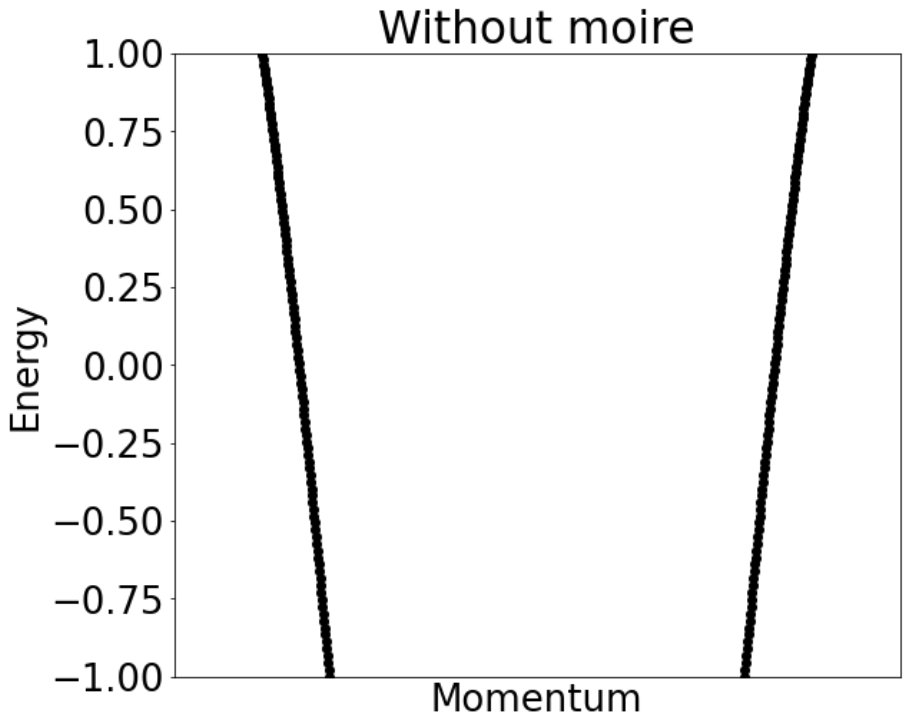
$$H = H_0 + H_J + H_R$$

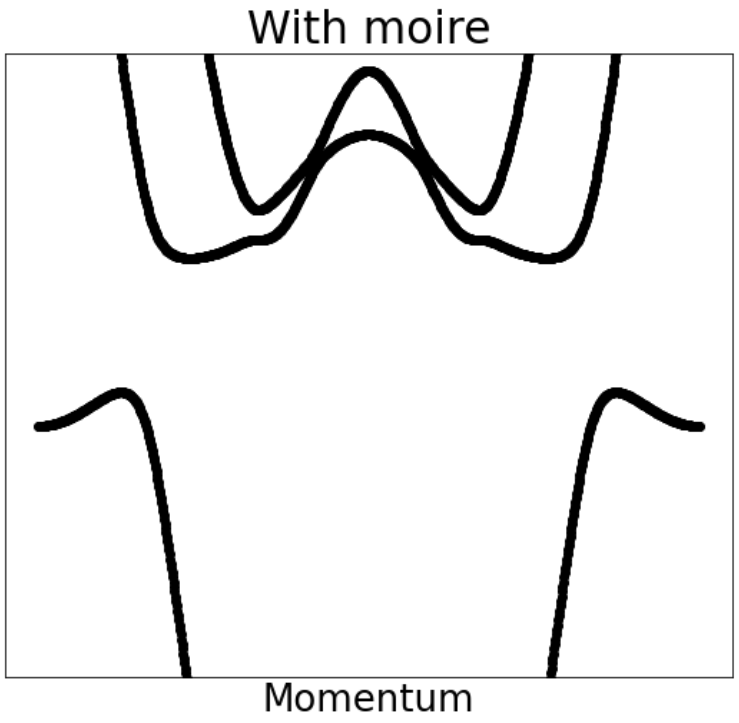
Kinetic energy

Exchange field

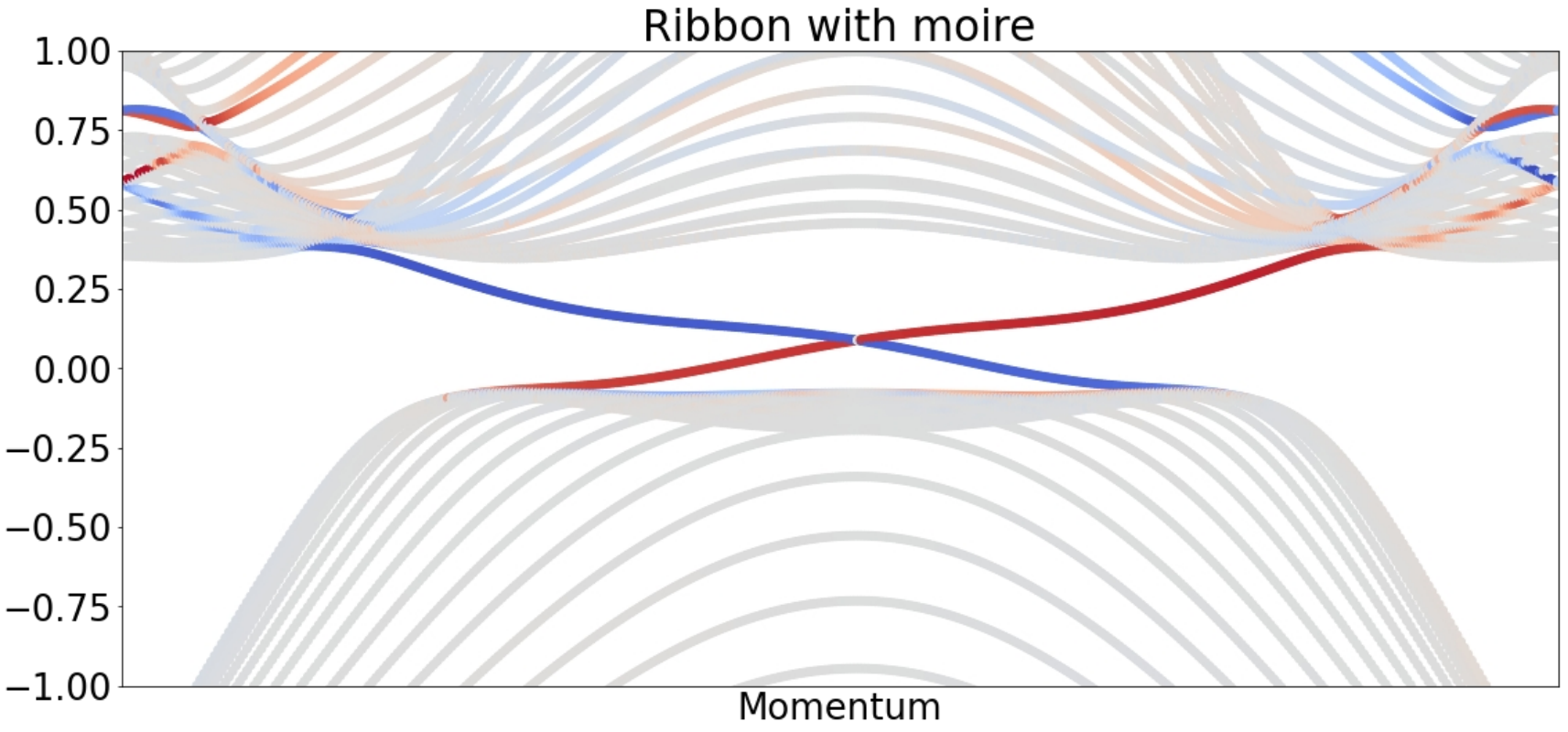
Rashba spin-orbit coupling

Moire driven gaps in the band structure





Moire driven gaps in the band structure



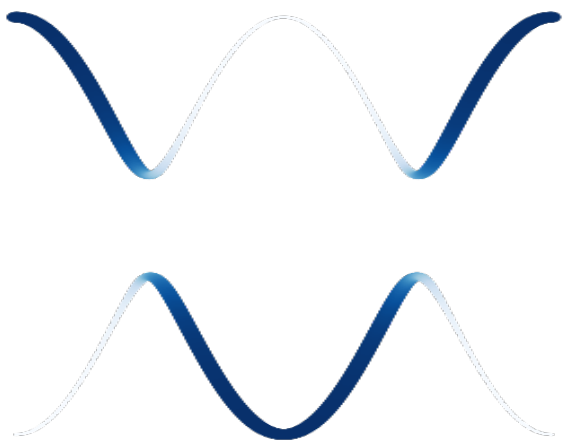
Chiral states appear in a ribbon driven by the moire

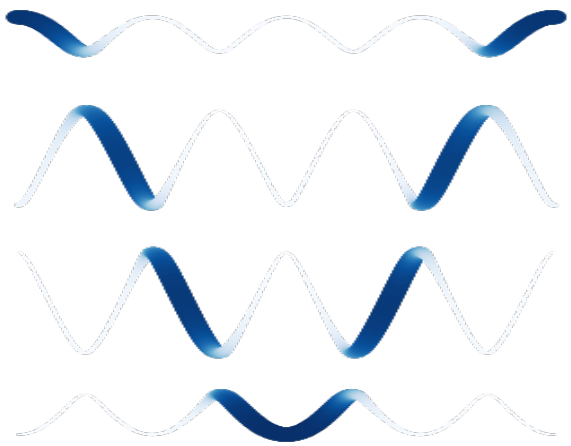
Break

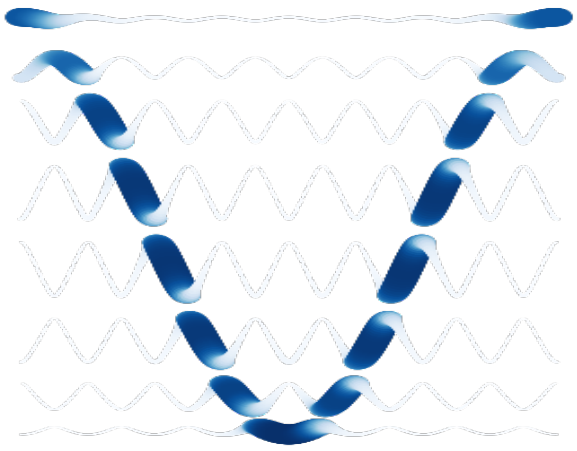
10-15 min break

(optional) to discuss during the break

Which band structure has more van Hove singularities?

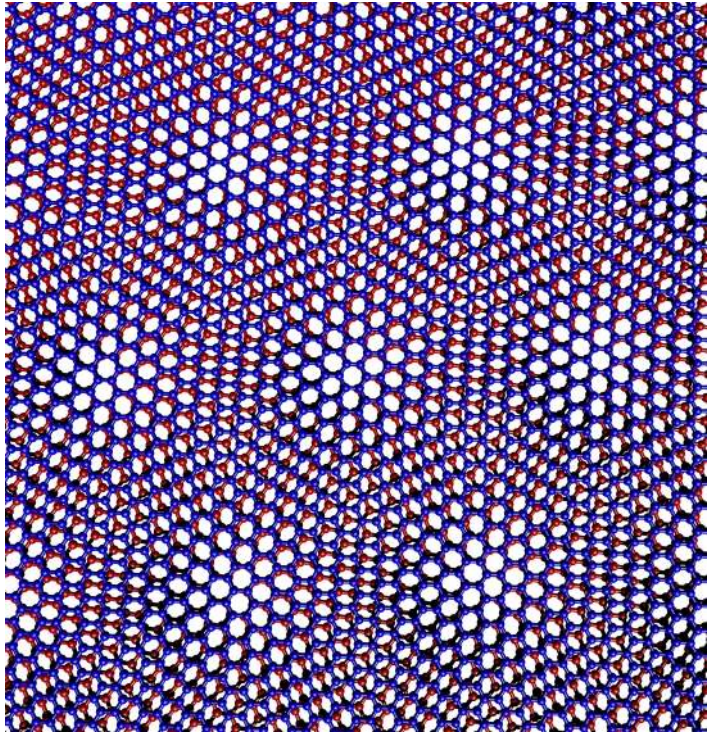


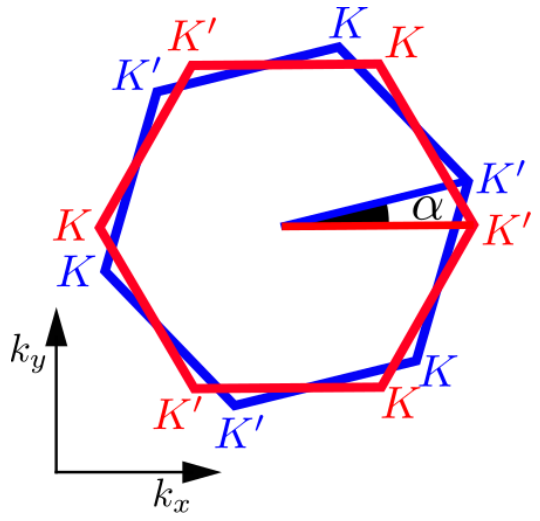




Electronic structure of twisted graphene multilayers

Twisted bilayer graphene



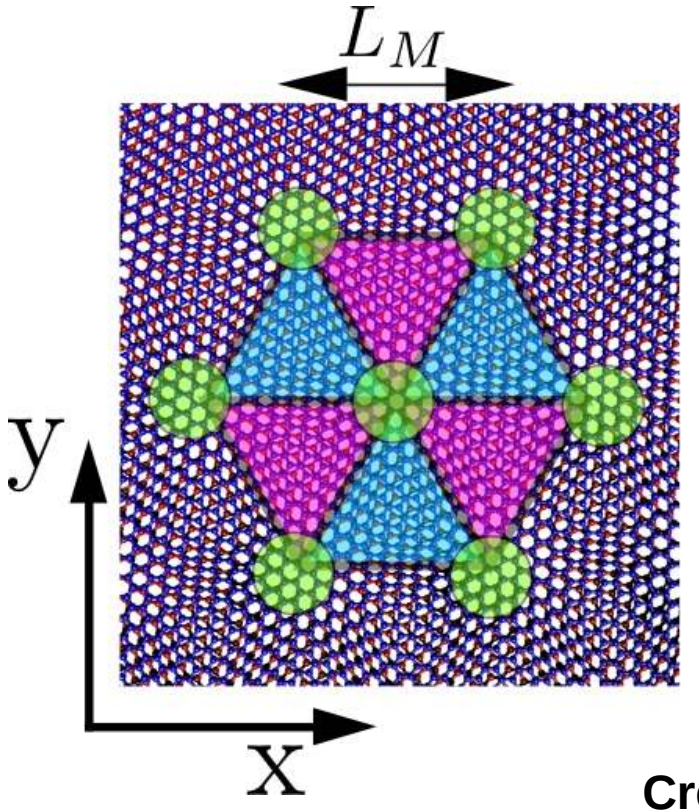


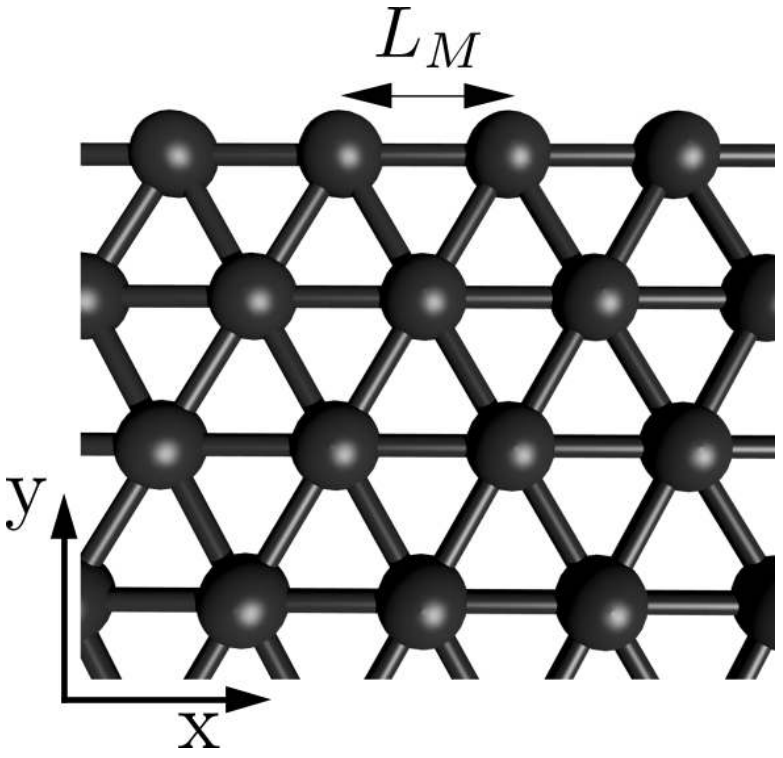
Additional parameters in the system

Angle between the layers α

Bias between the layers U

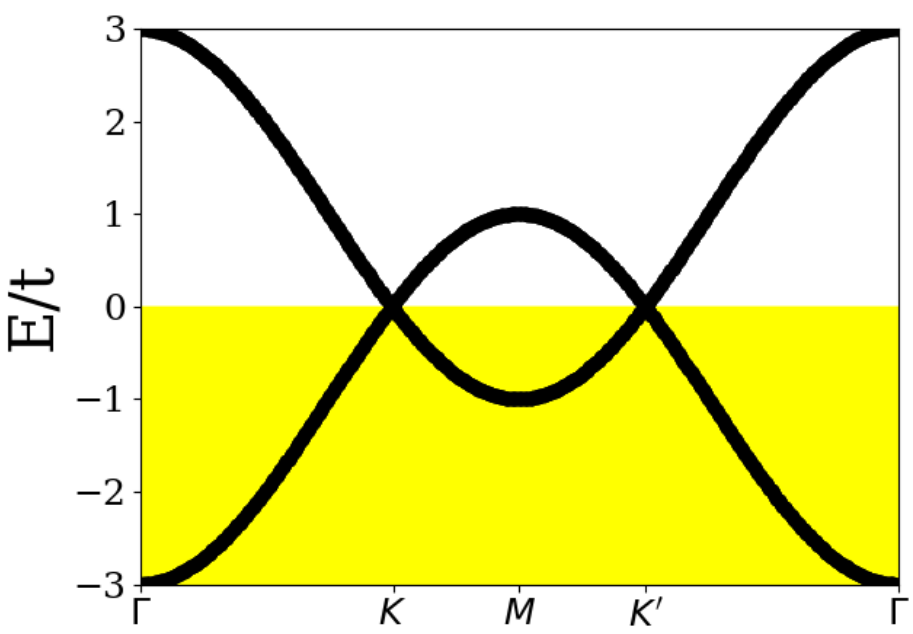
A new length scale: the moire length

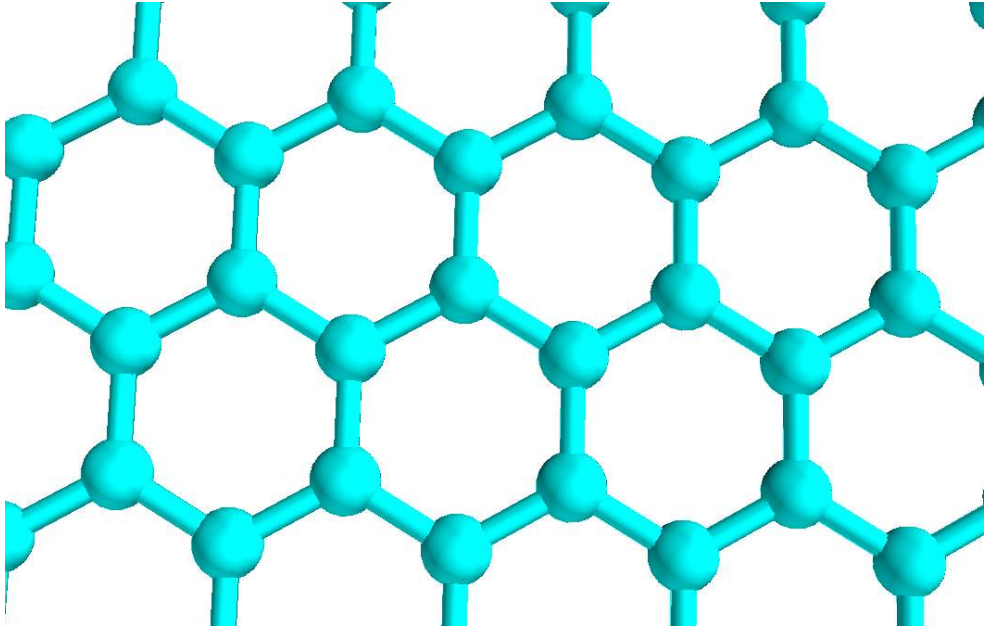




Creating effective lattices with tunable lattice constants

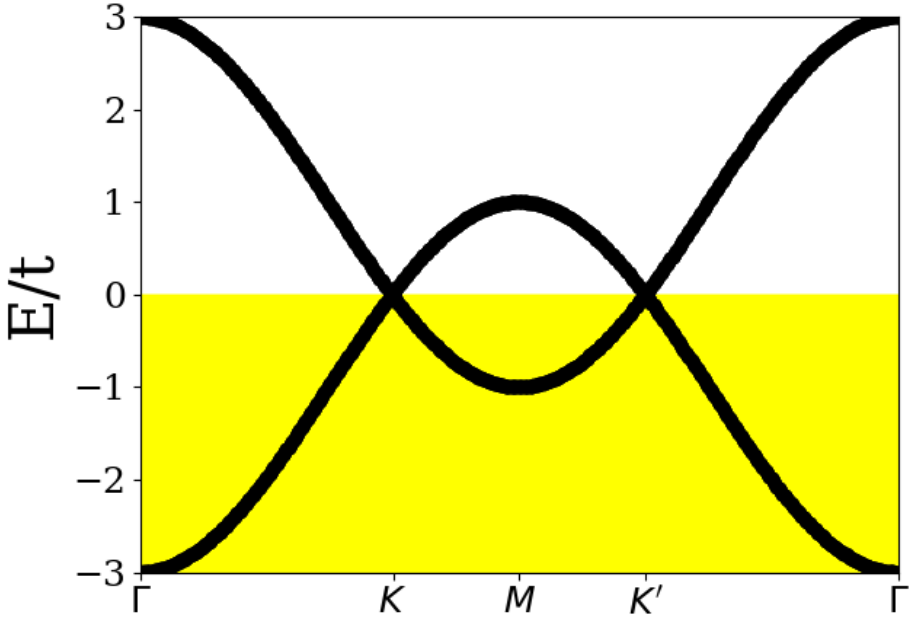
Structure of graphene





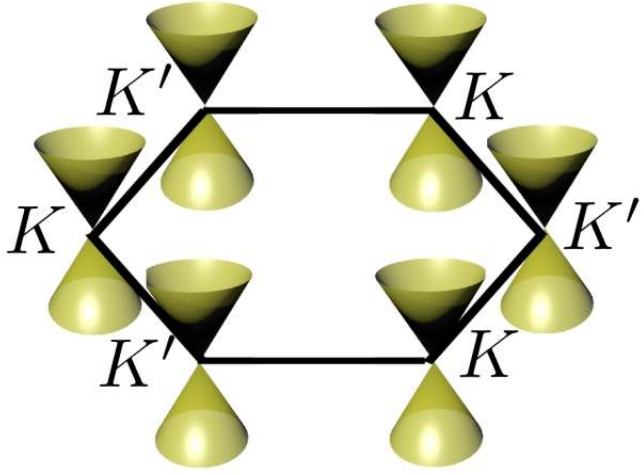
Minimal model: Single orbital in a honeycomb lattice

The electronic structure of graphene

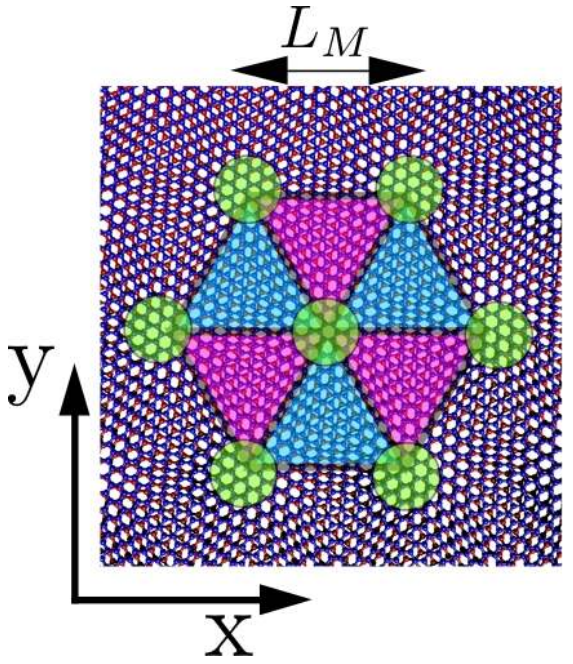


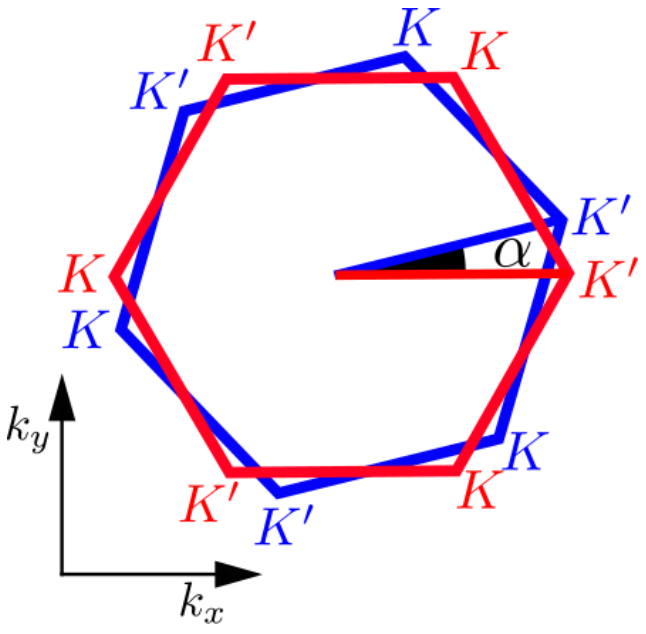
$$H = \begin{pmatrix} 0 & p_x \pm i p_y \\ p_x \mp i p_y & 0 \end{pmatrix}$$

$$H = p_x \sigma_x \pm p_y \sigma_y$$



Real and reciprocal space in twisted bilayer graphene



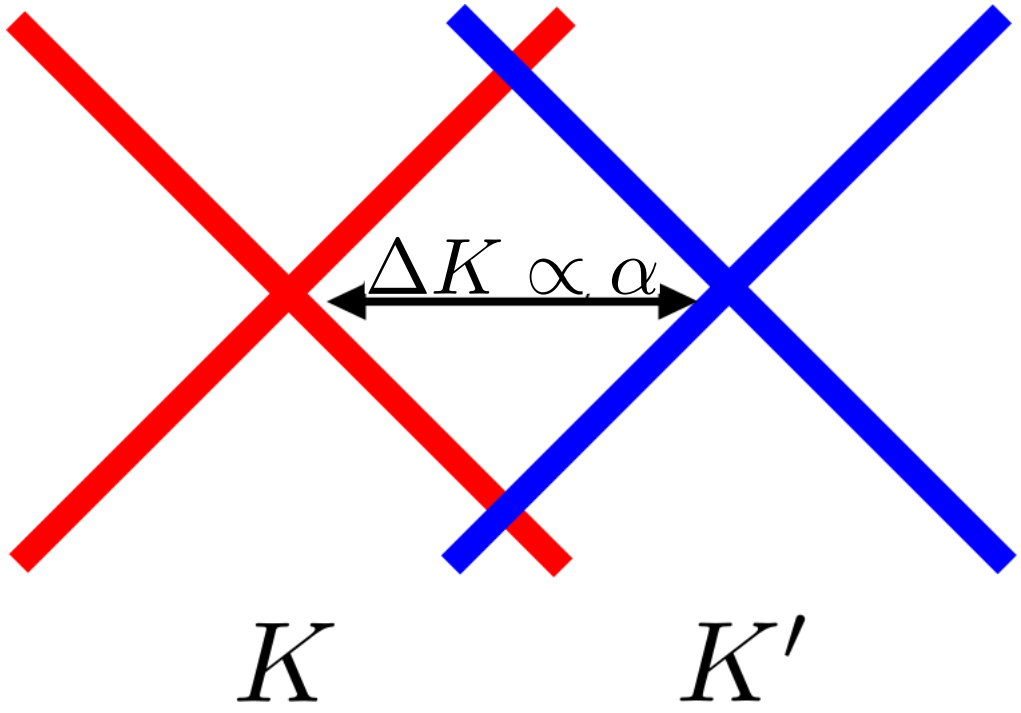


Intralayer Interlayer Bias

$$H = t\sum_{\langle ij\rangle} c_i^\dagger c_j + \sum_{ij} \hat{t}_\perp(\mathbf{r}_i, \mathbf{r}_j) c_i^\dagger c_j + U\sum_i \tau_z^{ii} c_i^\dagger c_i,$$

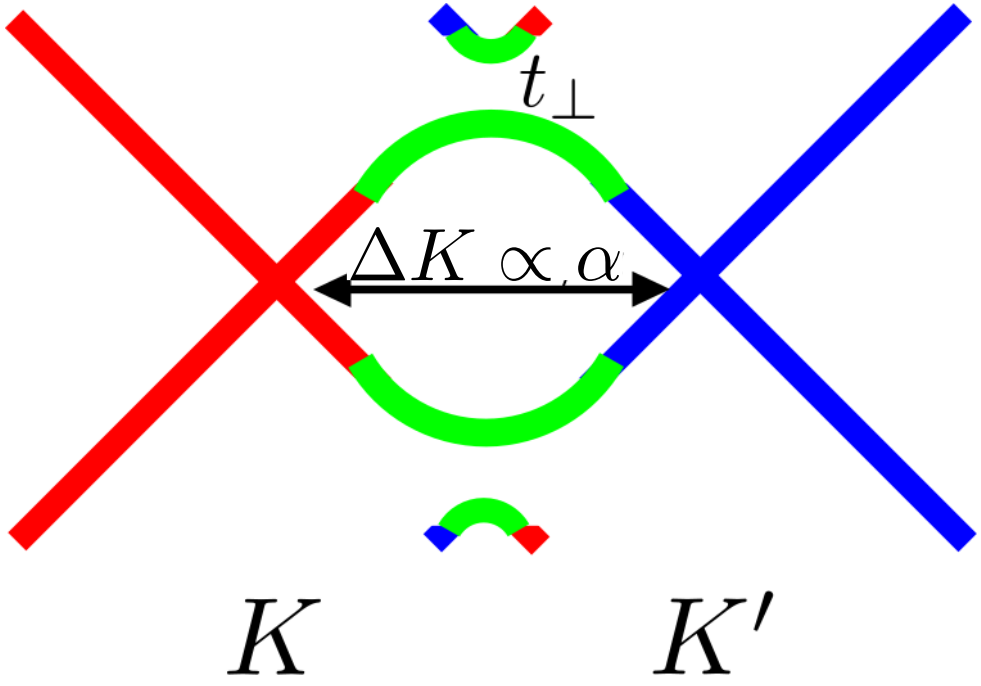
Velocity renormalization at large angle

$$\bar{v}_F/v_F = 1 - 9[t_\perp/v_F\Delta K]$$



Velocity renormalization at large angle

$$\bar{v}_F/v_F = 1 - 9[t_\perp/v_F\Delta K]$$

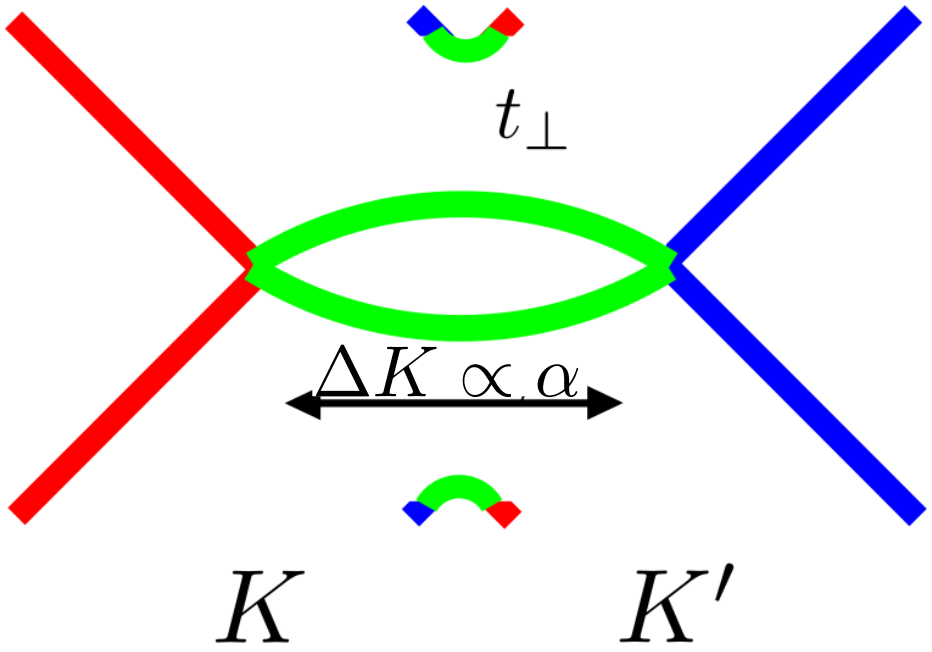


Relevant ratio

$$\frac{t_\perp}{\alpha}$$

Velocity renormalization at large angle

$$\bar{v}_F/v_F = 1 - 9[t_\perp/v_F\Delta K]$$

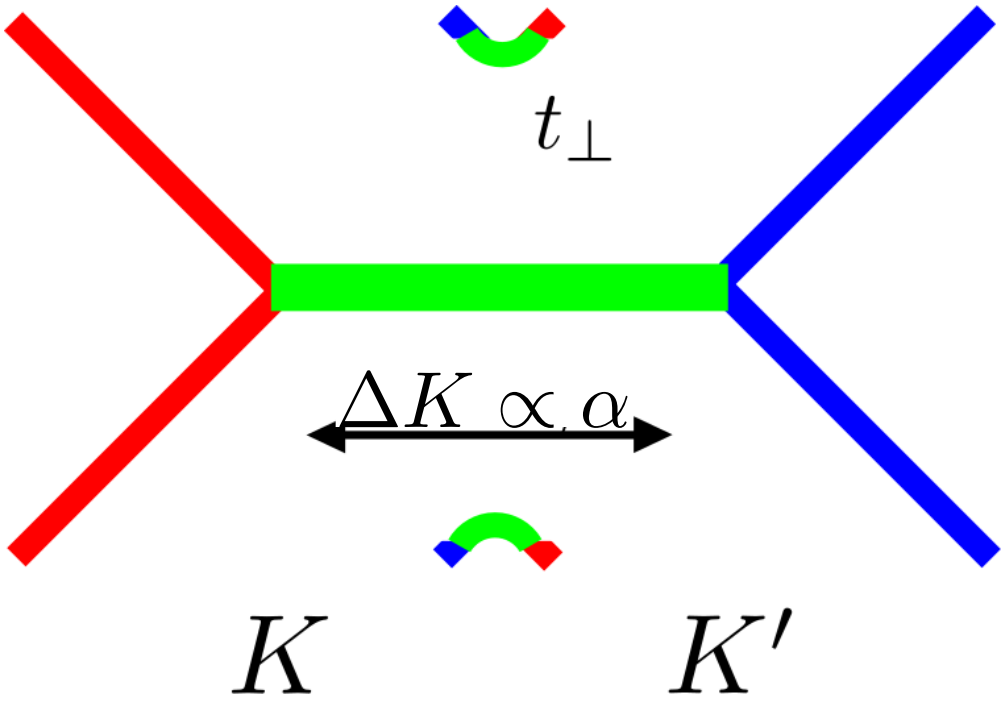


Relevant ratio

$$\frac{t_\perp}{\alpha}$$

Velocity renormalization

$$\bar{v}_F/v_F = 1 - 9[t_\perp/v_F\Delta K]$$

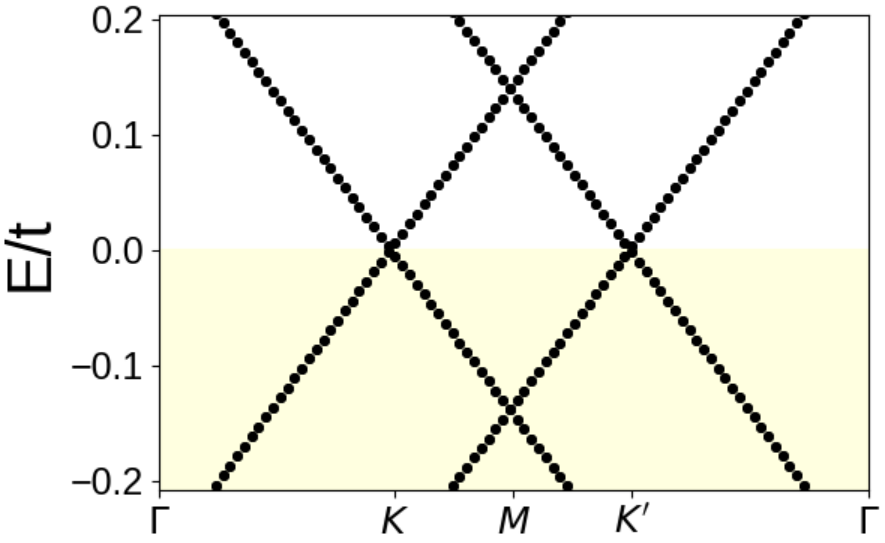


Relevant ratio

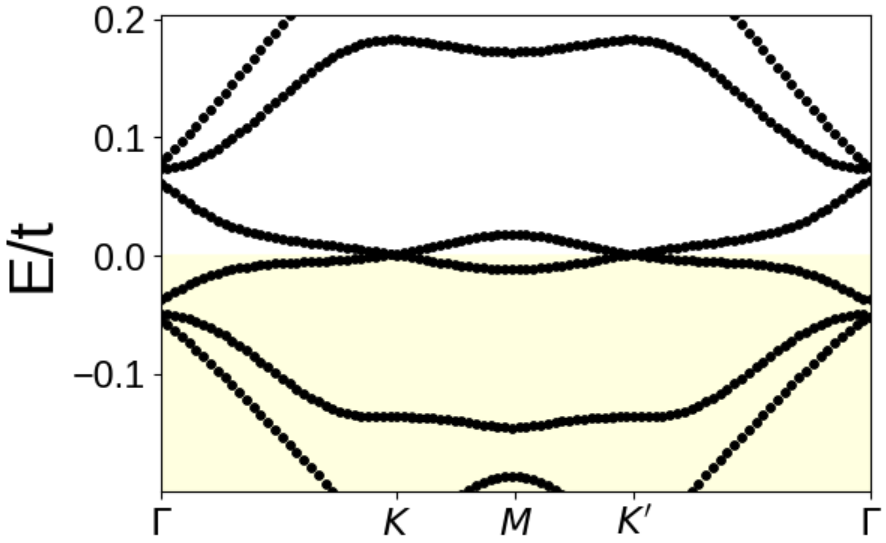
$$\frac{t_\perp}{\alpha}$$

Band structure of twisted bilayer graphene

Decoupled



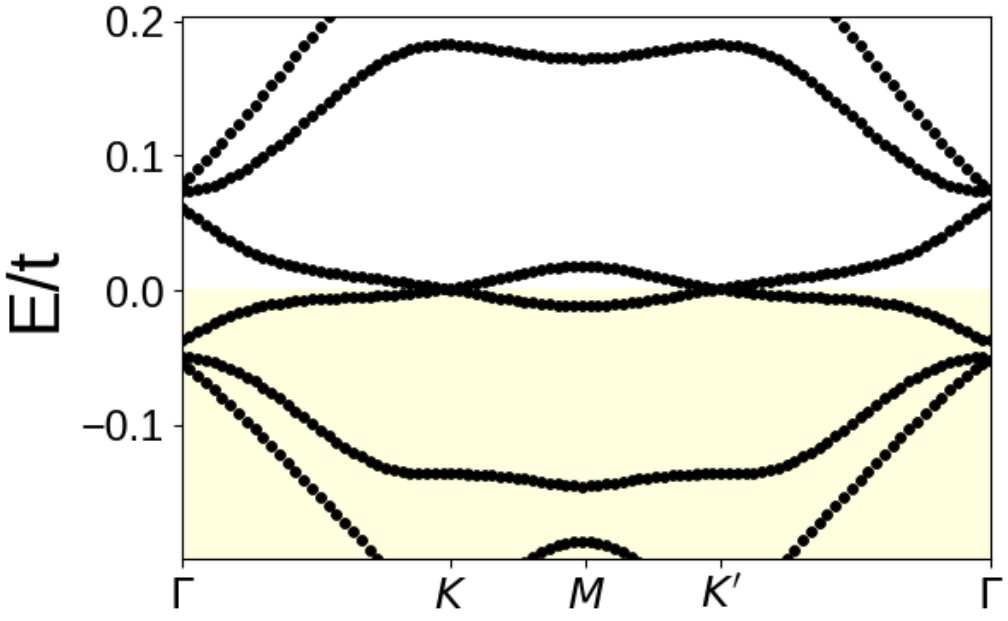
$\alpha = 1.5°$



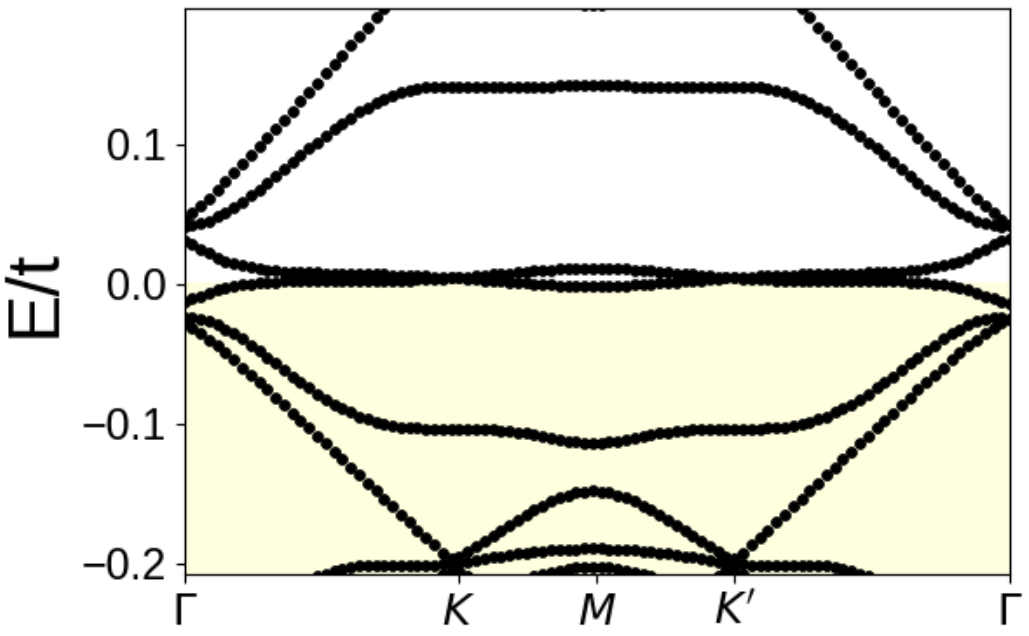
As the angle between layers in decreased, the bands become flatter

Band structure of twisted bilayer graphene

$\alpha = 1.5°$

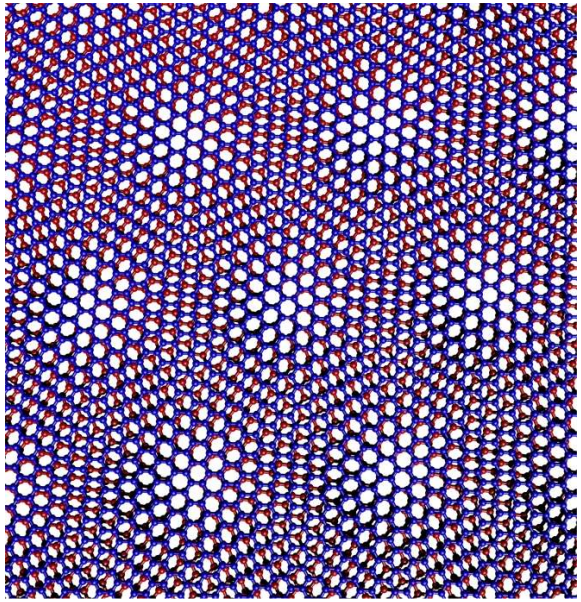


$\alpha = 1.2°$

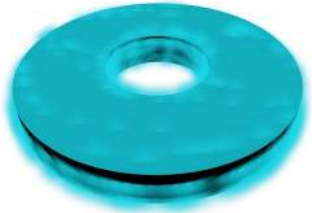


As the rotation angle approached 1 degree, the lowest band becomes flatter

Correlations in twisted bilayer graphene flat bands

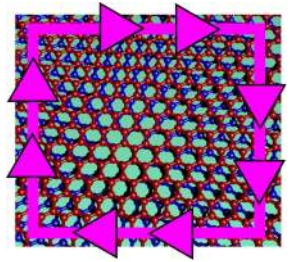


Superconductivity



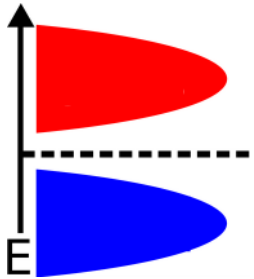
Nature 556, 43–50 (2018)

Chern insulators



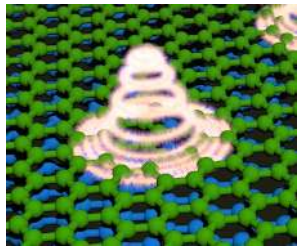
Science 365, 605-608 (2019)

Correlated insulators



Nature 556, 80–84 (2018)

Fractional Chern insulators

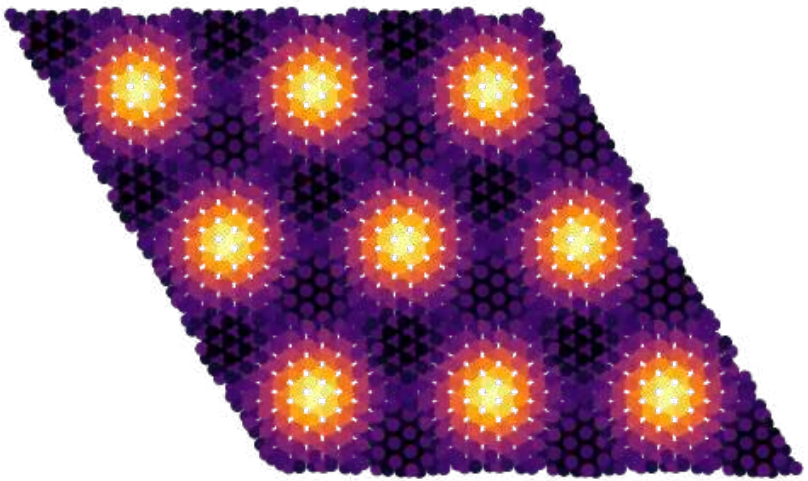


Nature 600, 439–443 (2021)

Correlated states in flat bands give rise to a wide variety of phenomena

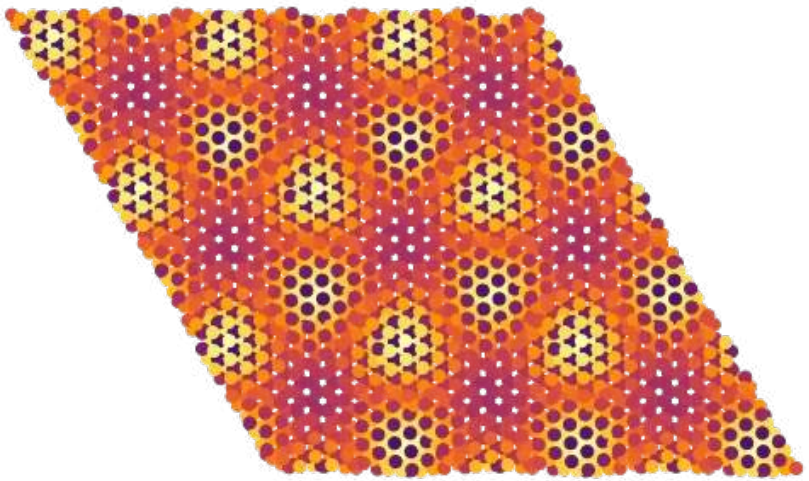
Distribution of states in the twisted graphene bilayer

E = 0.0



Triangular

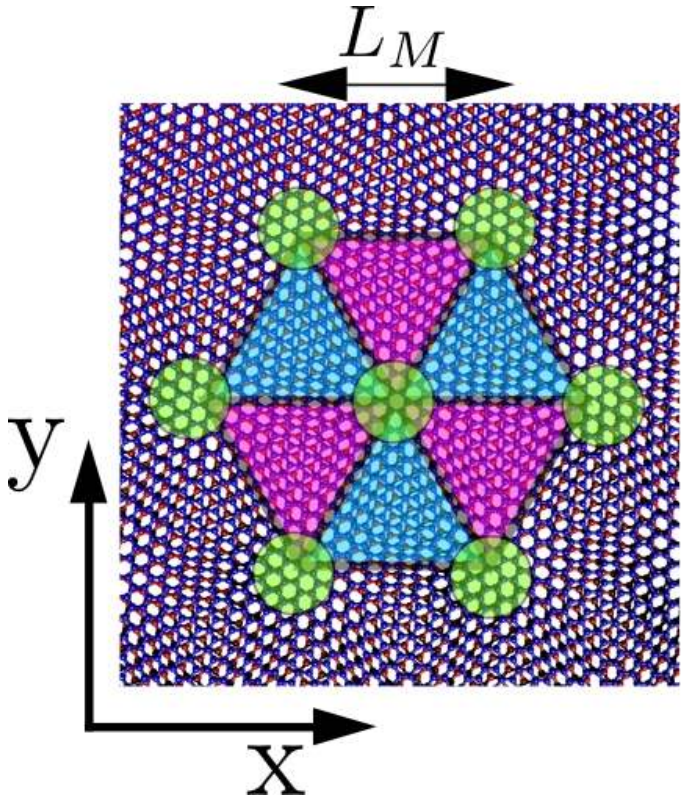
E = 0.25

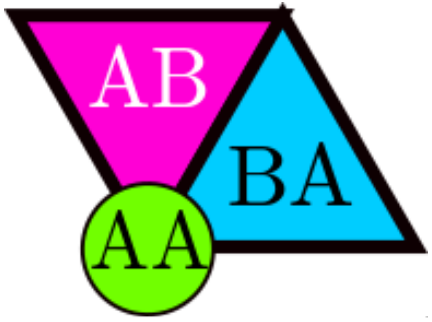


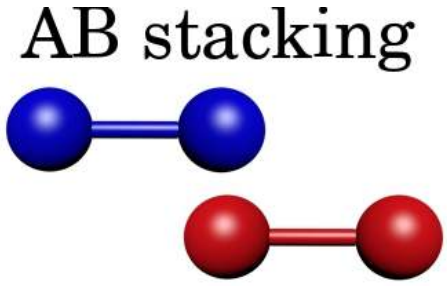
Hexagonal

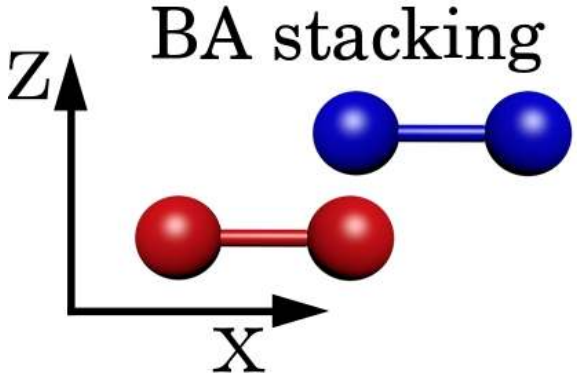
The spatial distribution of the states is highly dependent on the energy

Stacking of twisted bilayer graphene

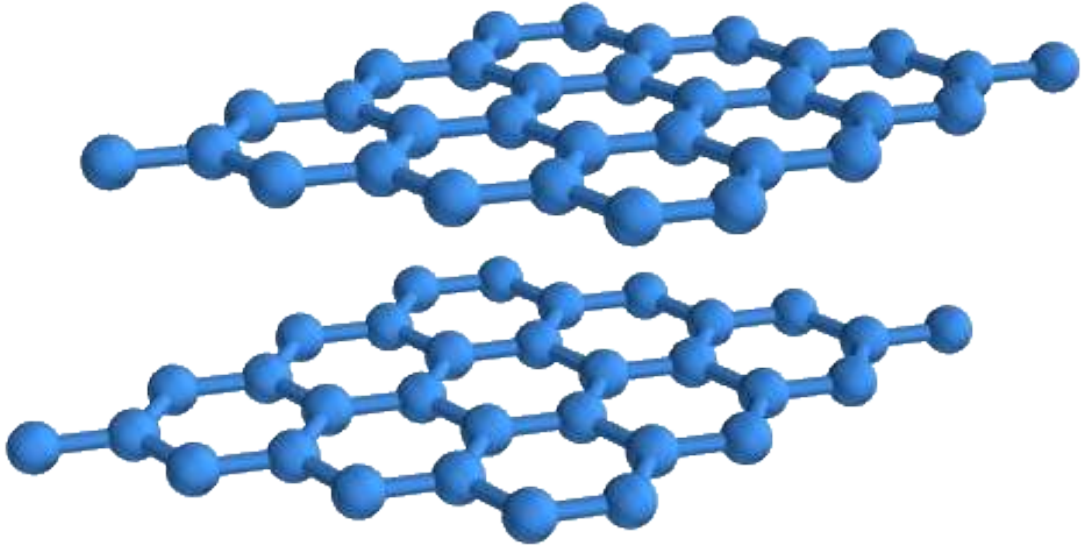








Bias in AB bilayer graphene



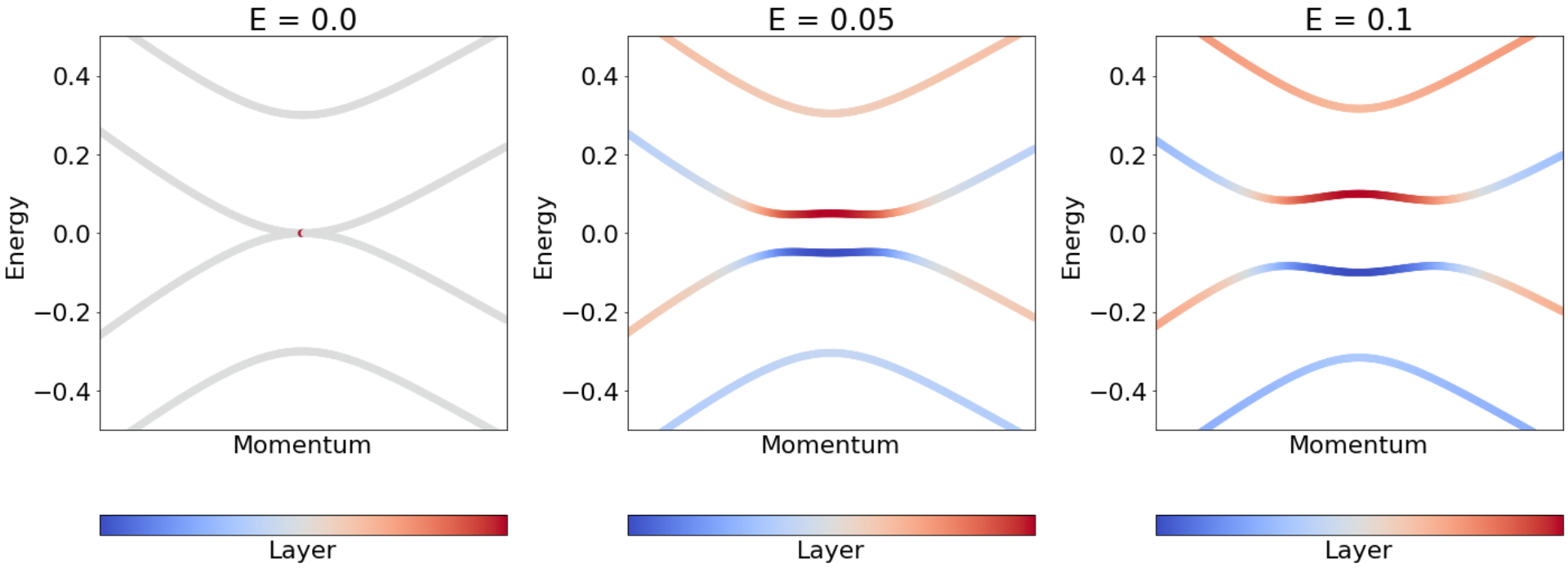
$$V c_n^\dagger c_n$$

$$-V c_n^\dagger c_n$$

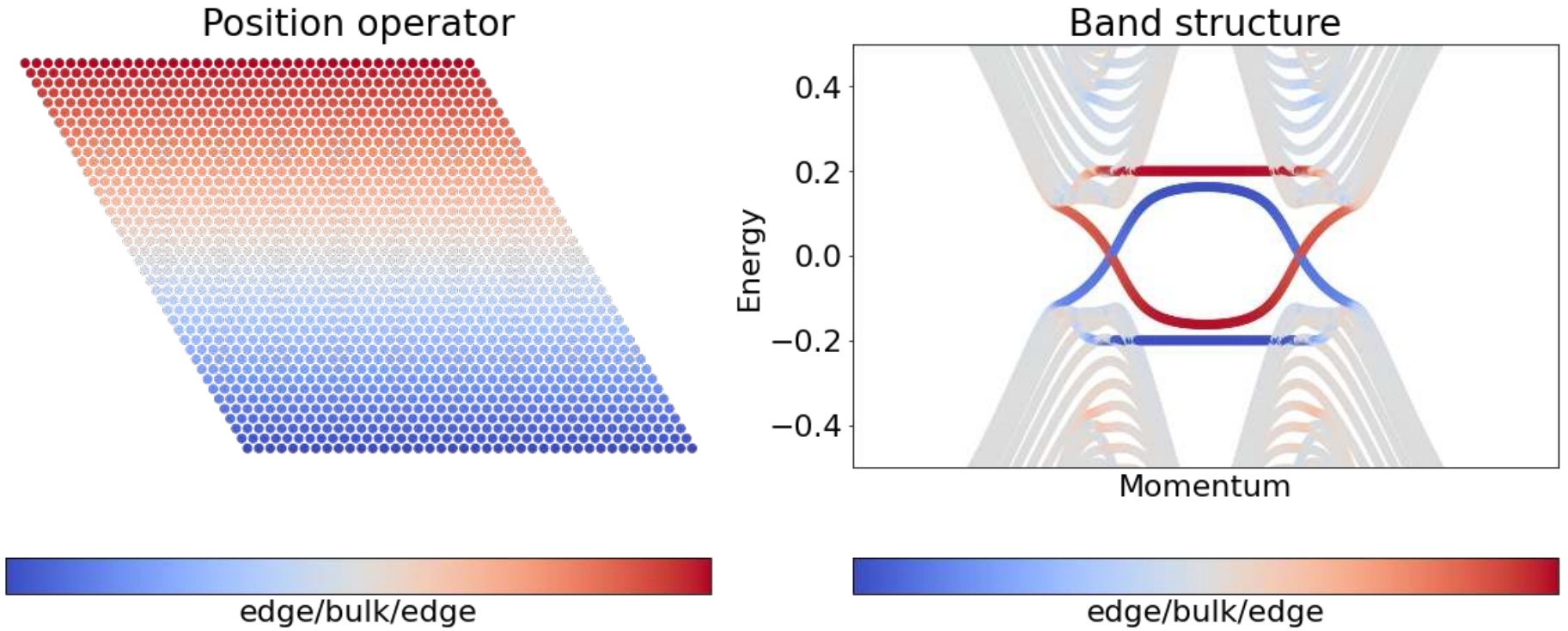
Let us look at the impact of a bias in an aligned graphene bilayer

The electronic structure of bilayer graphene

Graphene bilayers open a gap when an interlayer bias is applied

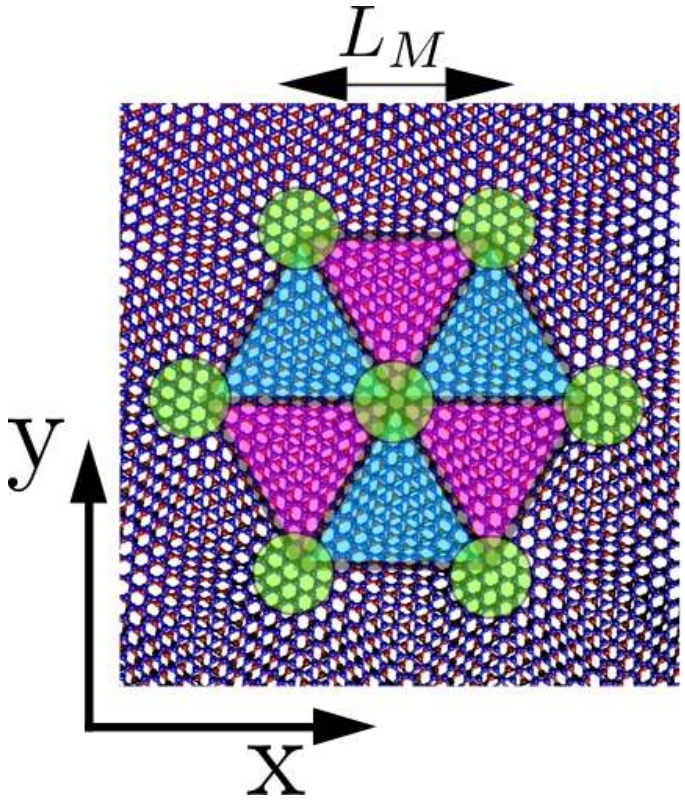


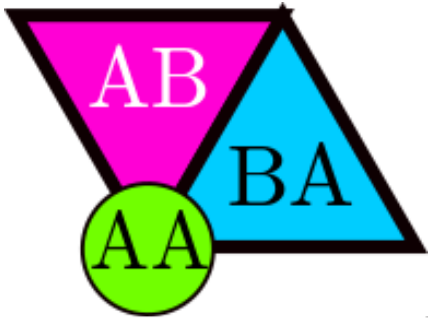
Biased bilayer graphene, pseudo-helical states

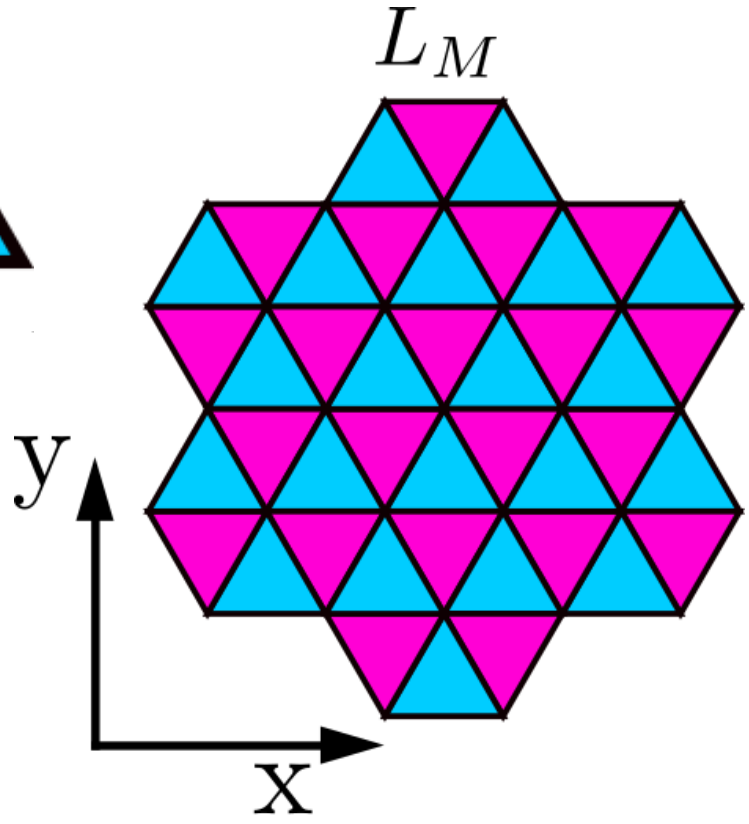


Edge states appear in the presence of a bias between layers

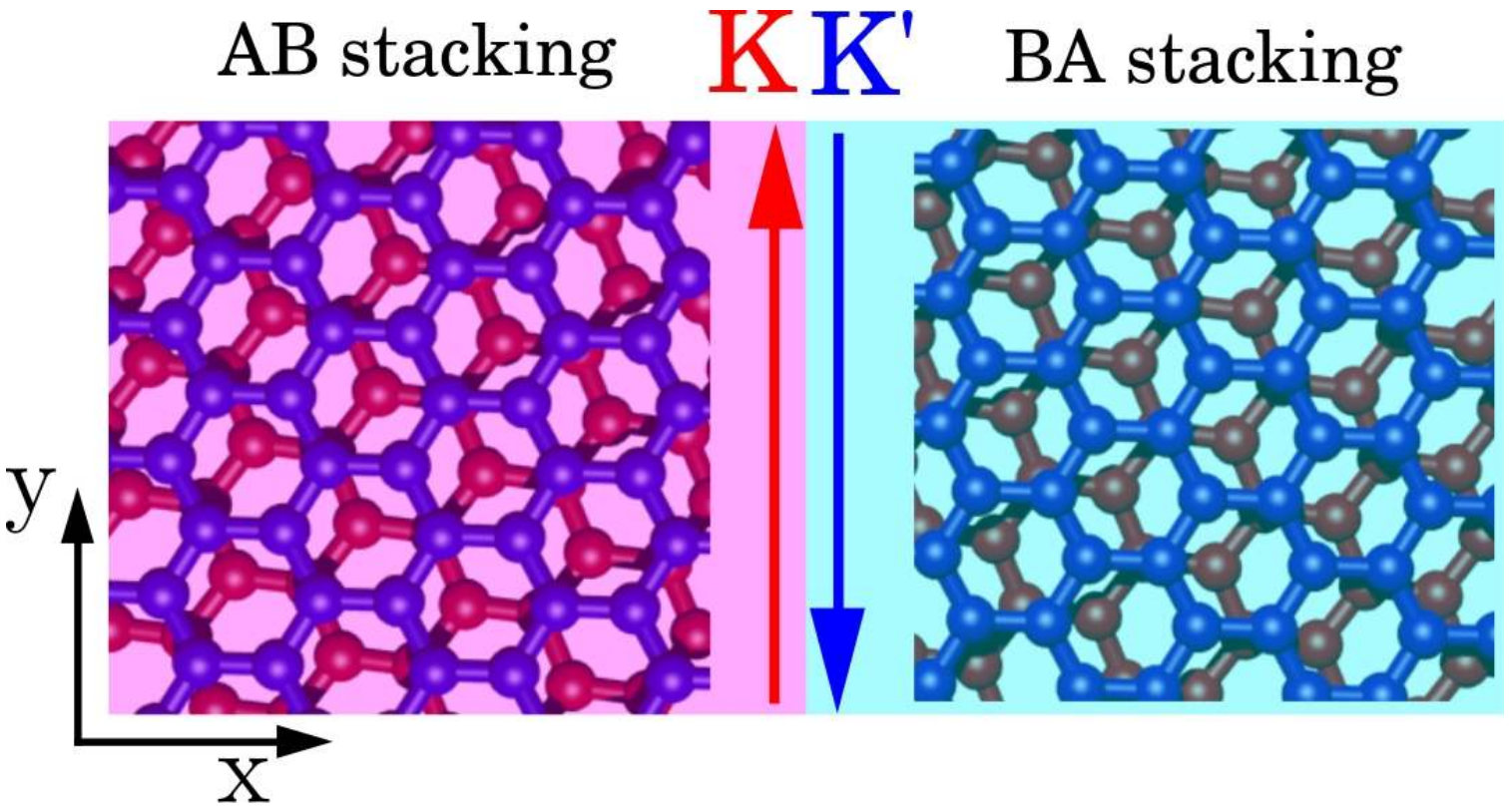
Stacking of twisted bilayer graphene



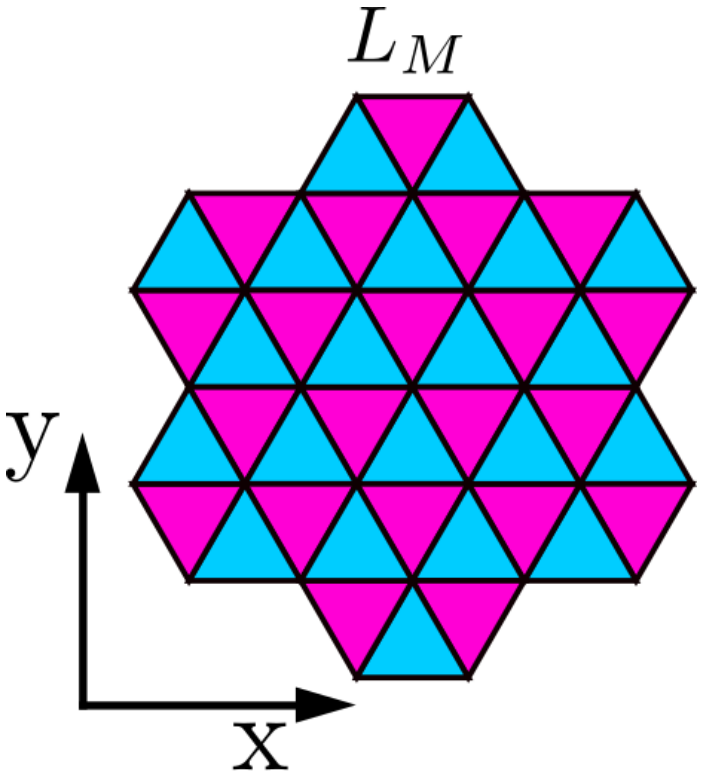


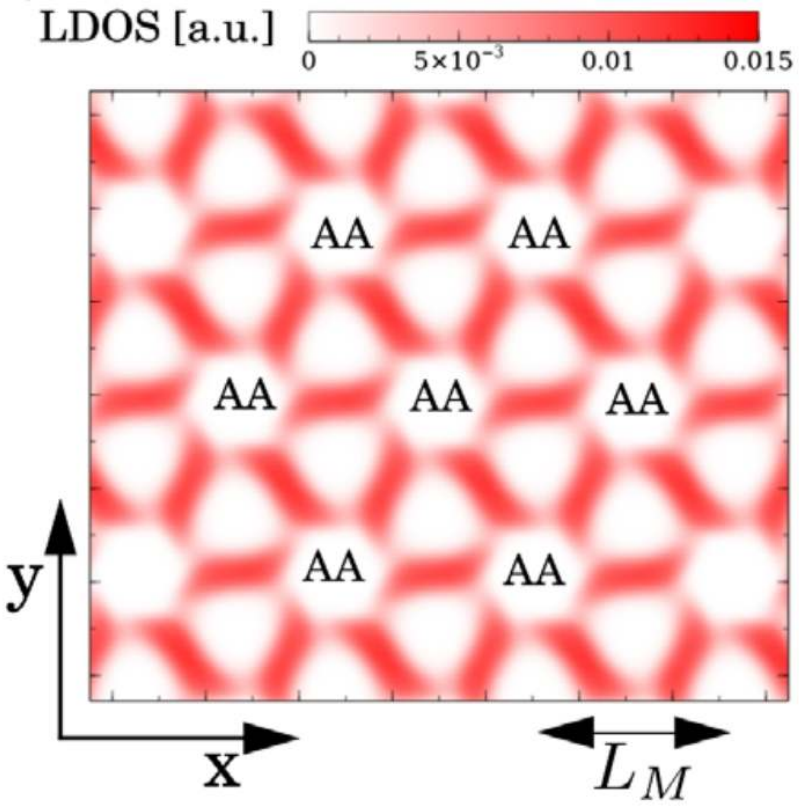


Interfacial modes in biased TBG



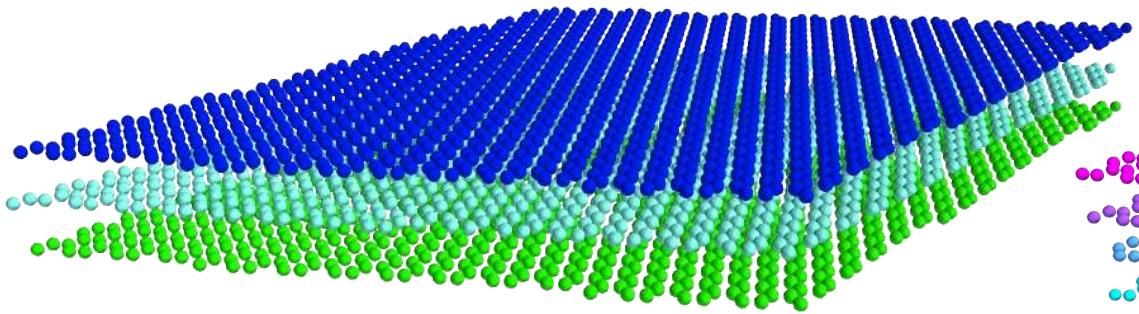
Helical networks in TBG



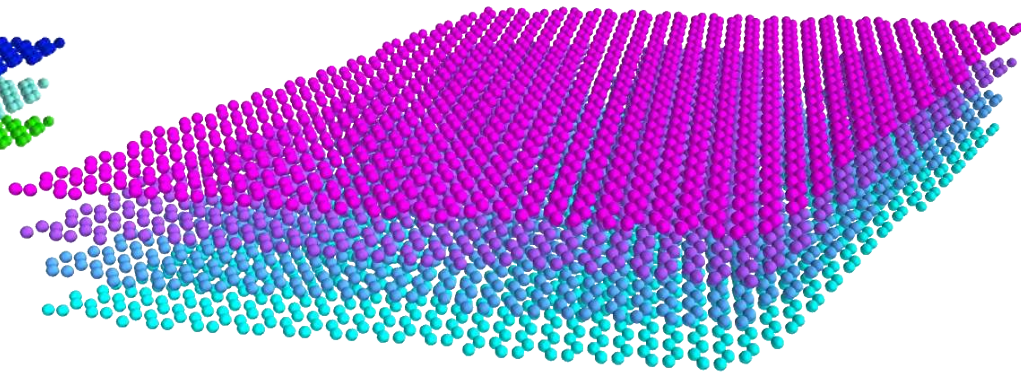


Other twisted graphene multilayers

Twisted graphene trilayer

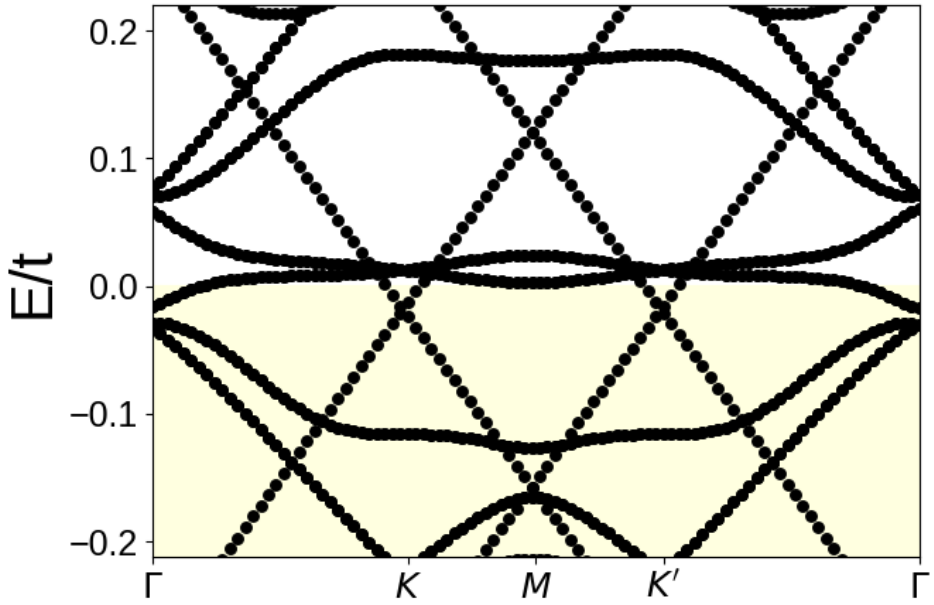


Twisted graphene double bilayer

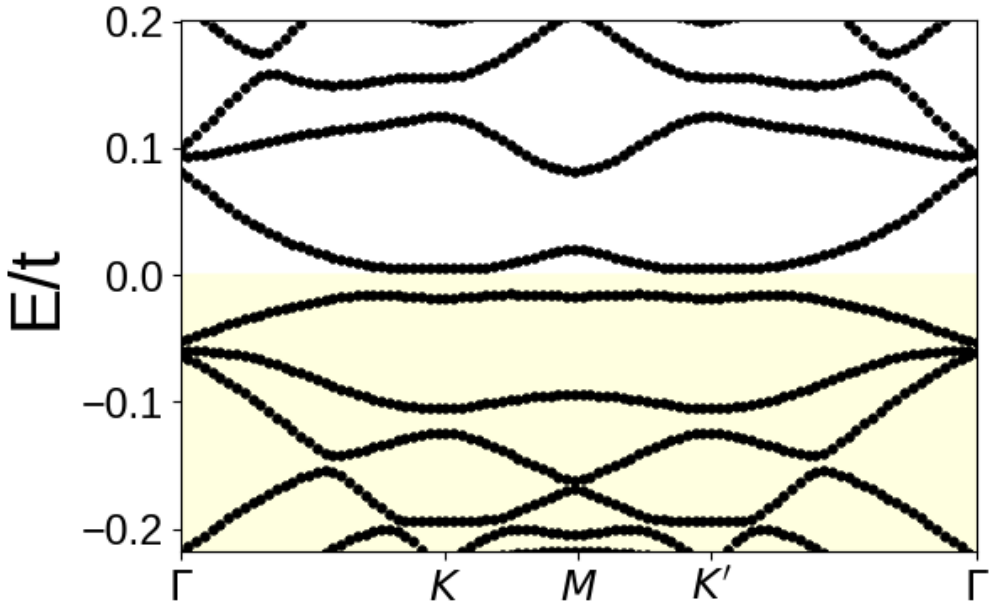


Other twisted graphene multilayers

Twisted graphene trilayer



Twisted graphene double bilayer



Flat and dispersive moire bands appear in generic twisted graphene multilayers

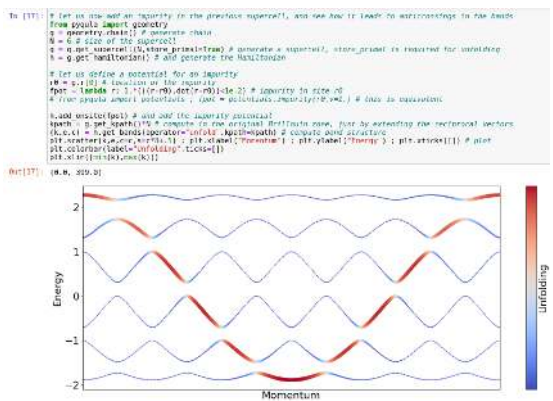
For the exercise session this afternoon

Download the Jupyter-notebook from

https://github.com/joselado/jyvaskyla_summer_school_2022/blob/main/sessions/session4.ipynb

The tasks during the exercise sessions

You will see examples with the code



You have to modify them, and answer questions

Exercise

- Change the size of the supercell. Do the anticrossings appear at the same energies?
- If the strength of the impurity becomes very large, what happens to the electronic structure? Discuss why it has the behavior observed